

Gold-Ceramic Thin Films: The New Gold Standard for High Performance Electrical Sliding Contacts

Presented by Nicolas Argibay

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Albuquerque NM, USA



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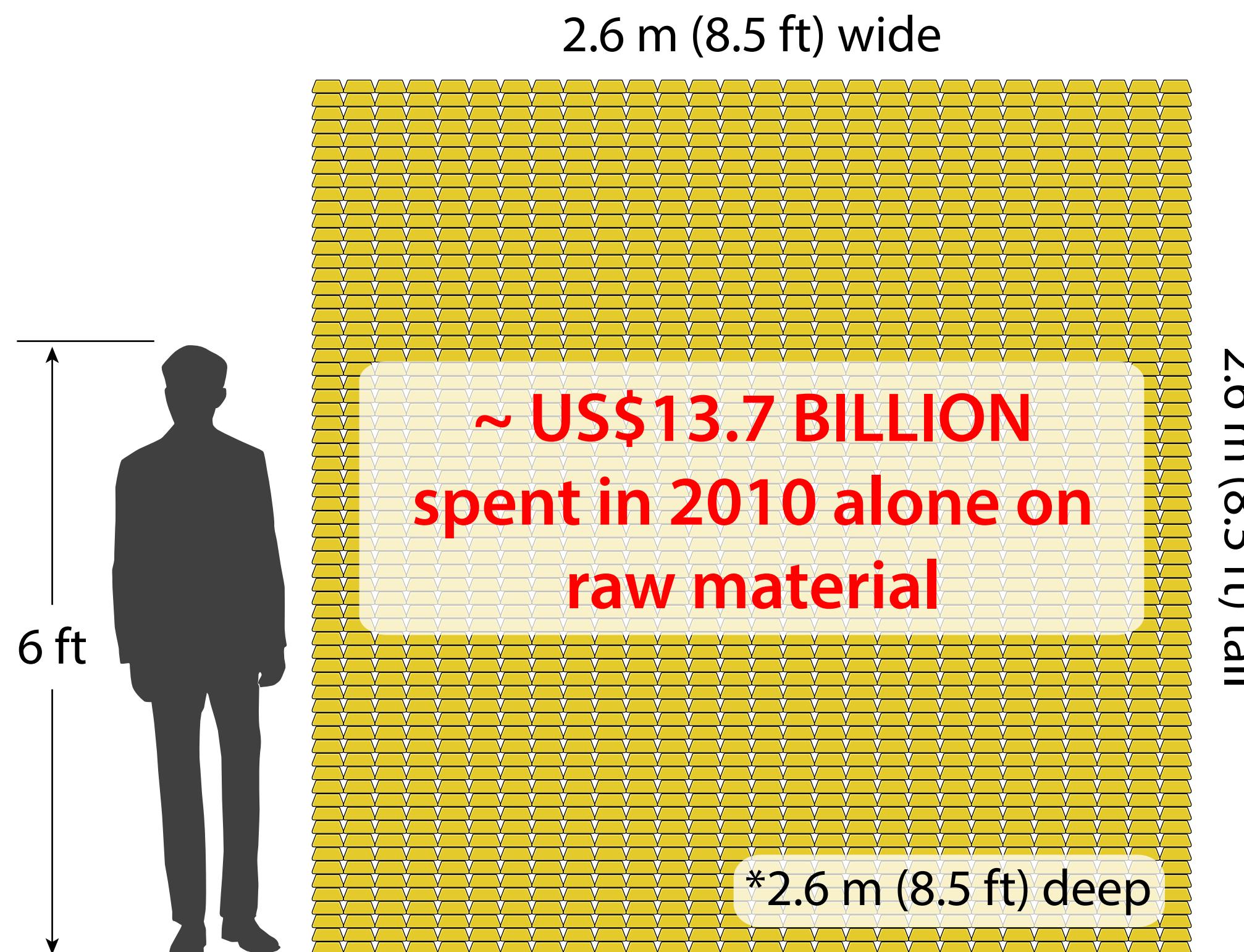


**U.S. DEPARTMENT OF
ENERGY**

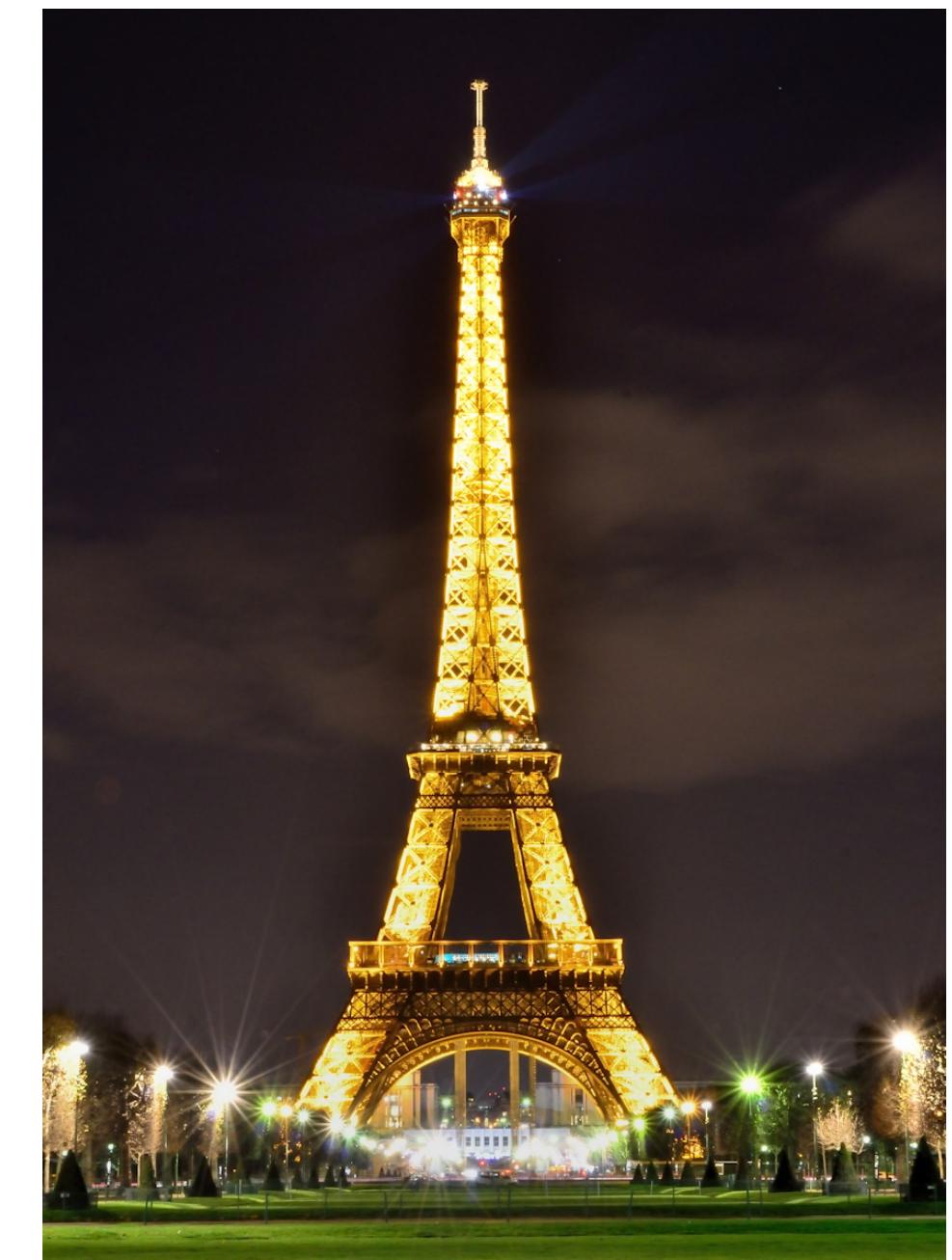
Brief aside: just how relevant is gold as a tribological coating?

An estimated **300 metric tons/year** of gold used in electronics related applications, most of it in electroplated connectors and contacts (**11% of yearly amount mined**)

Equivalent to a cube comprised of ~25,000 standard gold bars (12 kg/26.4 lb each) *per year*...



... or enough to clad the entire surface of the Eiffel Tower with pure gold 70 μm thick *every year*



What is a common theme in the vast majority of electrical contacts?

MEMS: 1-2 μm thick gold and gold alloy films are typical

printed circuit boards (PCBs): 200 - 500 nm thick electroless gold films on soldered connections to prevent oxidation on PCBs

aerospace: 1 - 3 μm thick hard gold (ASTM/MilSpec) used to achieve predictable friction AND contact resistance over years or decades

	silver 47	
Pd 106.42 platinum 78	Ag 107.87 gold 79	Ca 112.41 mercury 80
Pt 195.08 ununnilium 110	Au 196.97 unununium 111	Hg 200.59 ununbium 112
Un [272]	Uuu	Uup

What is electroplated “hard gold”?

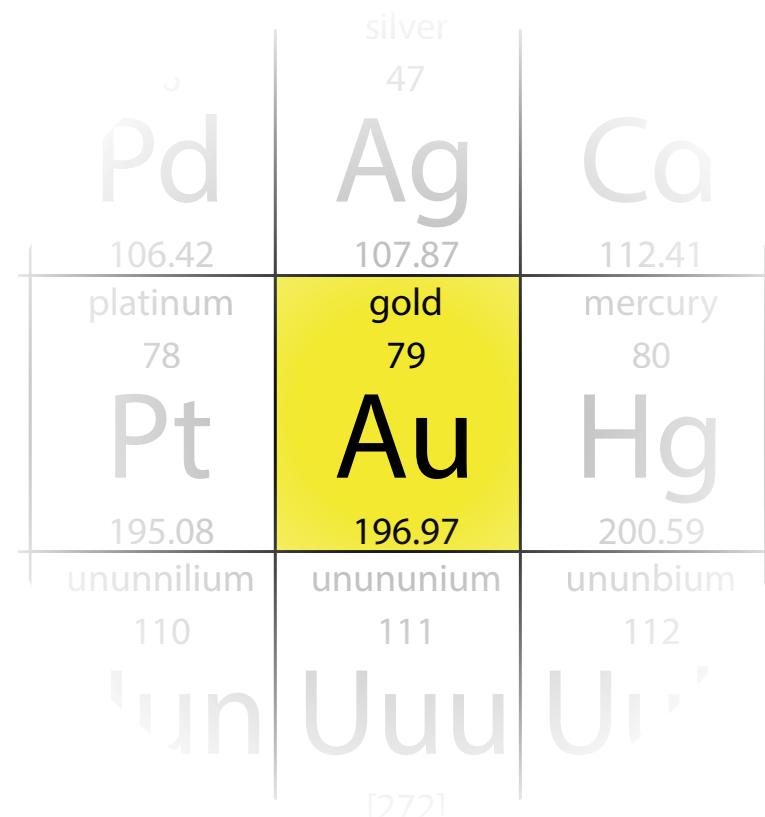
Nominally gold with the addition of Ni/Co/Fe not exceeding 1 wt. %

What is a common theme in the vast majority of electrical contacts?

MEMS: 1-2 μm thick gold and gold alloy films are typical

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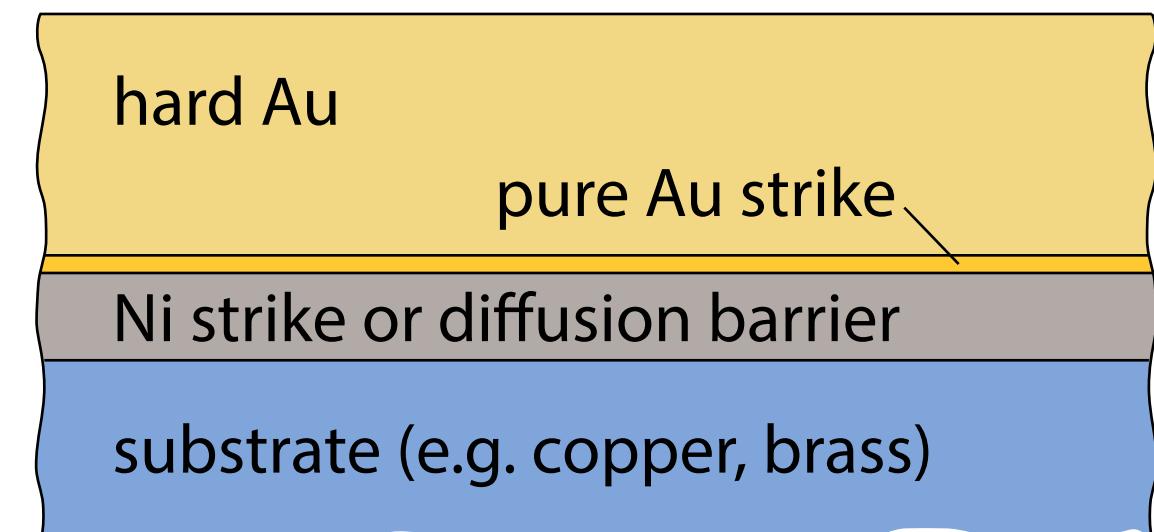
Why? Critical to performance are:

- **oxidation resistance** **YES**

- **ductility** **YES**

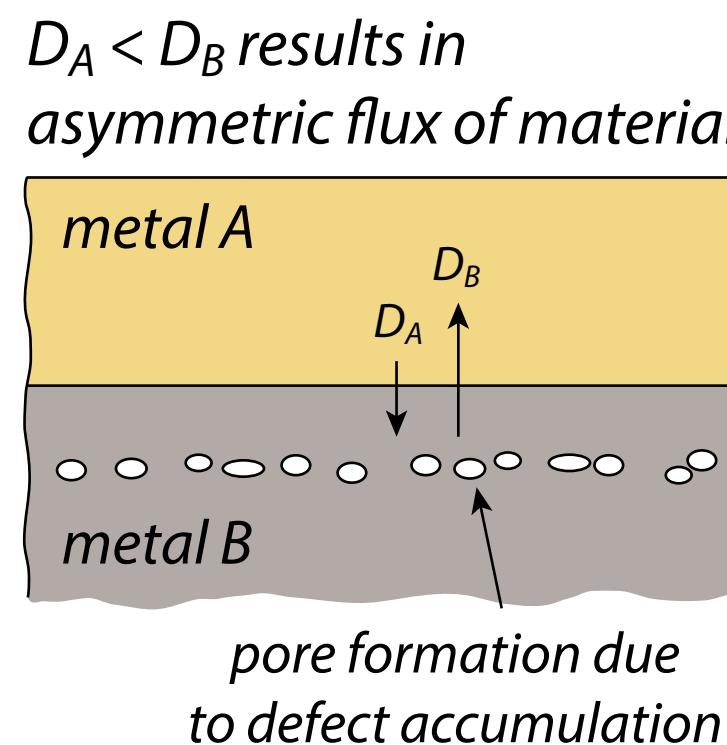
- **electrical conductivity** **YES**

...but low friction/wear? use alloys (hard gold)

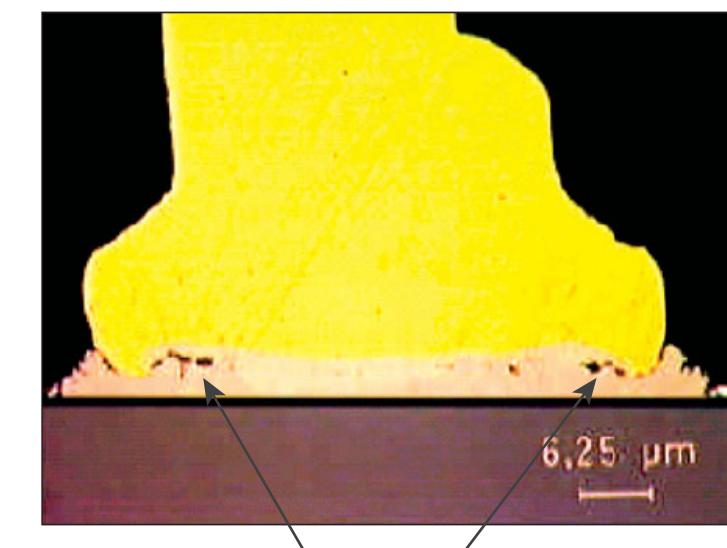


What materials aging phenomena are relevant to tribological contacts?

Kirkendall **porosity** (voiding) and the formation of **intermetallics** (embrittlement):

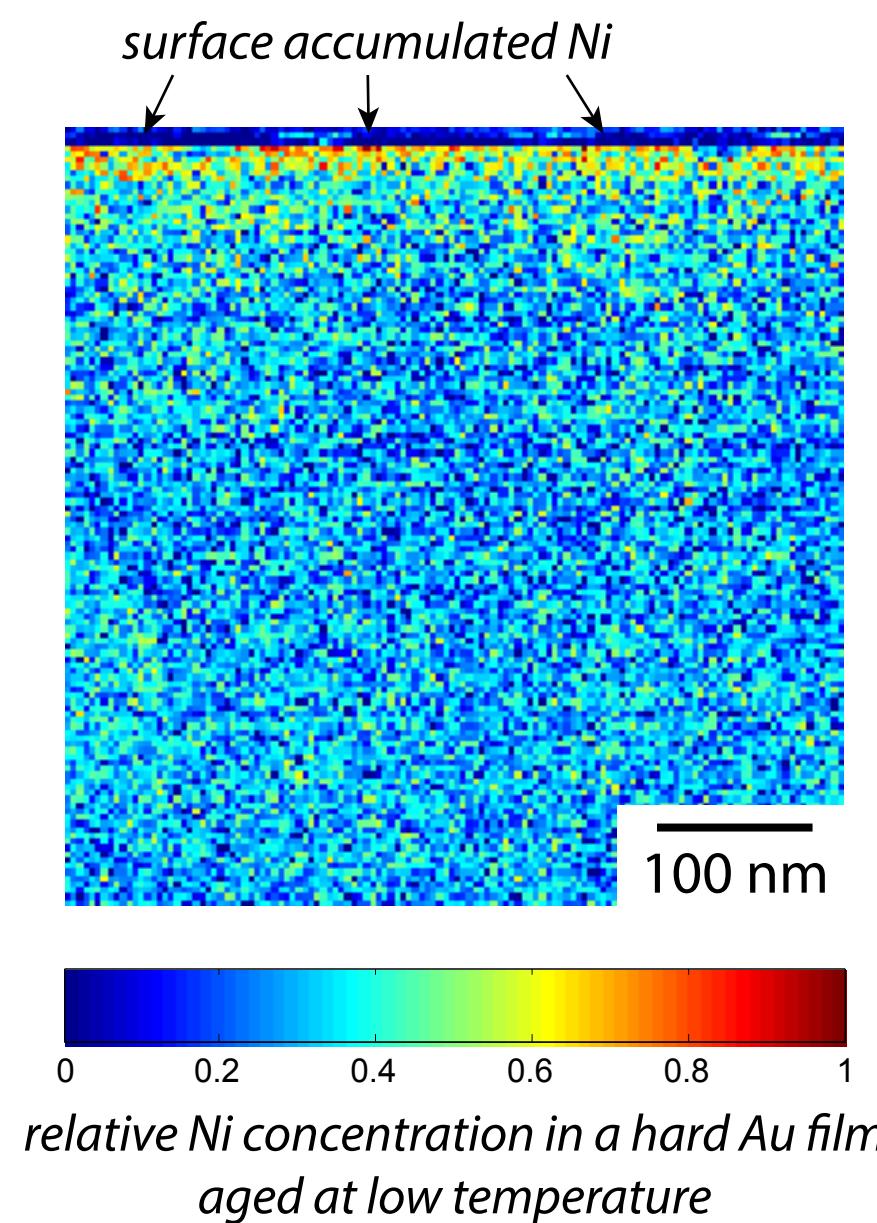


aged Au-Al ball bond used in flip chip bonding

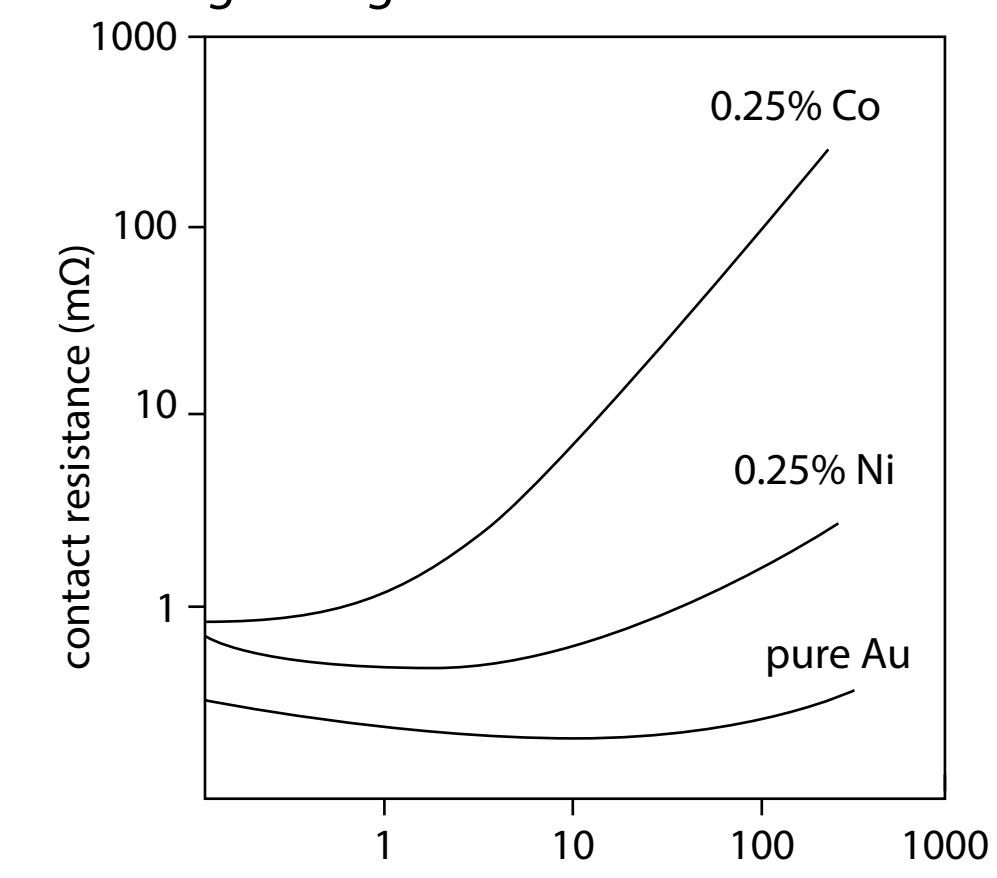


formation of voids and interfacial fractures driven by formation of intermetallics

Surface accumulation of underlayer and codeposited species:



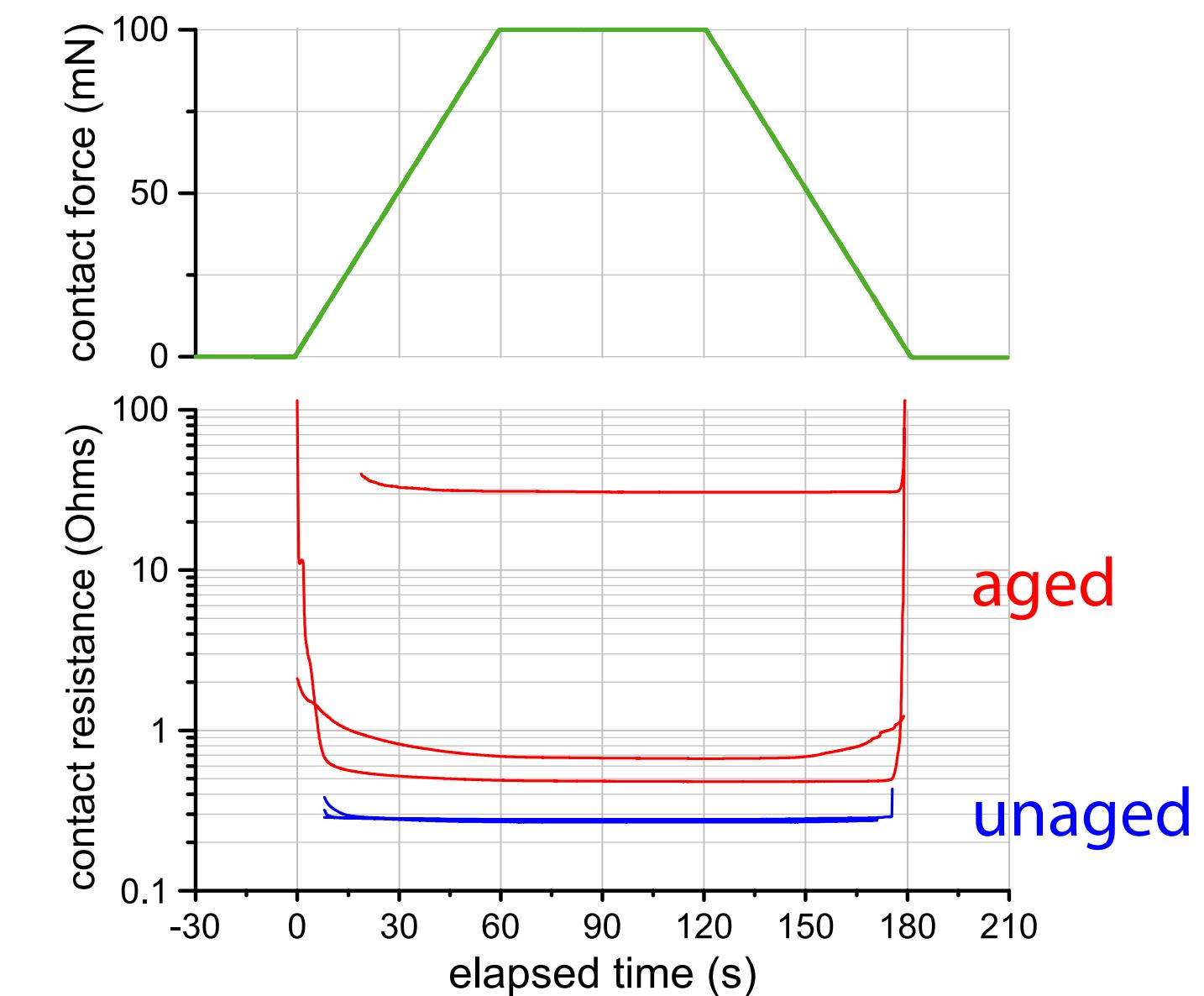
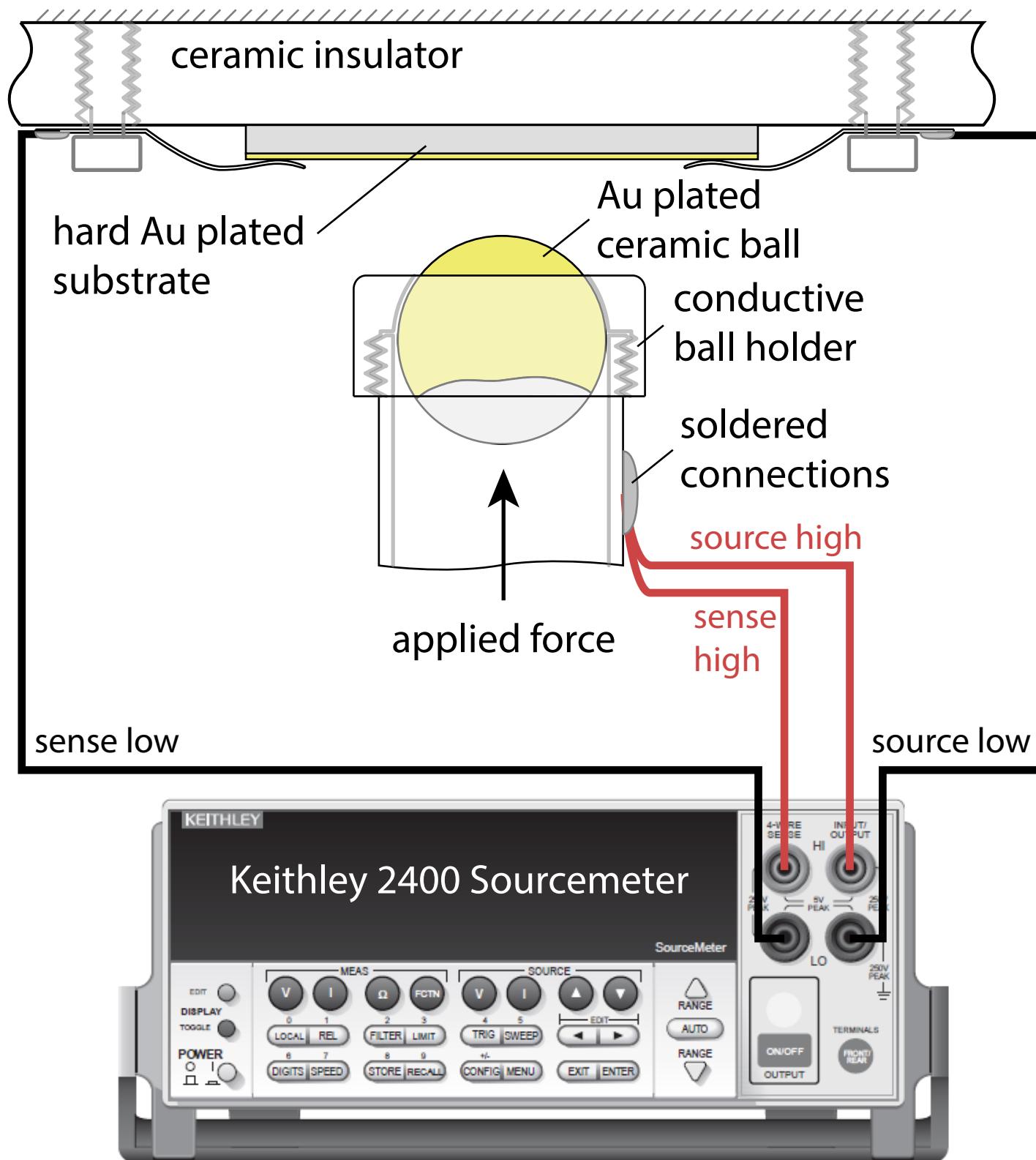
aging of **bulk** pure and alloyed gold ingots:



Reference: M. Antler, Plating and Surface Finishing, 1998

Surface accumulation and oxidation can significantly affect ECR

Electrical contact resistance of aged type I hard Au plated Fe-Ni substrate aged at 250°C for 42.5 hours in air:



- film thickness ~ 2 μm type I hard Au on a 5-7 μm Ni strike
- 1 mA current
- ball radius : 1/32" (~ 0.79 mm)

several order of magnitude changes in contact resistance can occur quickly

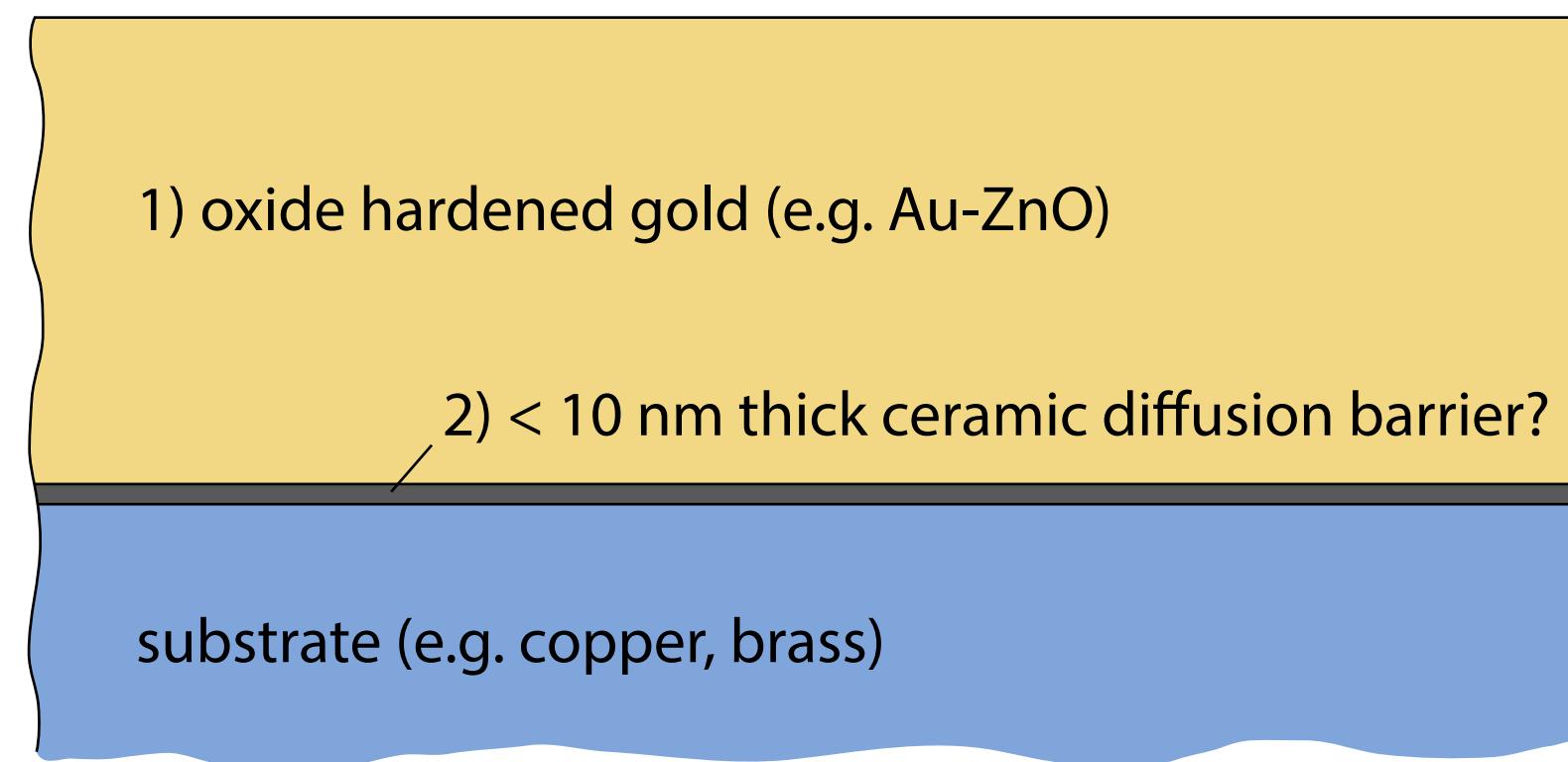
New routes for mitigating aging in gold electrical contacts?

Traditionally: mitigate the aging phenomena, increase the service life of a contact by,

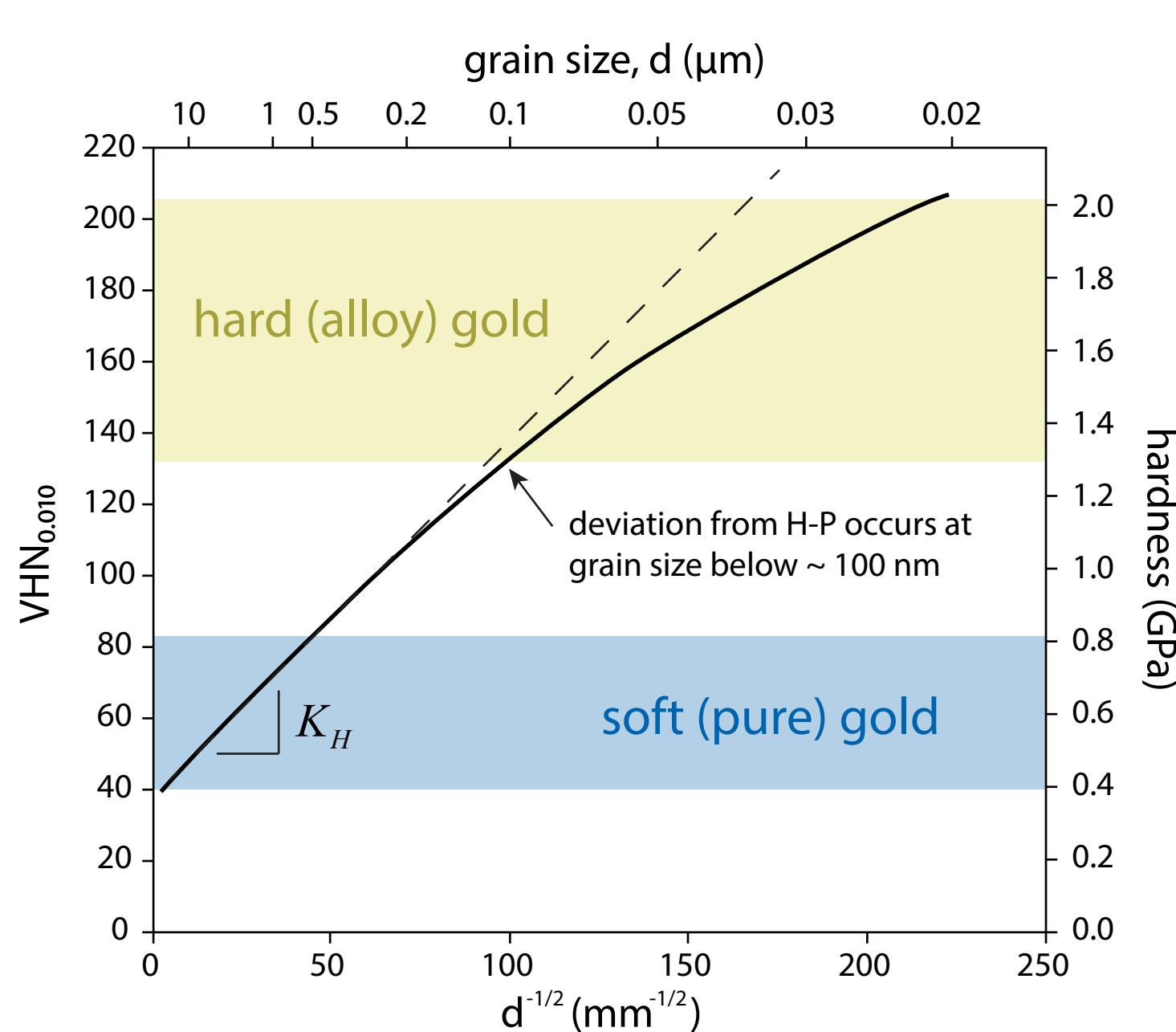
1. using sufficiently thick gold films
2. use an inert environment

Proposed: shut down solid diffusion of codeposited and underlayer materials via,

1. ceramics to harden Au in place of non-noble metals
2. introduce electron transparent ceramic diffusion barrier layers



Hard gold hardens primarily via Hall-Petch strengthening (grain refinement)

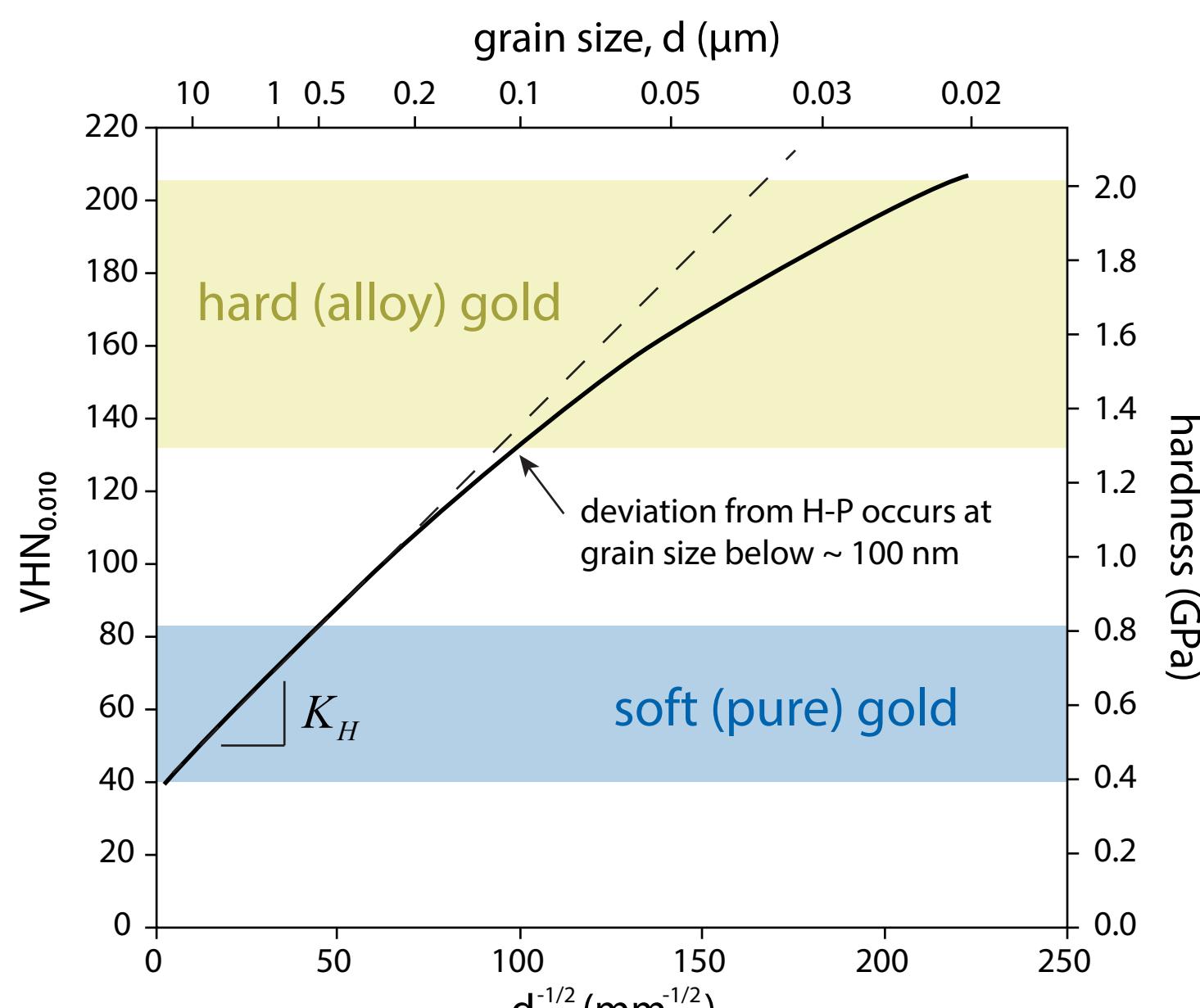


Reference: C. Lo, J. Augis, and M. Pinnel, JAP (1979)

Contact area to hardness relationship: $A_r \cong \frac{F_n}{H}$

Hall-Petch hardness to grain size relationship: $H = H_0 + K_H d^{-1/2}$

Zener pinning GB segregated second phase limits grain growth

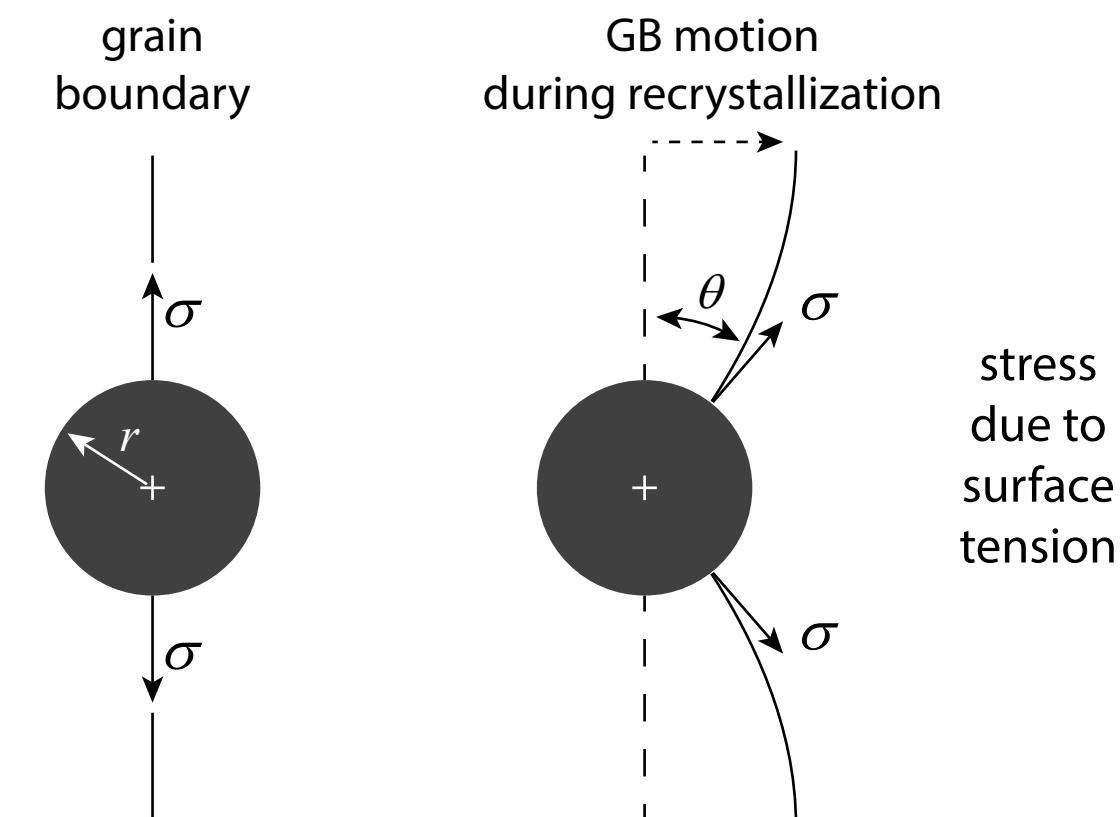
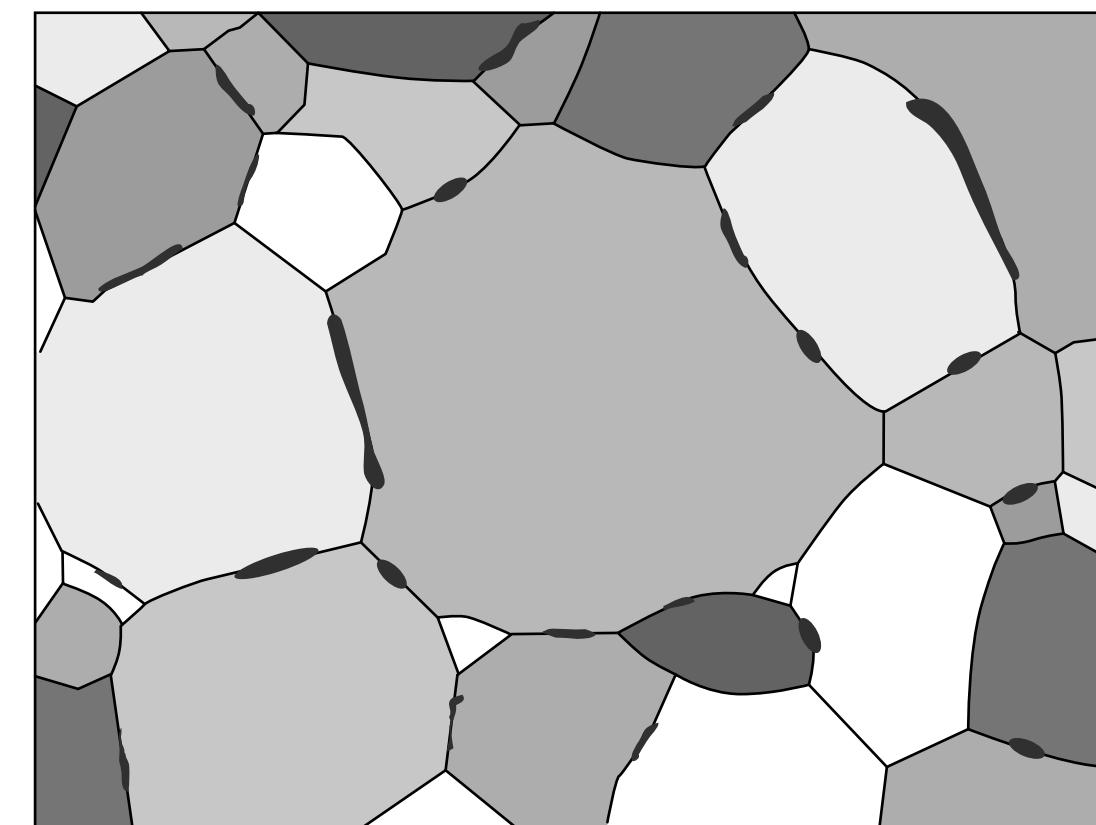


Reference: C. Lo, J. Augis, and M. Pinnel, JAP (1979)

Contact area to hardness relationship: $A_r \approx \frac{F_n}{H}$

Hall-Petch hardness to grain size relationship: $H = H_0 + K_H d^{-1/2}$

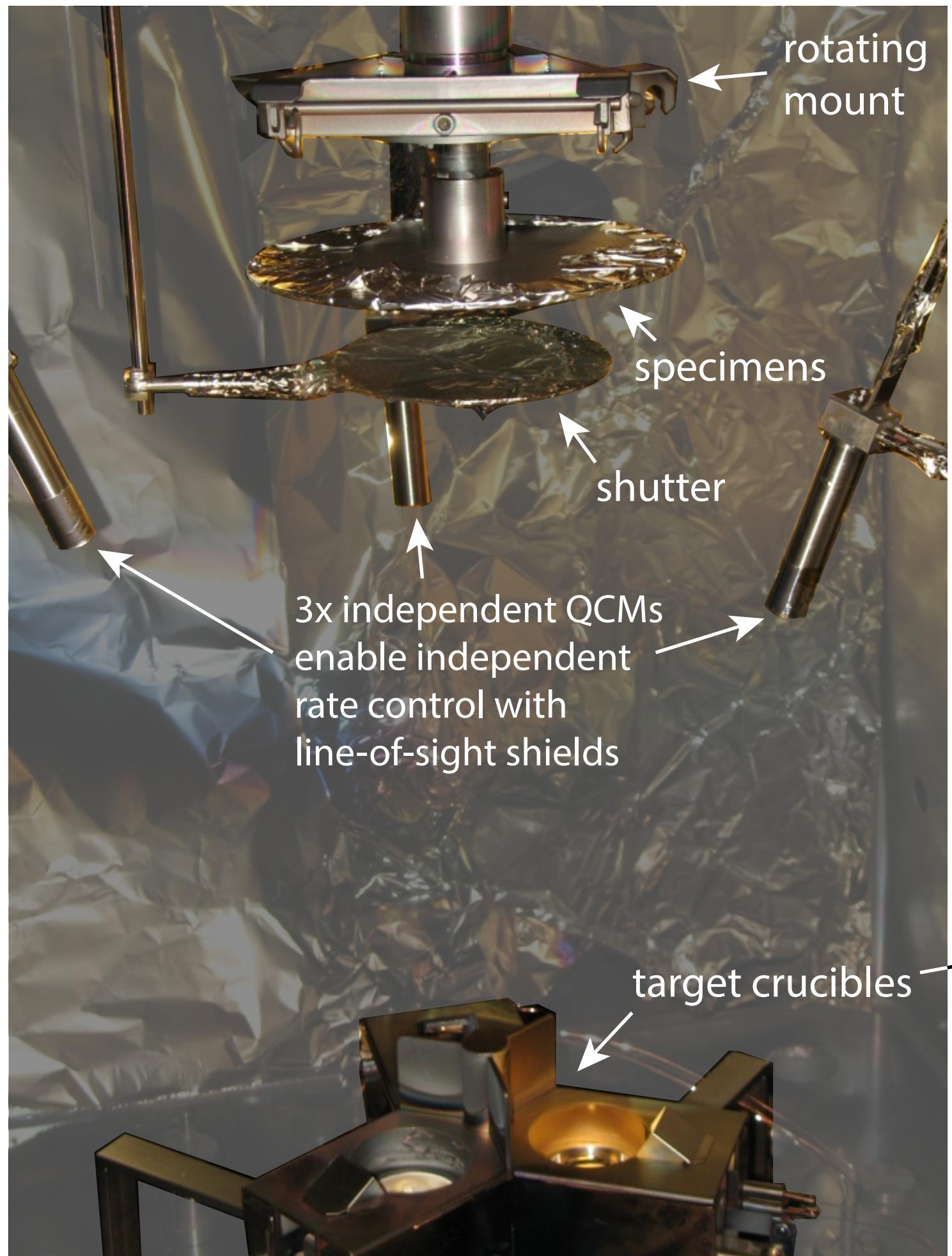
second-phase inclusions at GBs pin the boundaries and inhibit GB mobility (recrystallization)



drag force: $f_D = 2\pi r\sigma \cos \theta \sin \theta$

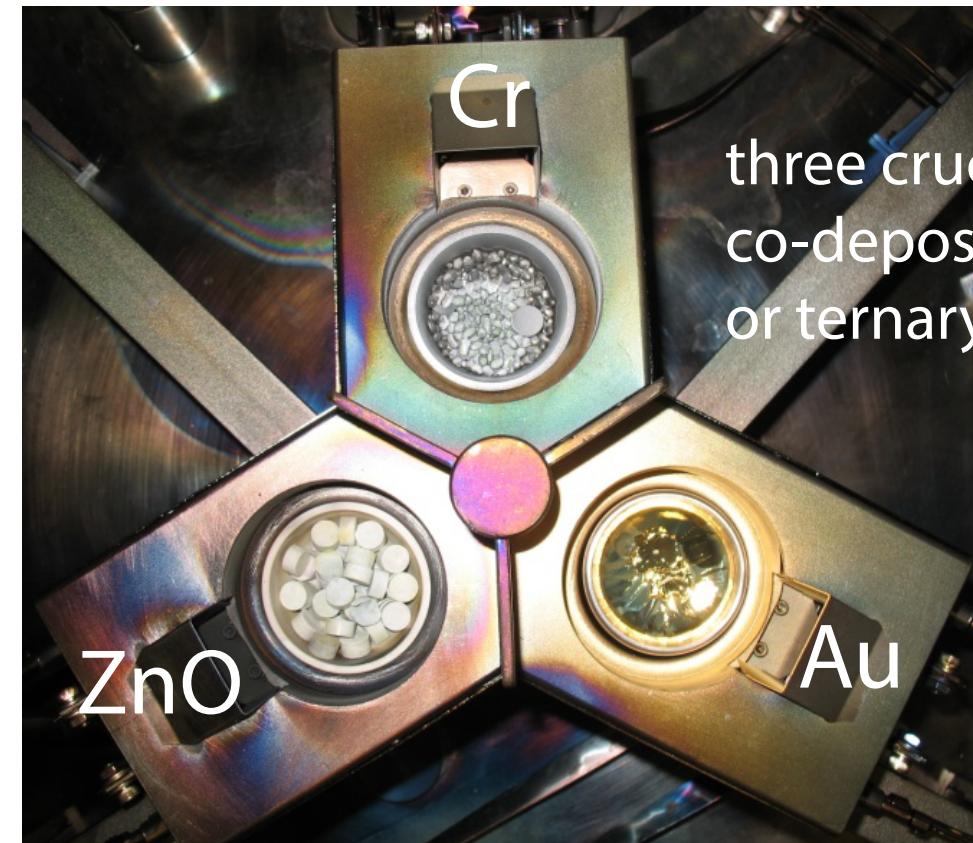
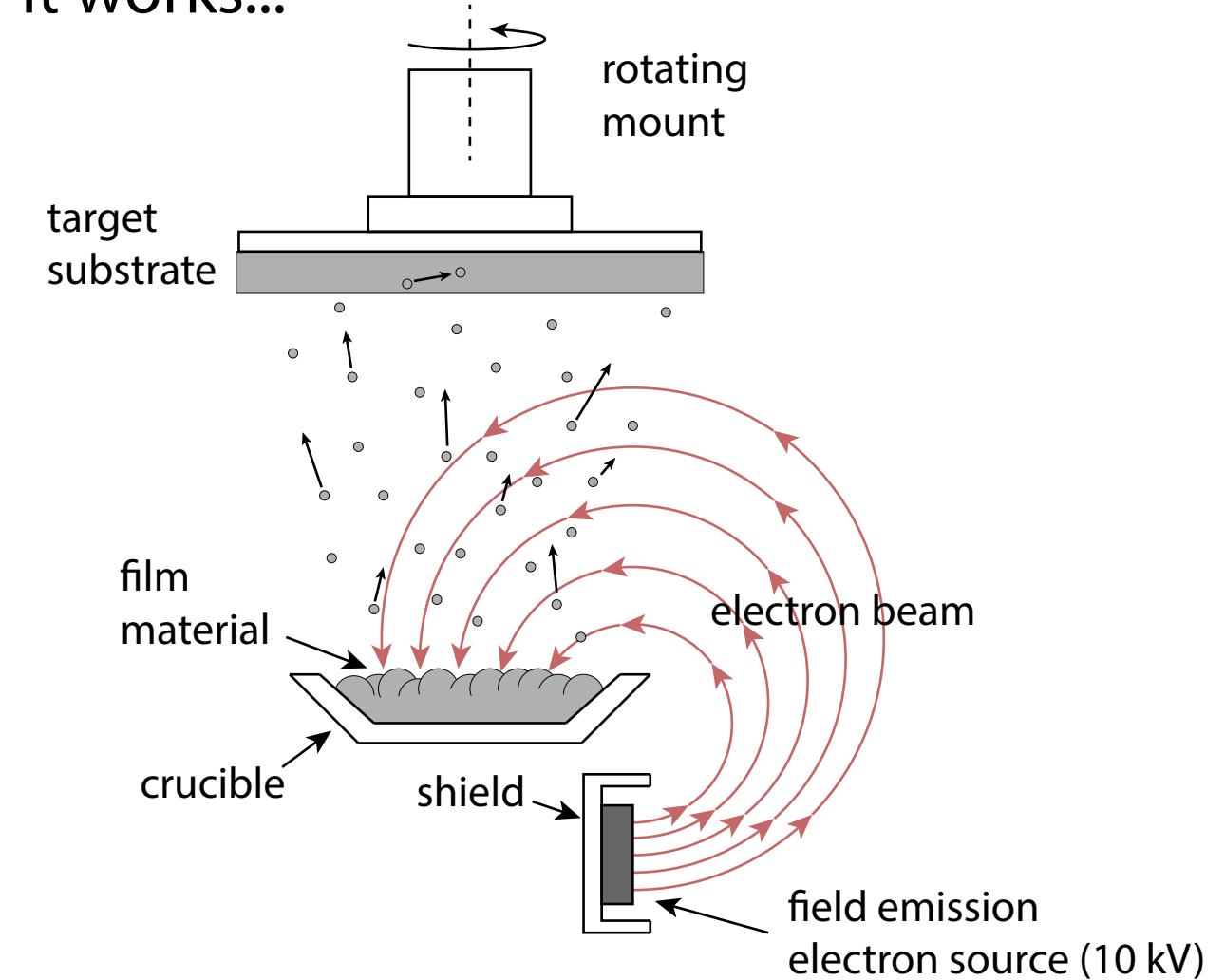
Electron beam deposition of metal-ceramic nanocomposite films

E-beam deposition chamber



Why e-beam? **ppm level composition control**

How it works...

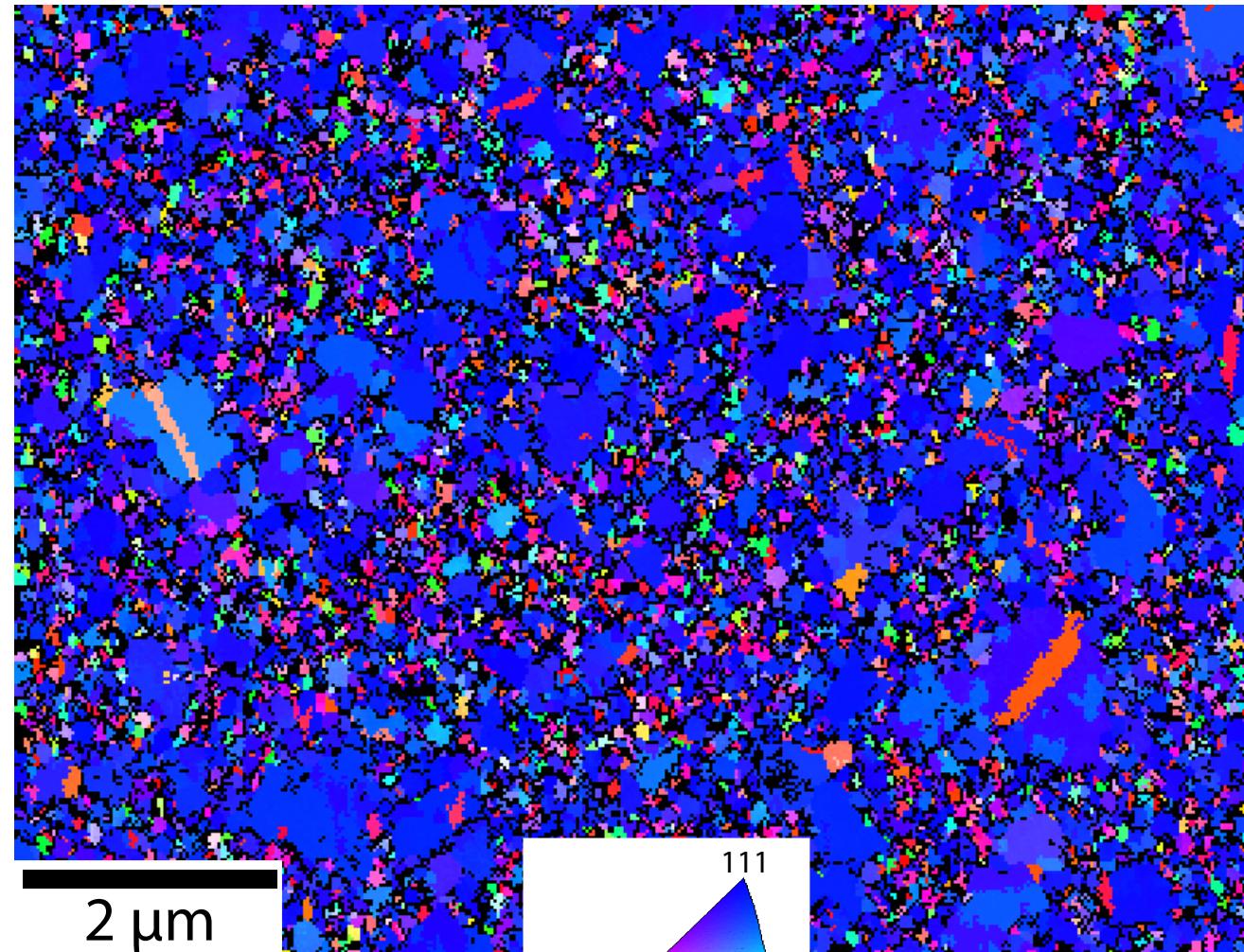


Electron backscatter diffraction maps showing grain refinement with alloying

(e-beam deposited films)

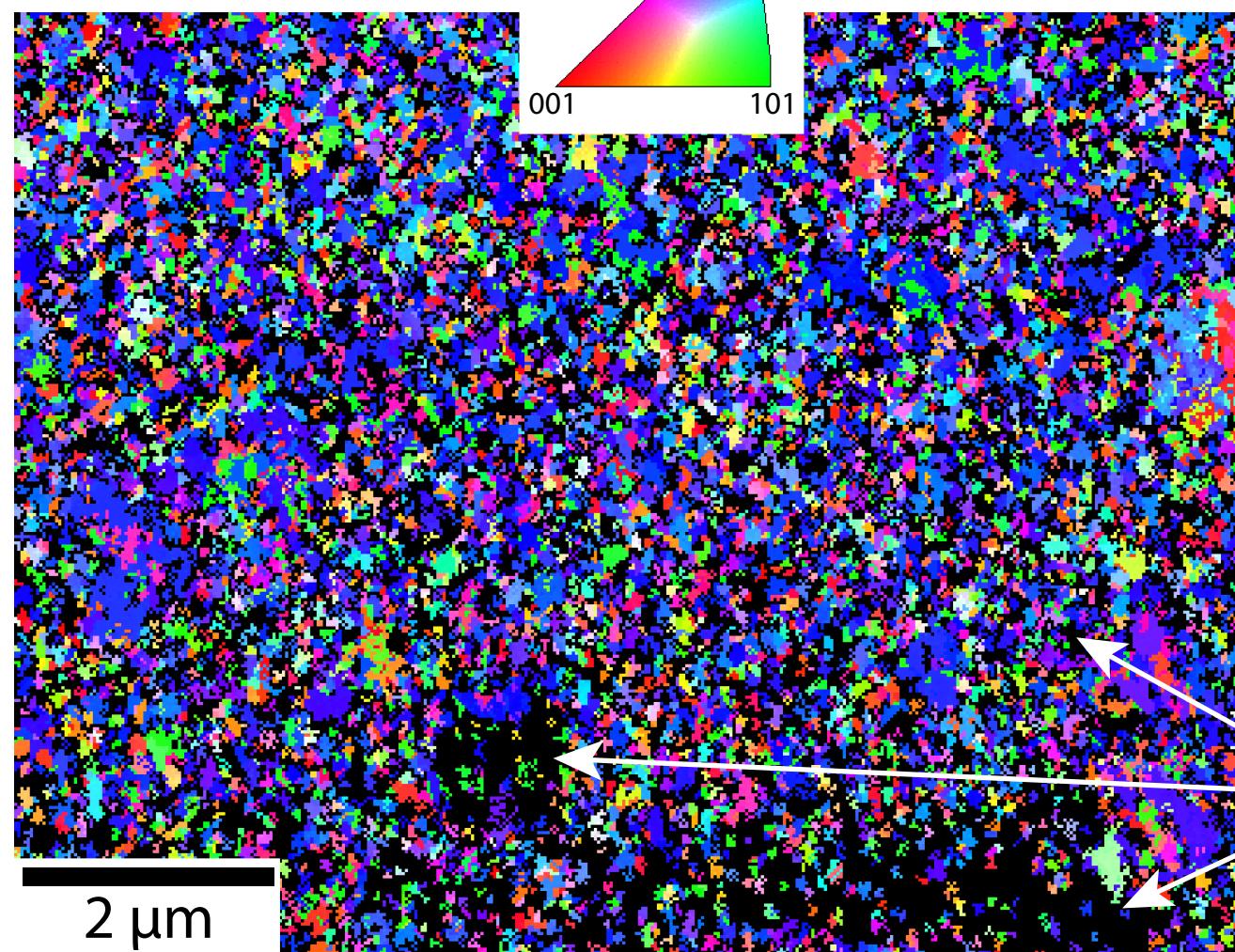
surface normal orientation

2 μ m thick
pure e-beam
gold film



grain size was bimodal
and textured,
avg. grain size > 500 nm

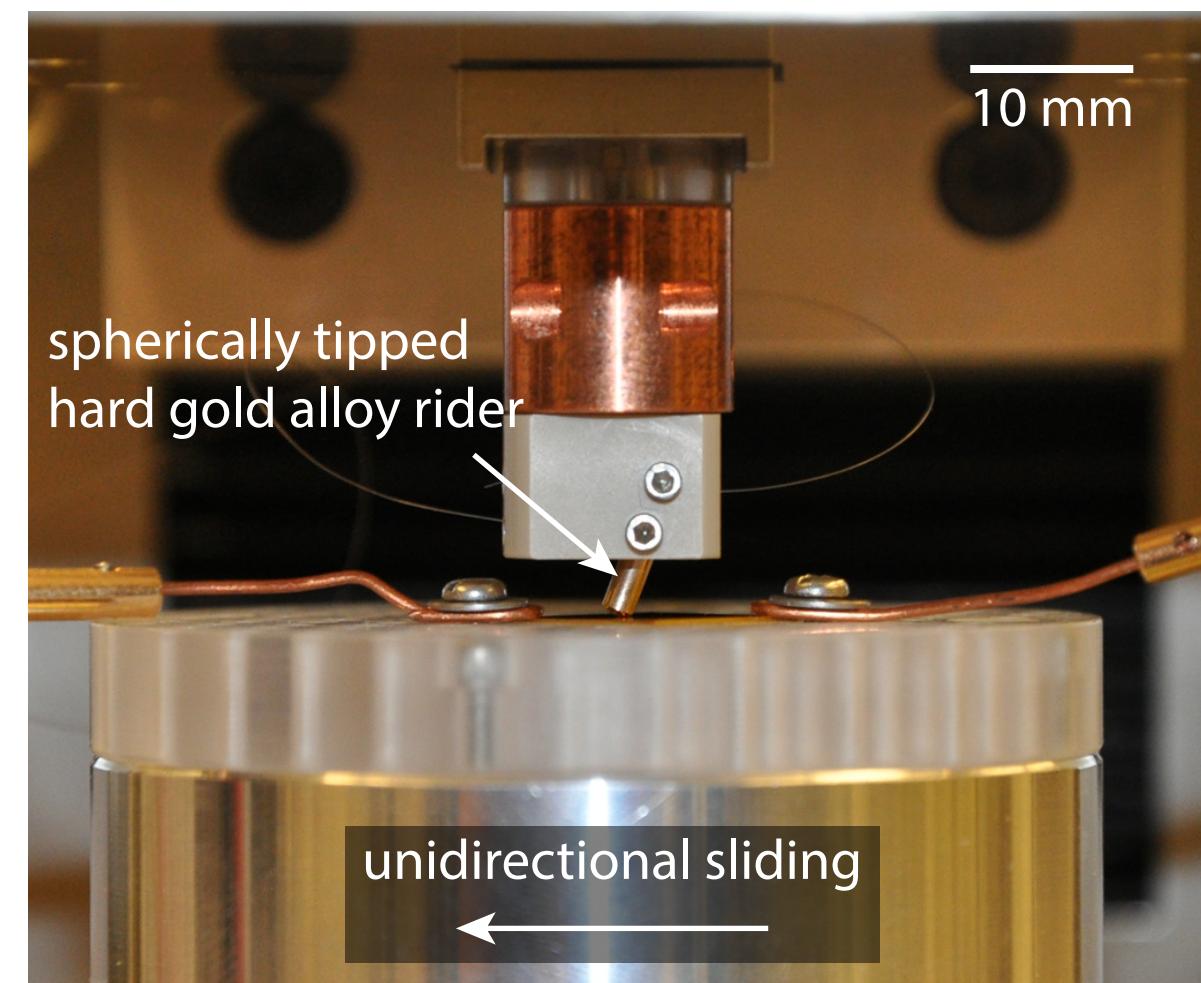
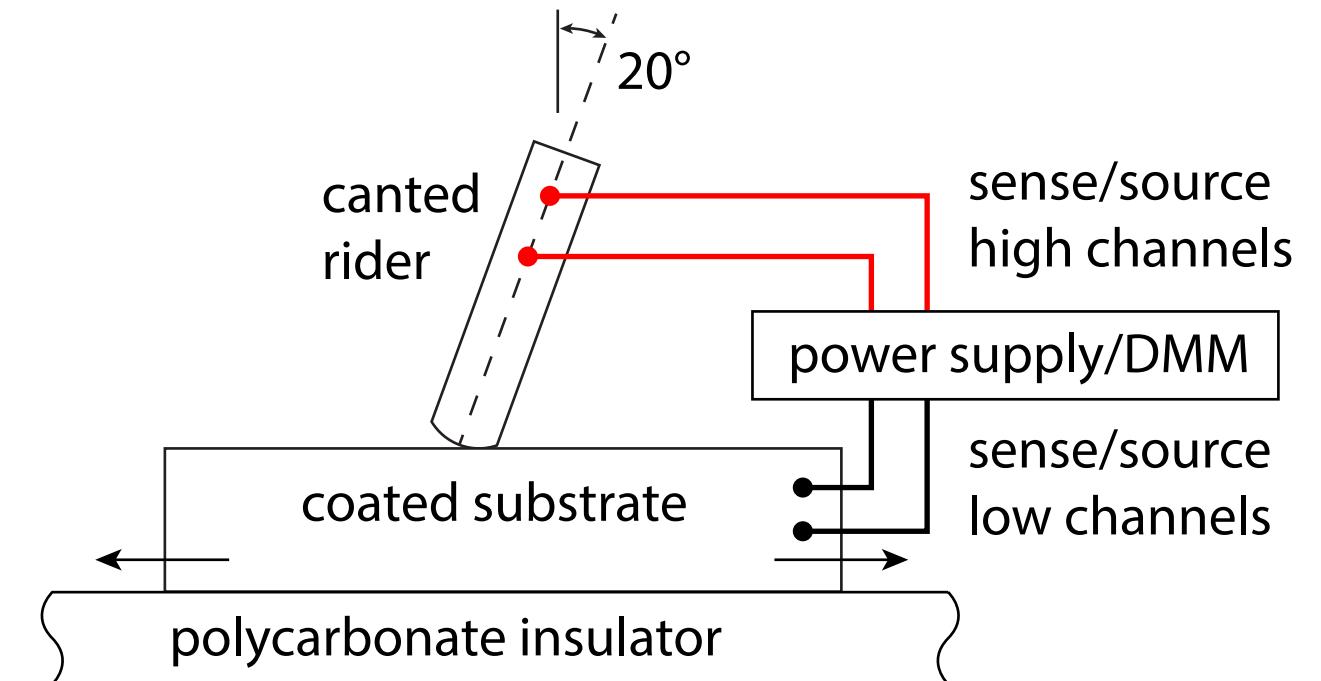
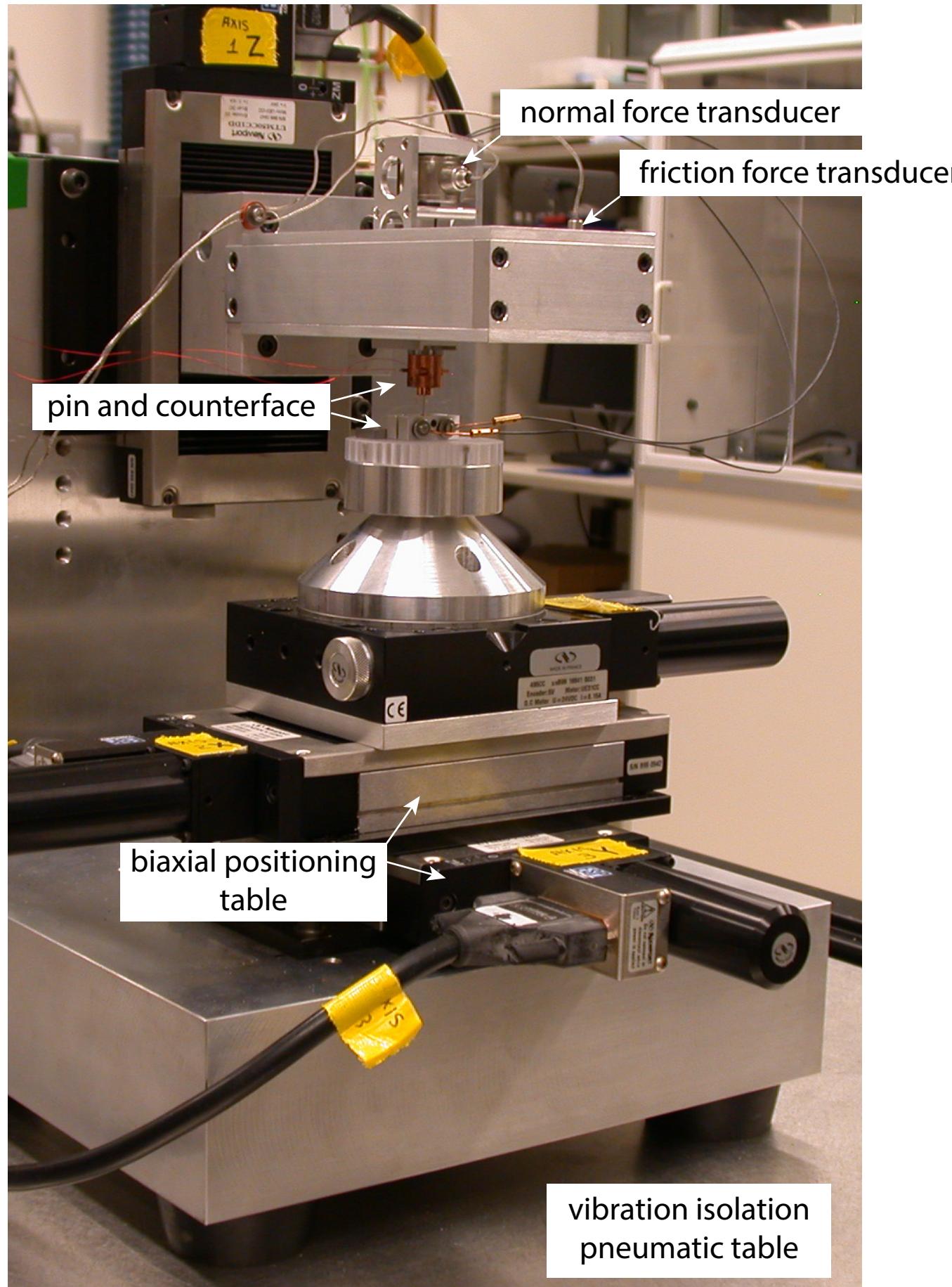
2 μ m thick
0.1 vol. % ZnO
(0.03 wt. %)
gold film



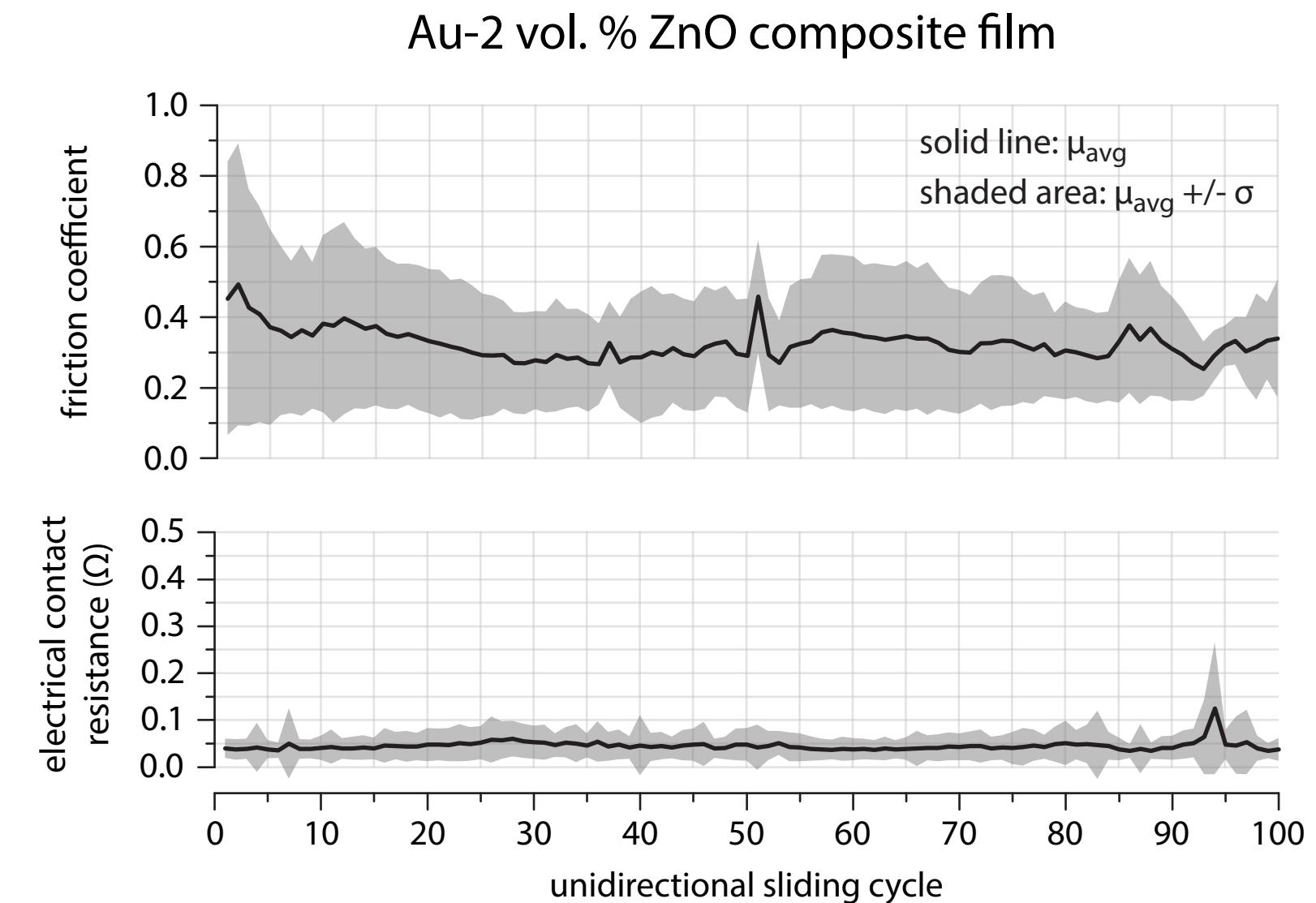
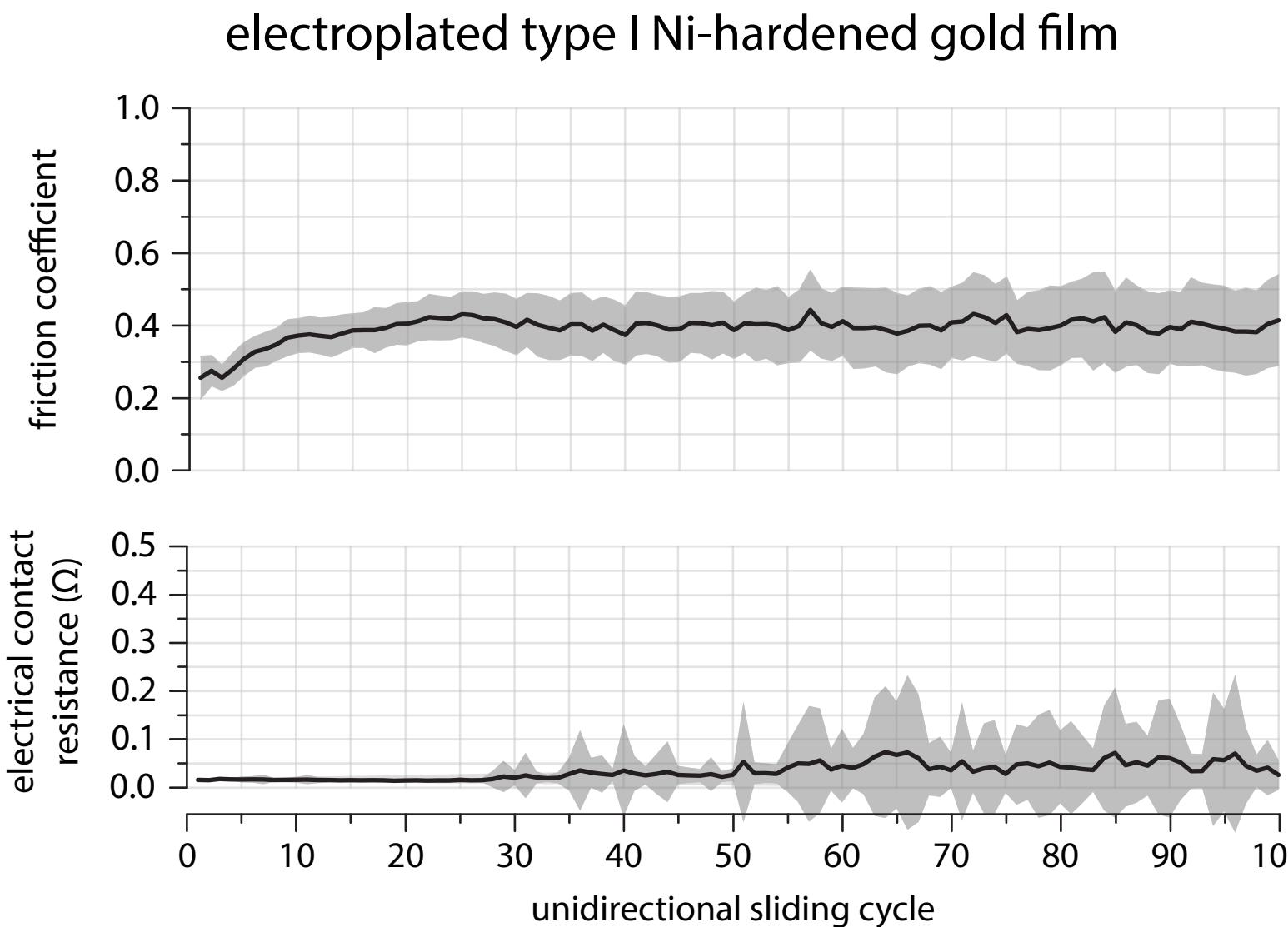
grains are equiaxed,
not textured,
avg. grain size ~ 100 nm

black pixels imply regions
with grain sizes < 50 nm

Sliding Electrical Contact Tester



Au-ZnO shows similar tribological behavior to electroplated hard gold

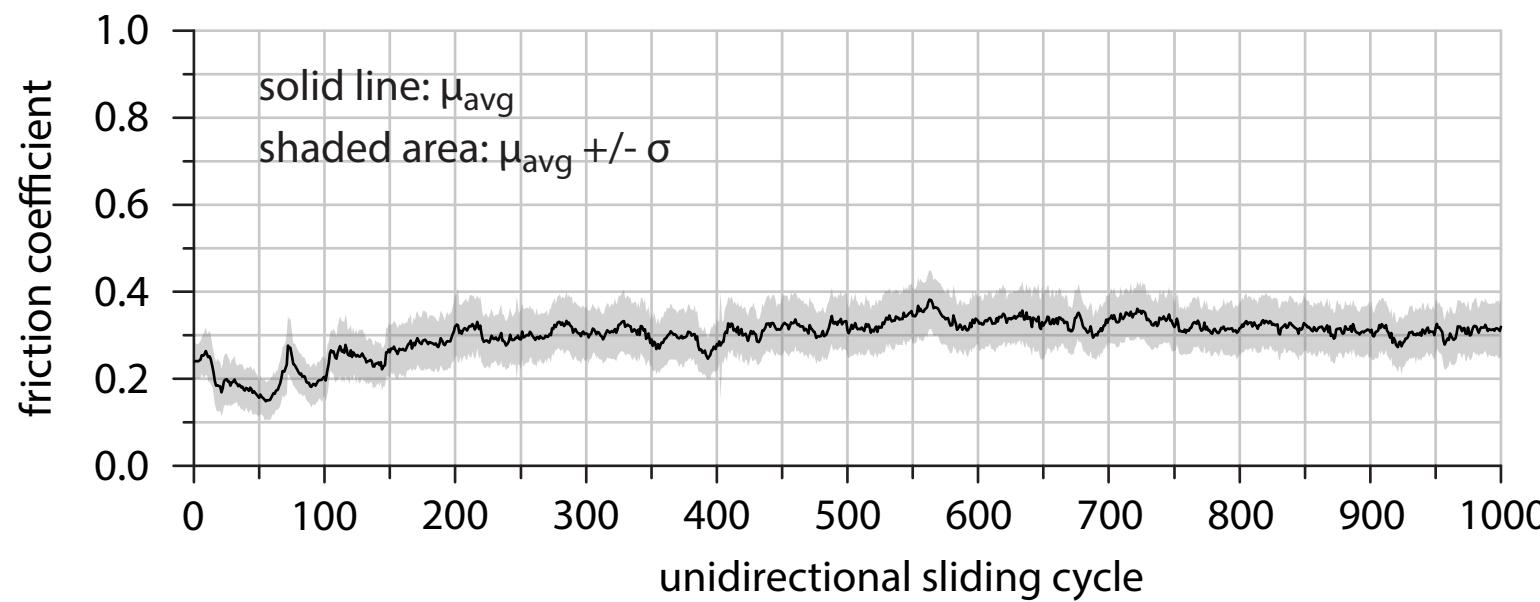


common testing parameters:

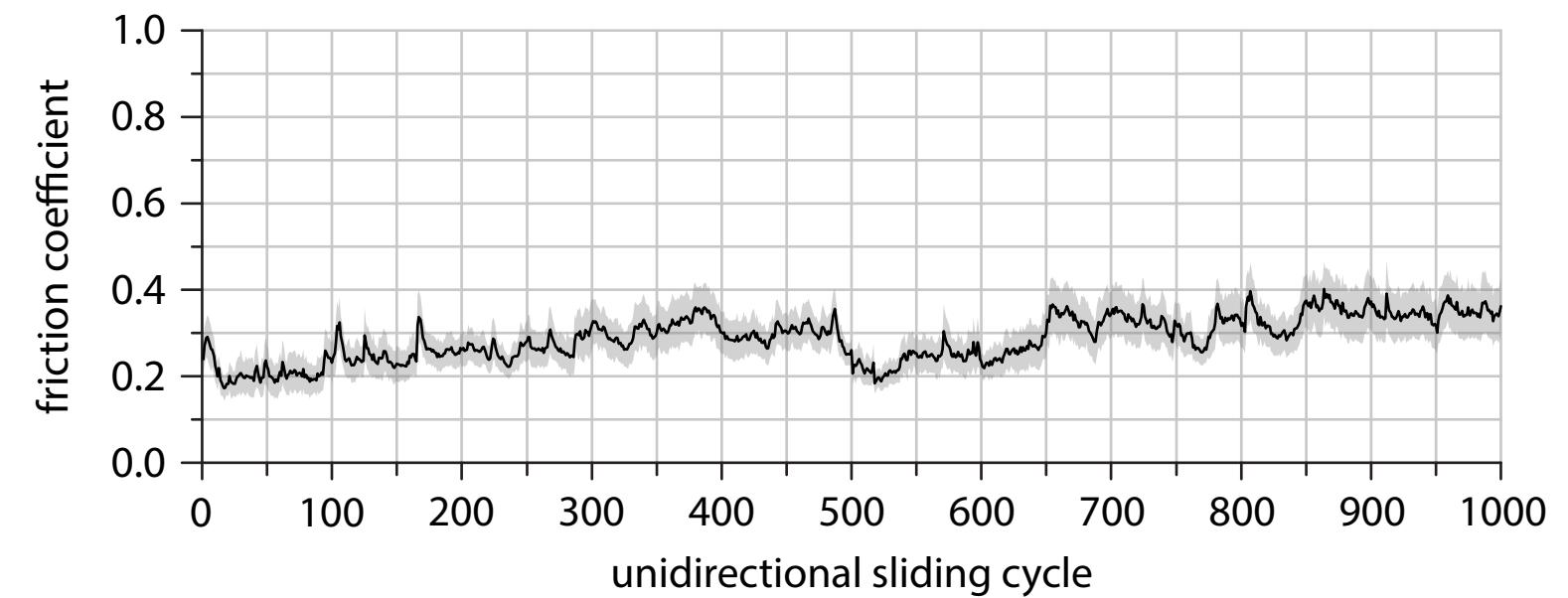
- sliding against a bulk hard gold alloy rider or pin (nominally 72-14-8-5-1 wt. % Au-Cu-Pt-Ag-Zn)
- rider tip radius was 3.175 mm
- contact force was 100 mN
- electrical probe current of 100 mA
- lab air at 21°C, sliding speed of 1 mm/s
- substrate material was alloy 52 (nominally 50/50 wt. % Fe/Ni)
- film thicknesses 2 - 5 μm ; Ti/Pt bonding layers

Wear comparison of electroplated hard gold and Au-ZnO -- against sapphire

electroplated type I hard gold sliding against sapphire



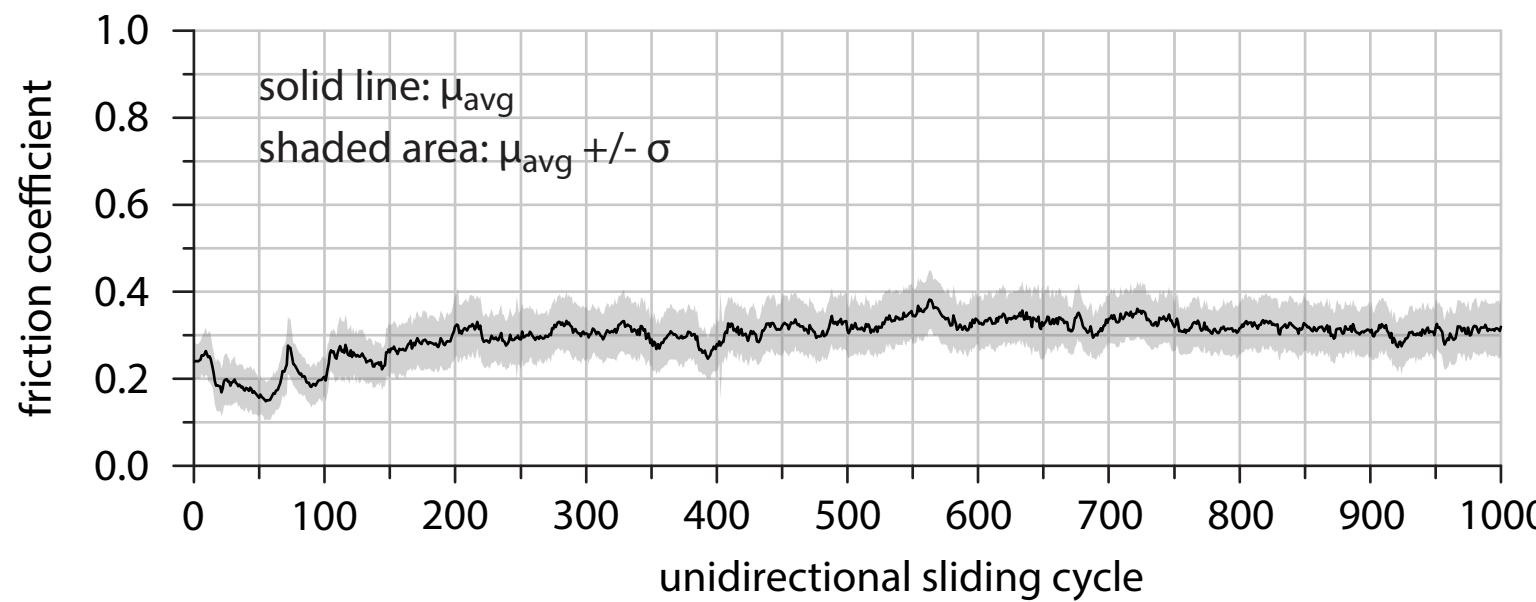
Au-5 vol. % ZnO sliding against sapphire



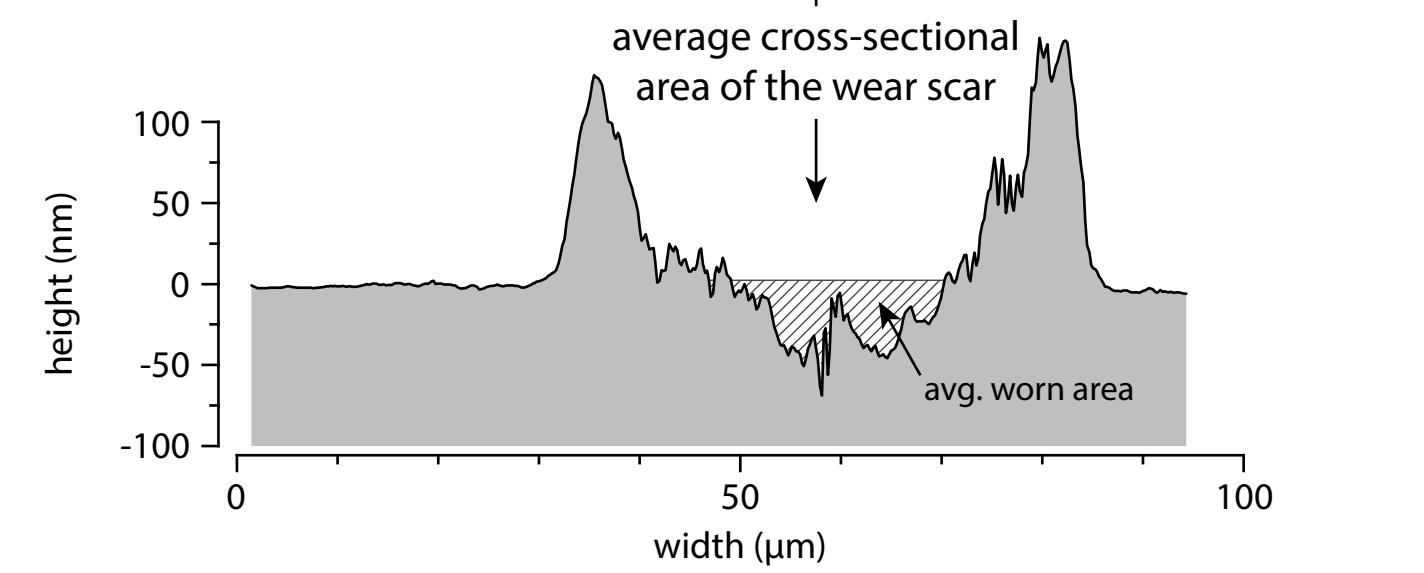
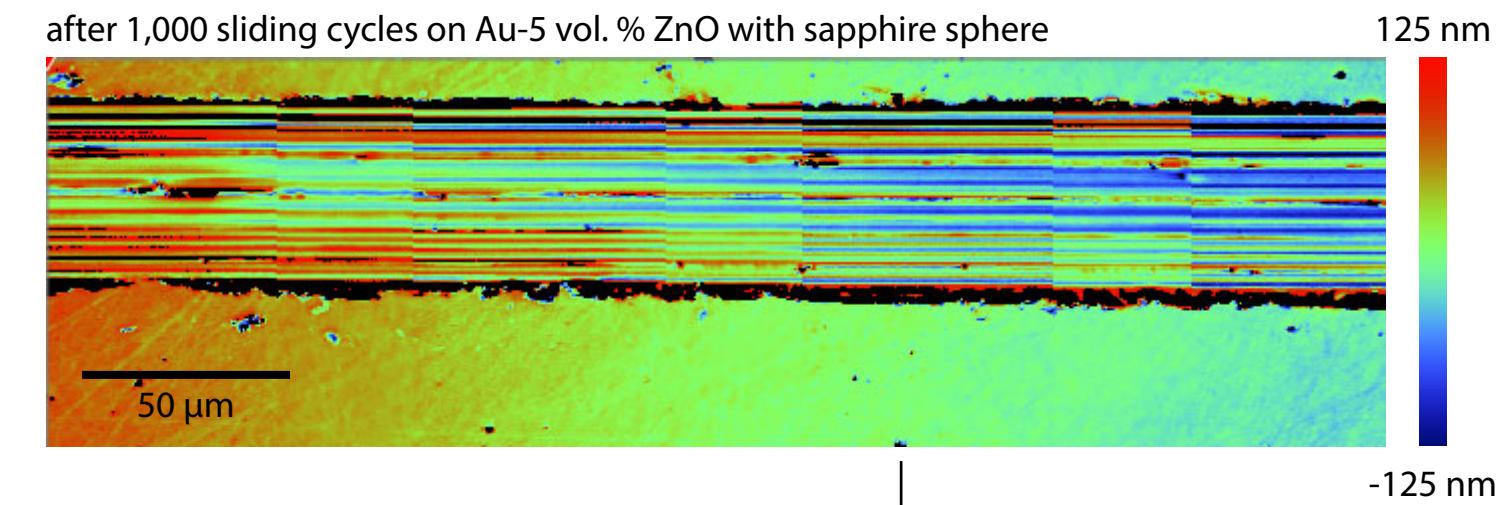
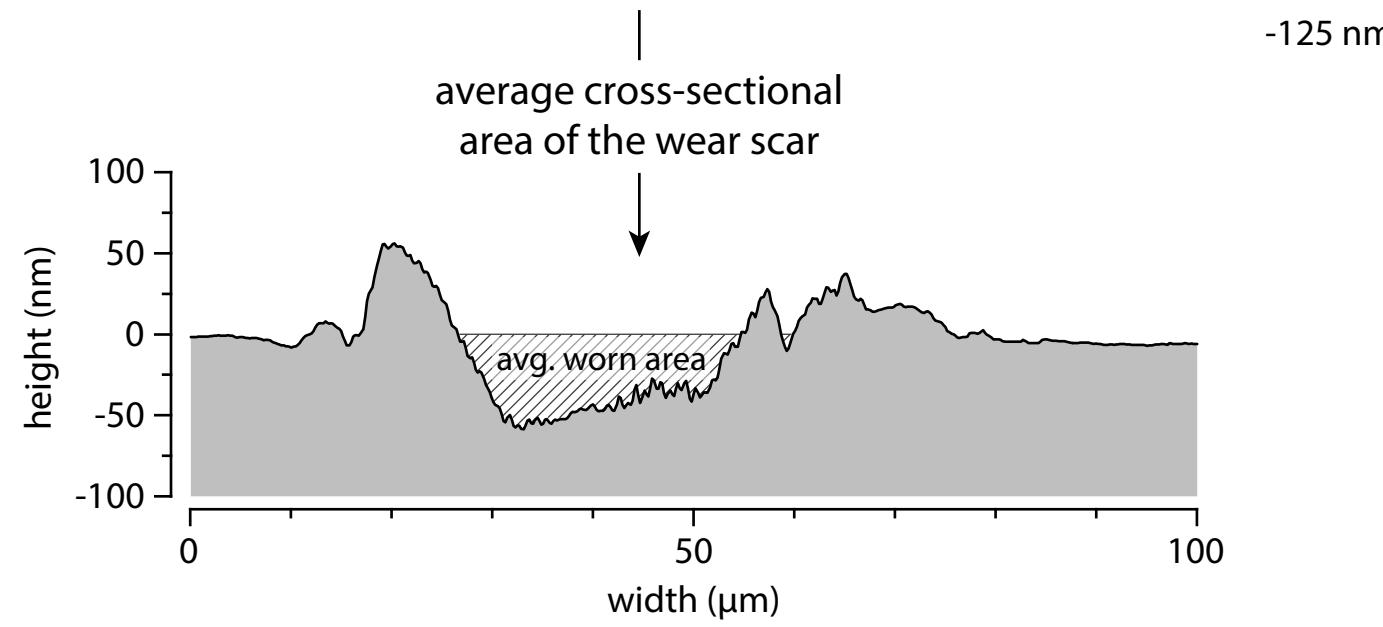
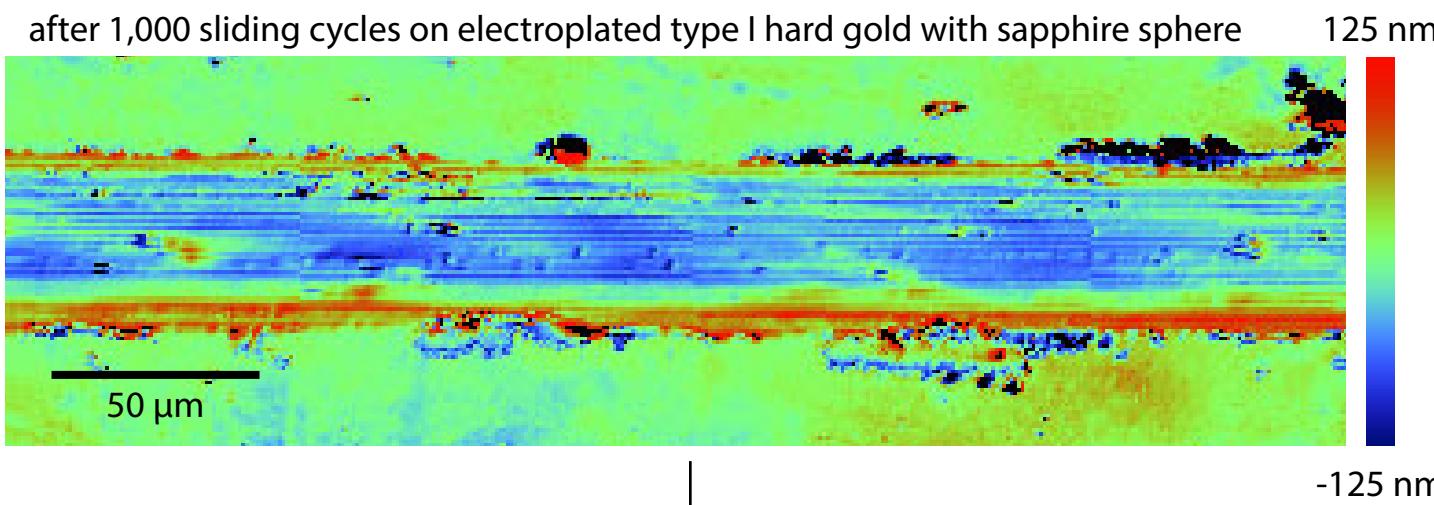
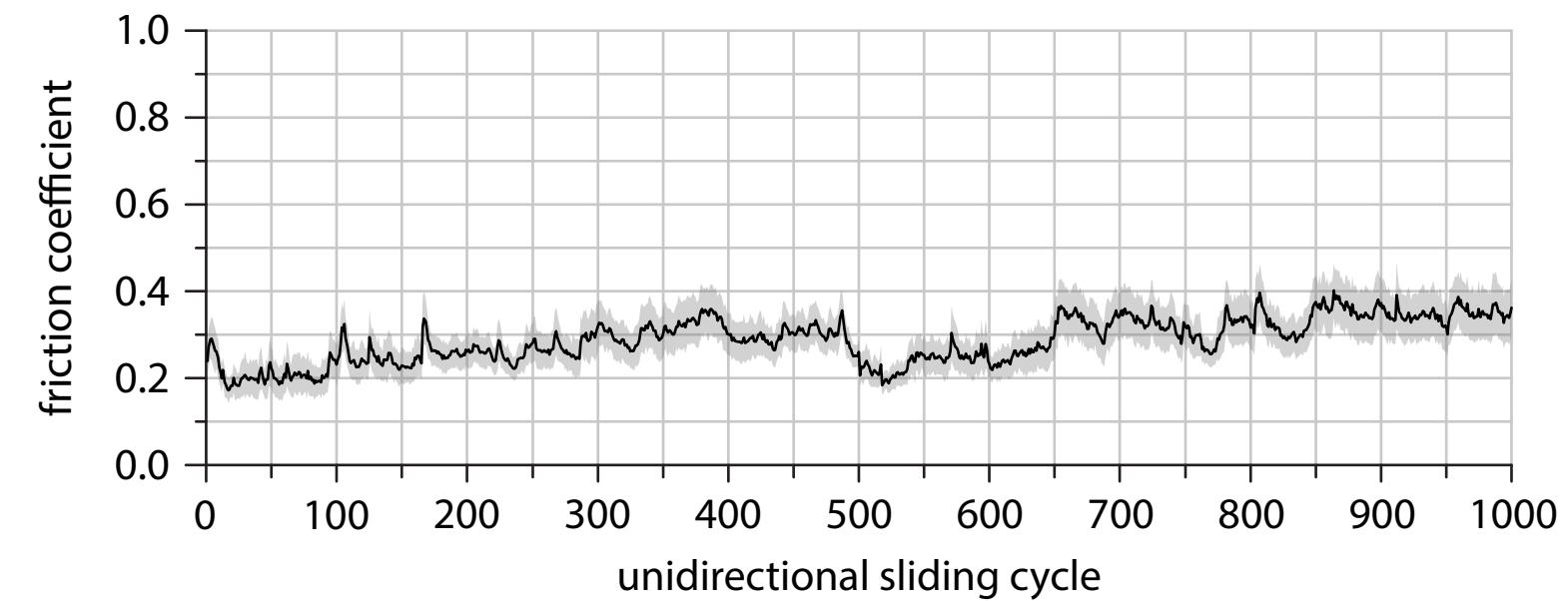
Now using 5 vol. % ZnO, sapphire ball radius of 1.59 mm, and contact force of 1N

Wear comparison of electroplated hard gold and Au-ZnO -- against sapphire

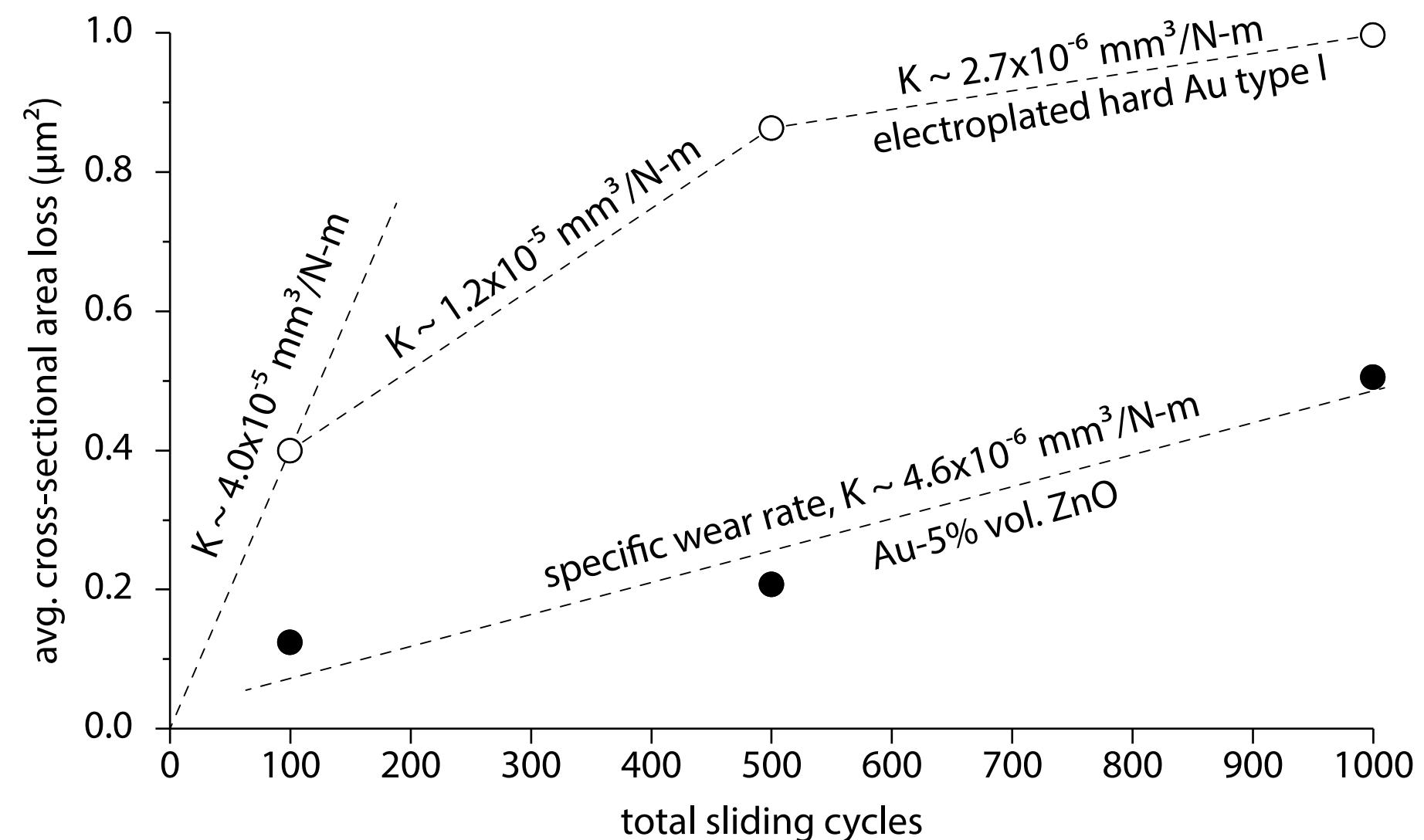
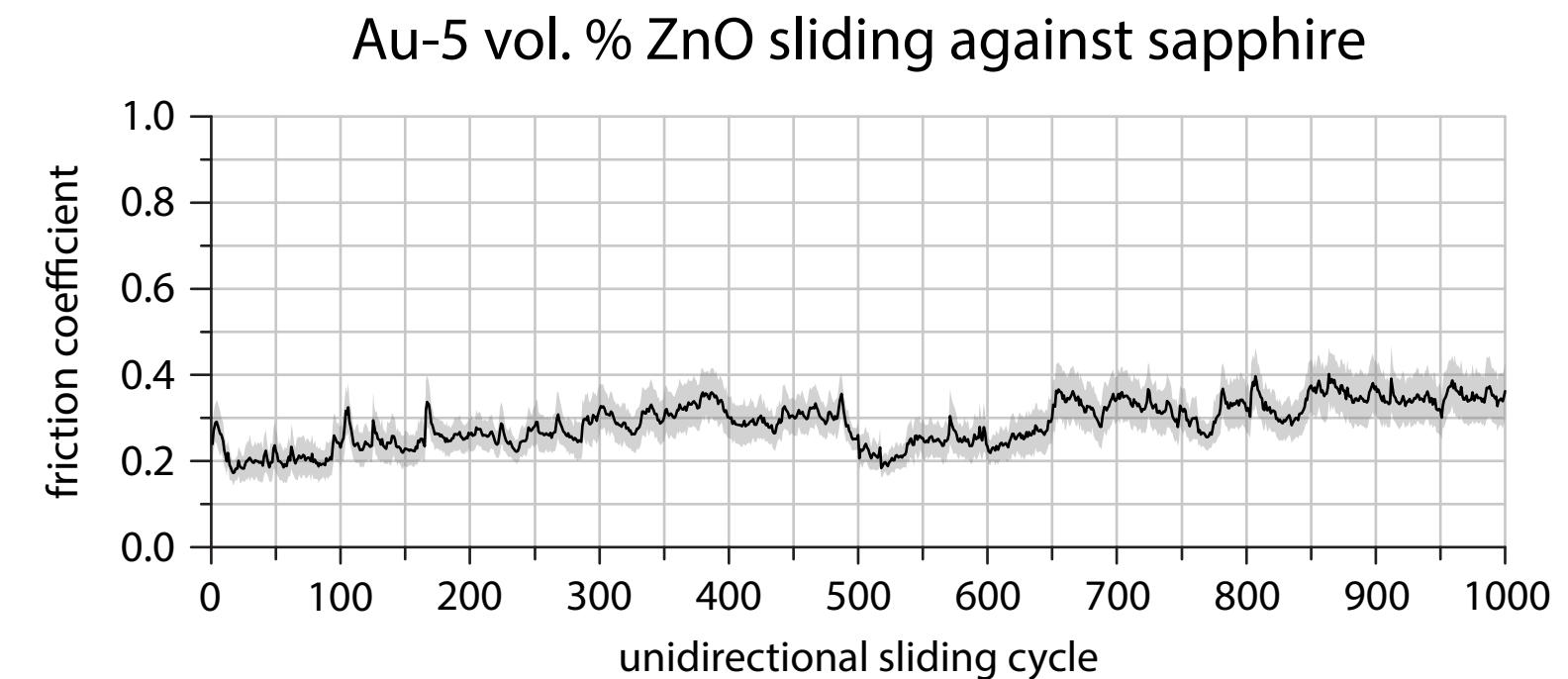
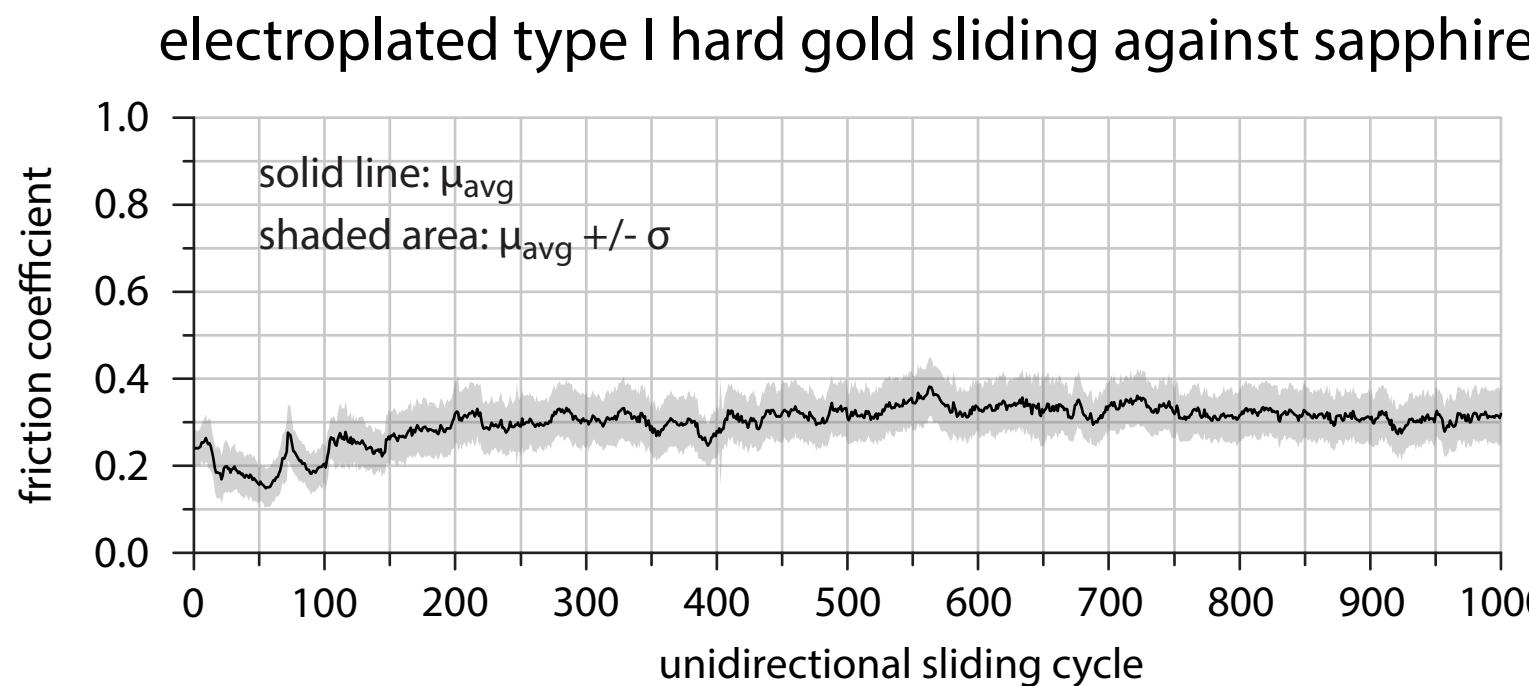
electroplated type I hard gold sliding against sapphire



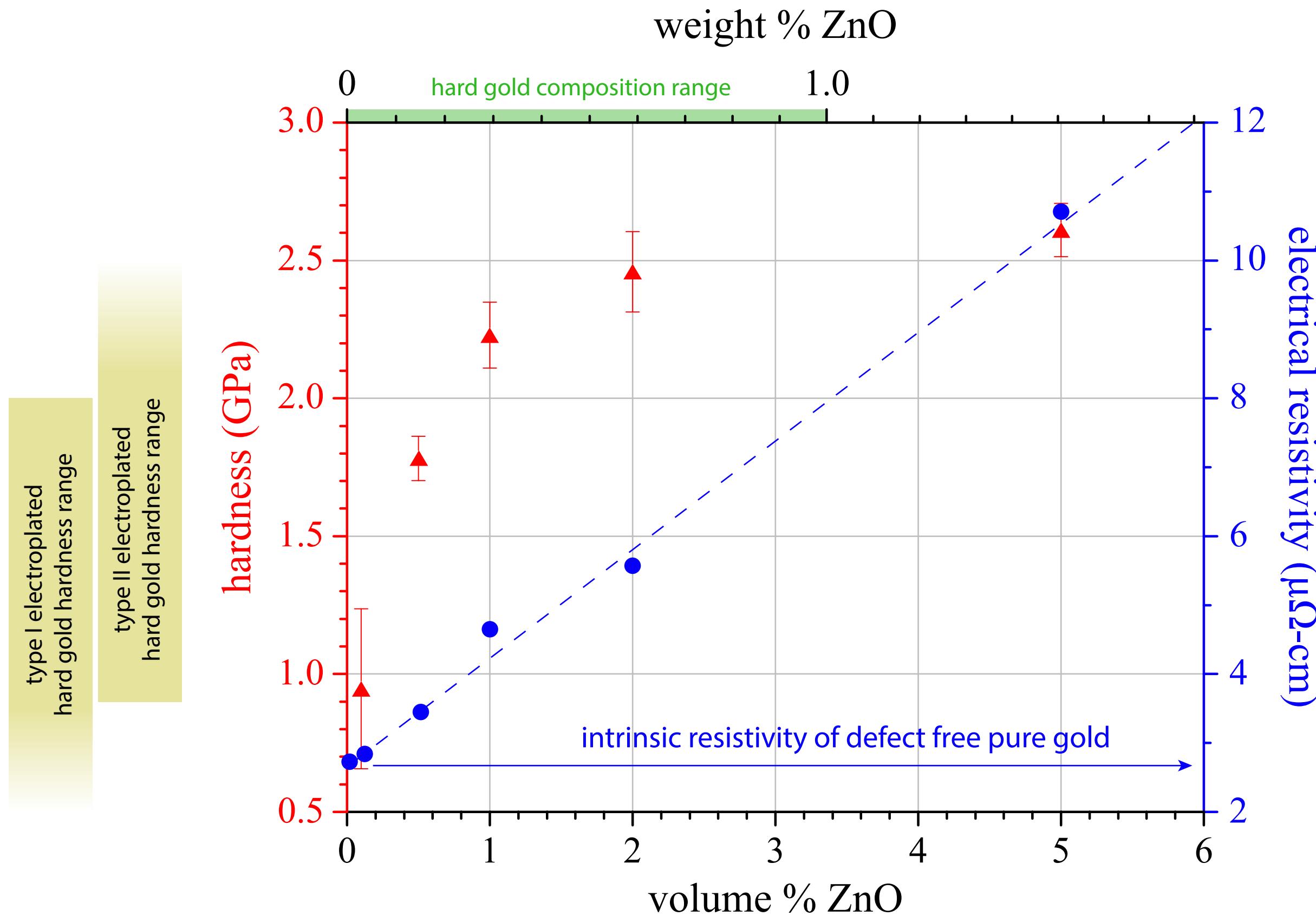
Au-5 vol. % ZnO sliding against sapphire



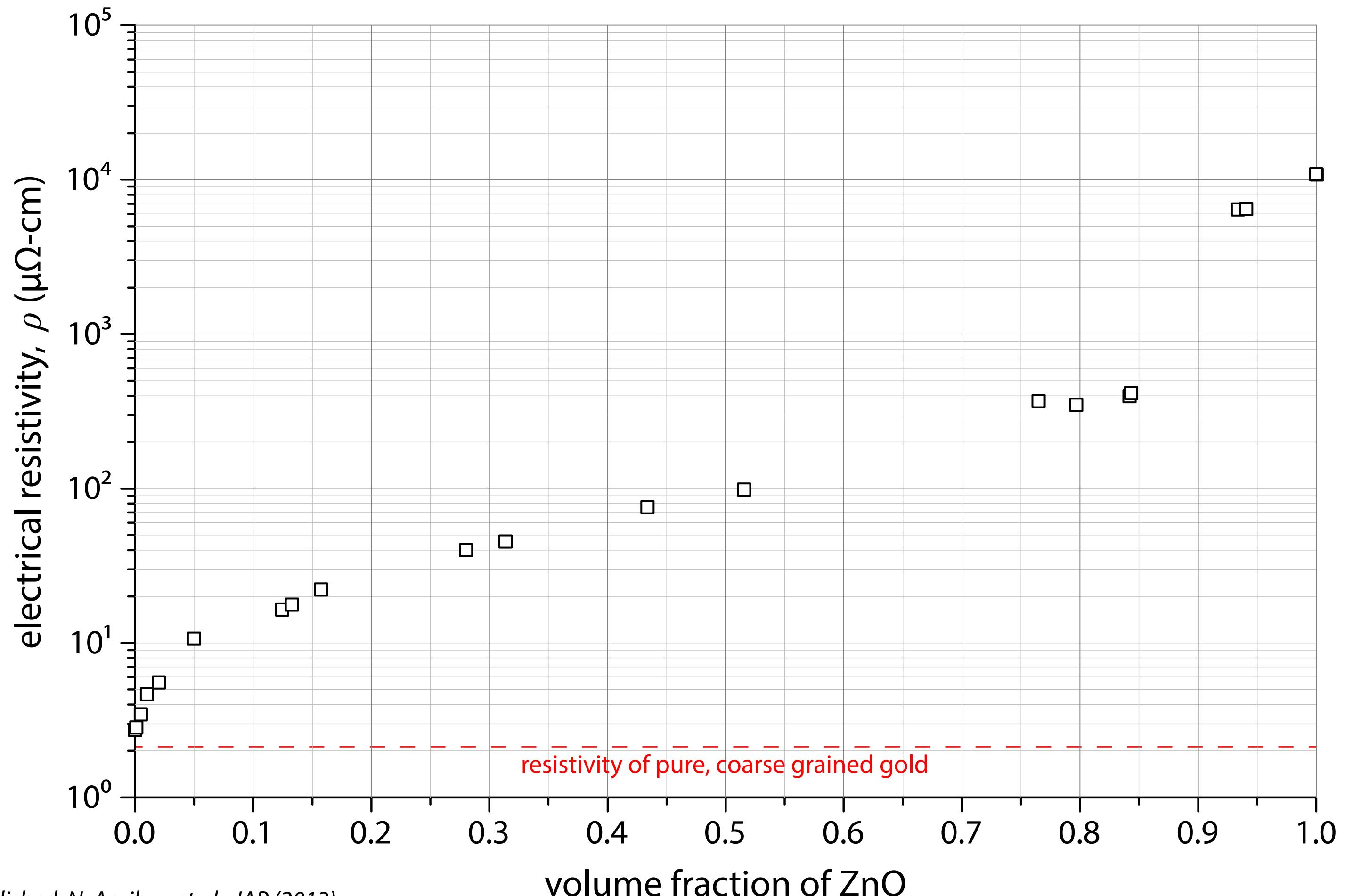
Au-ZnO nanocomposite shows similar wear behavior to electroplated hard Au



Hardness and electrical resistivity increase as function of composition

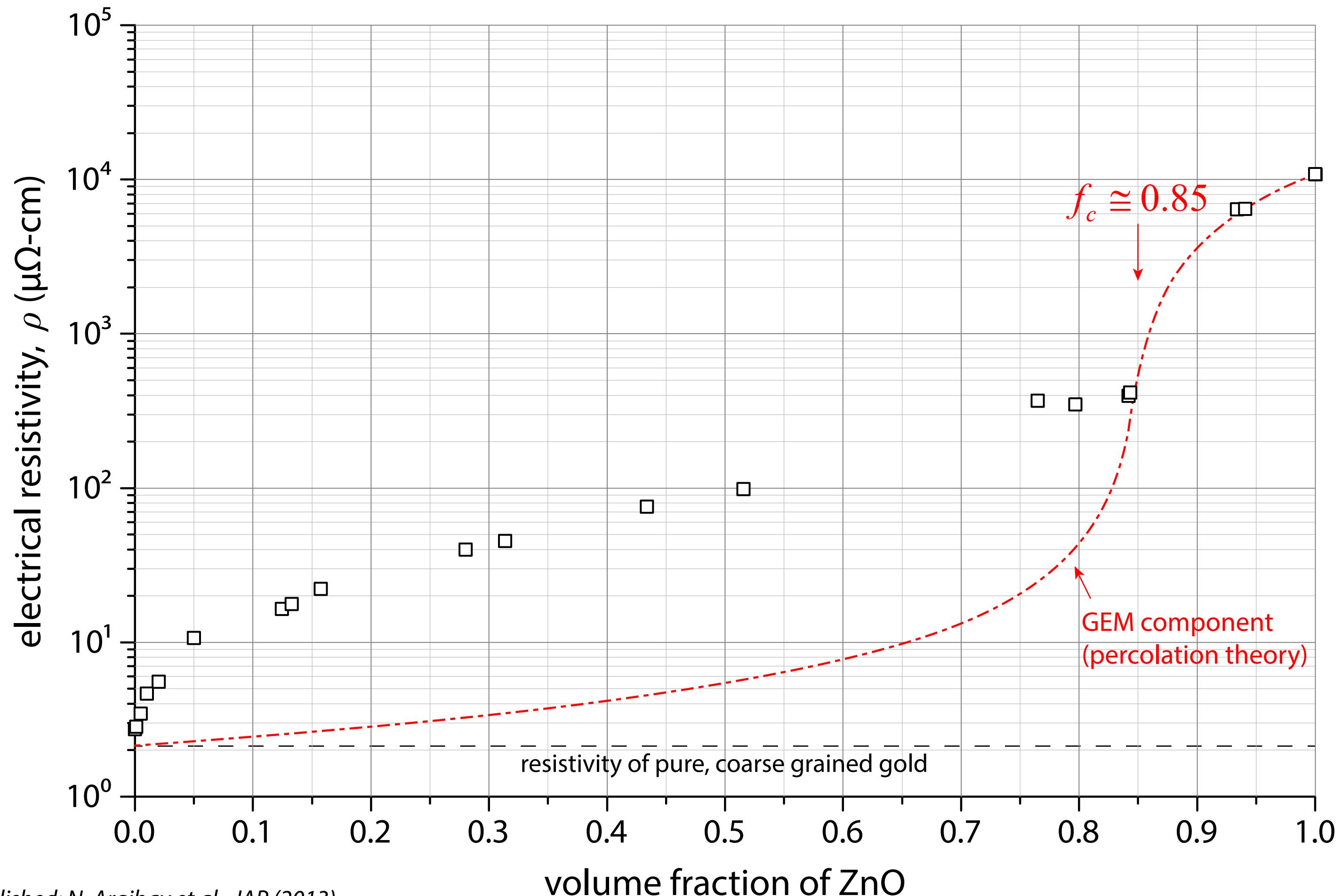


Au-ZnO Resistivity: combination of electron scattering at GBs and percolation theory



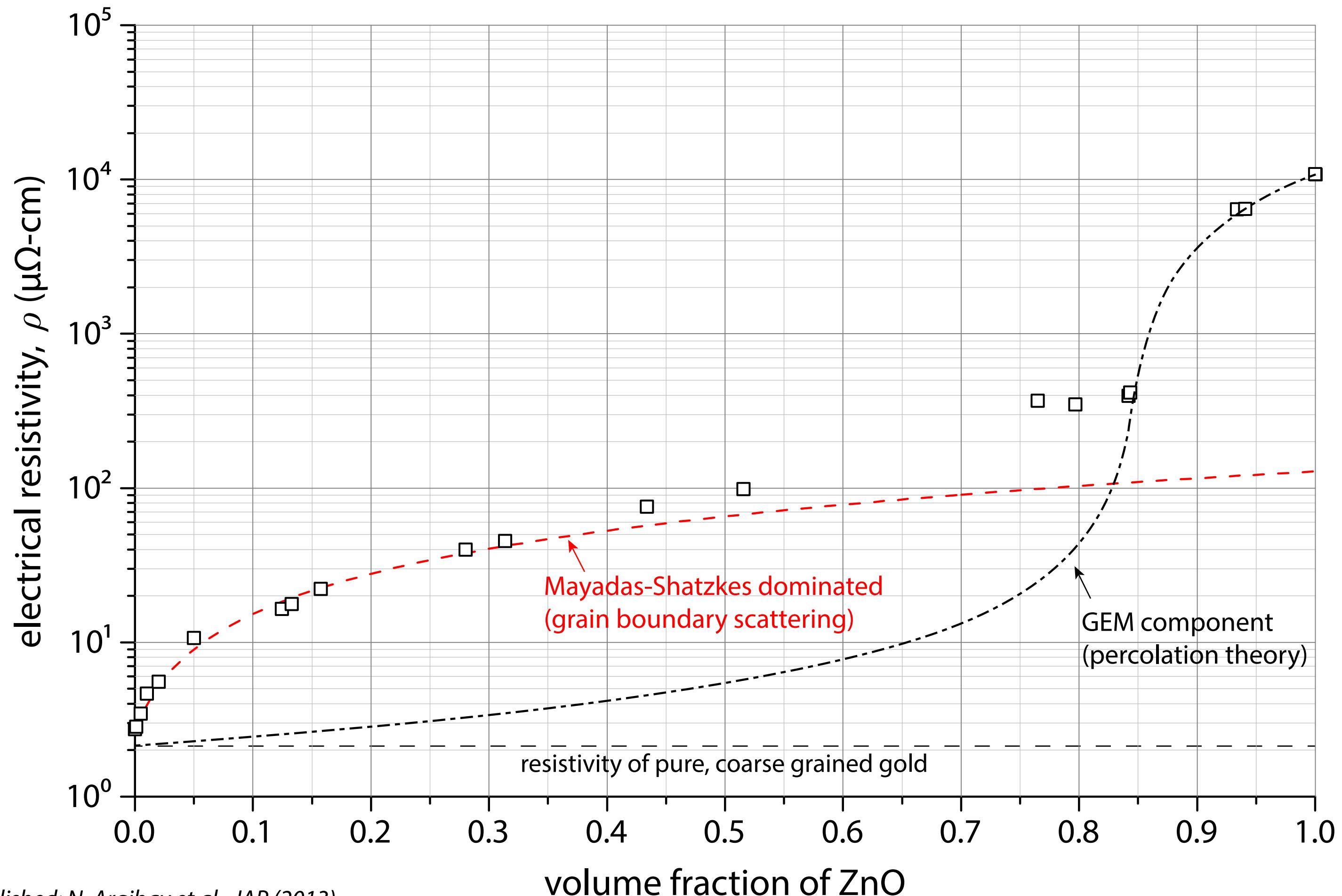
Published: N. Argibay et al., JAP (2013)

Au-ZnO Resistivity: combination of electron scattering at GBs and percolation theory



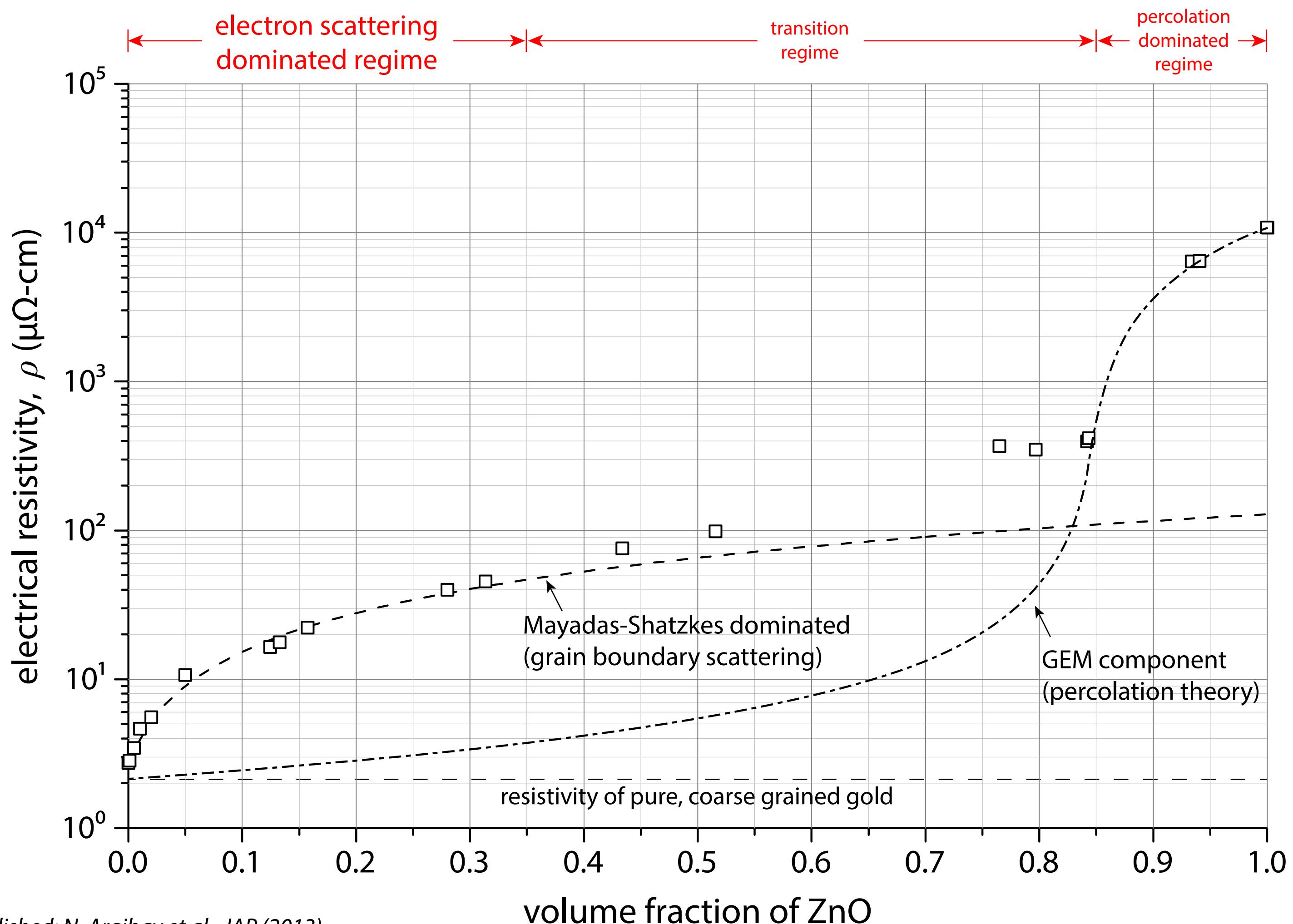
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Au-ZnO Resistivity: combination of electron scattering at GBs and percolation theory



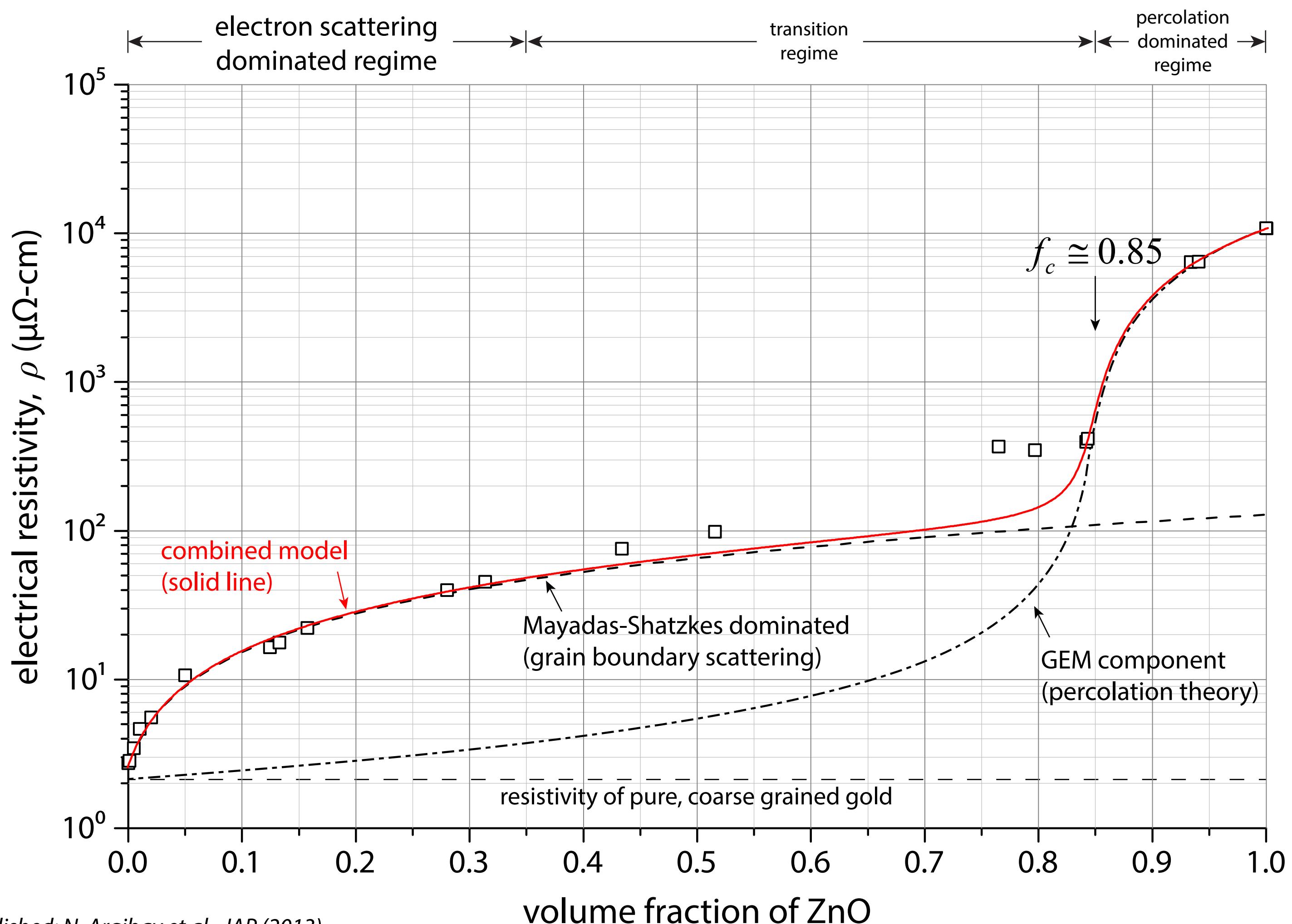
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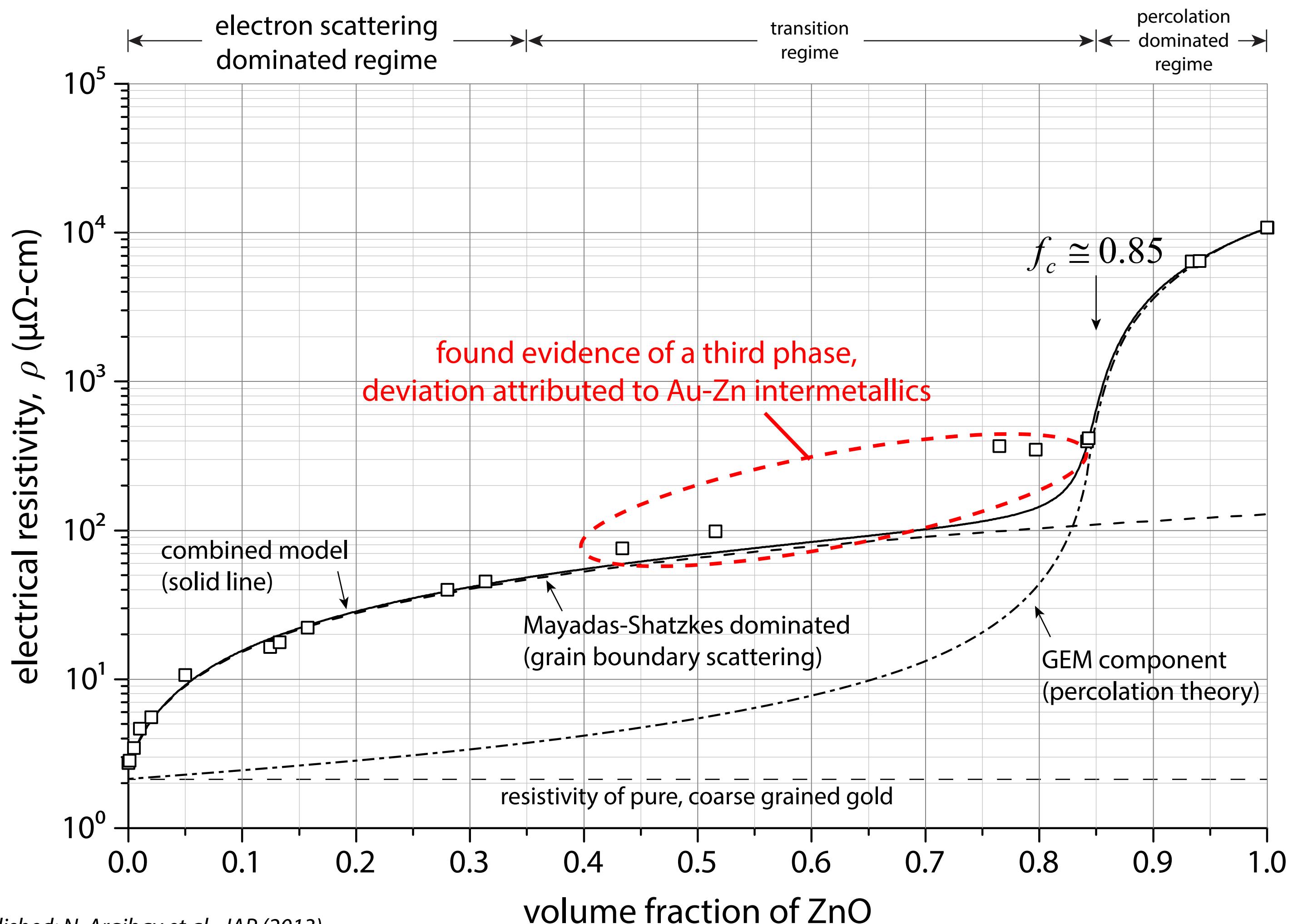


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Au-ZnO Resistivity: combination of electron scattering at GBs and percolation theory



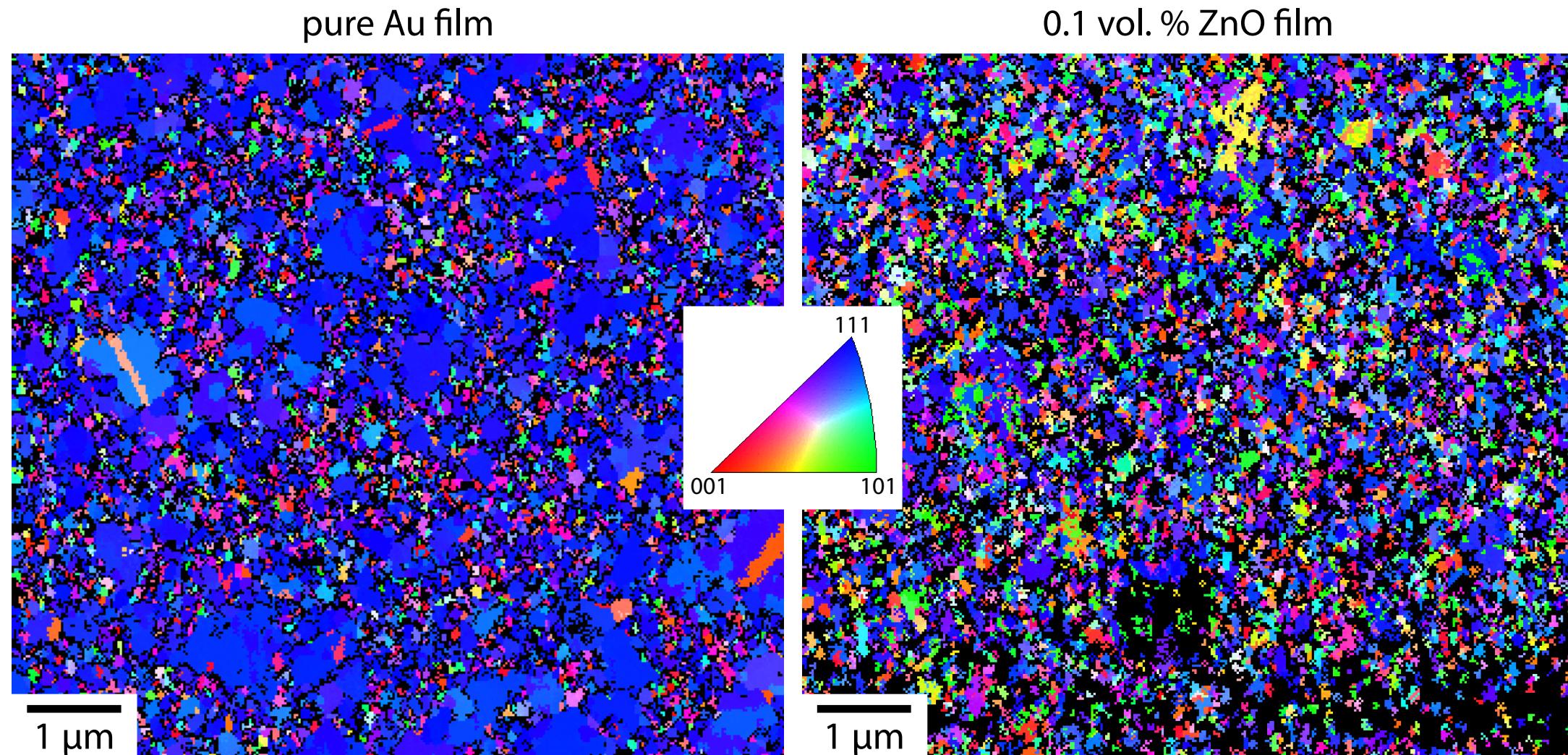
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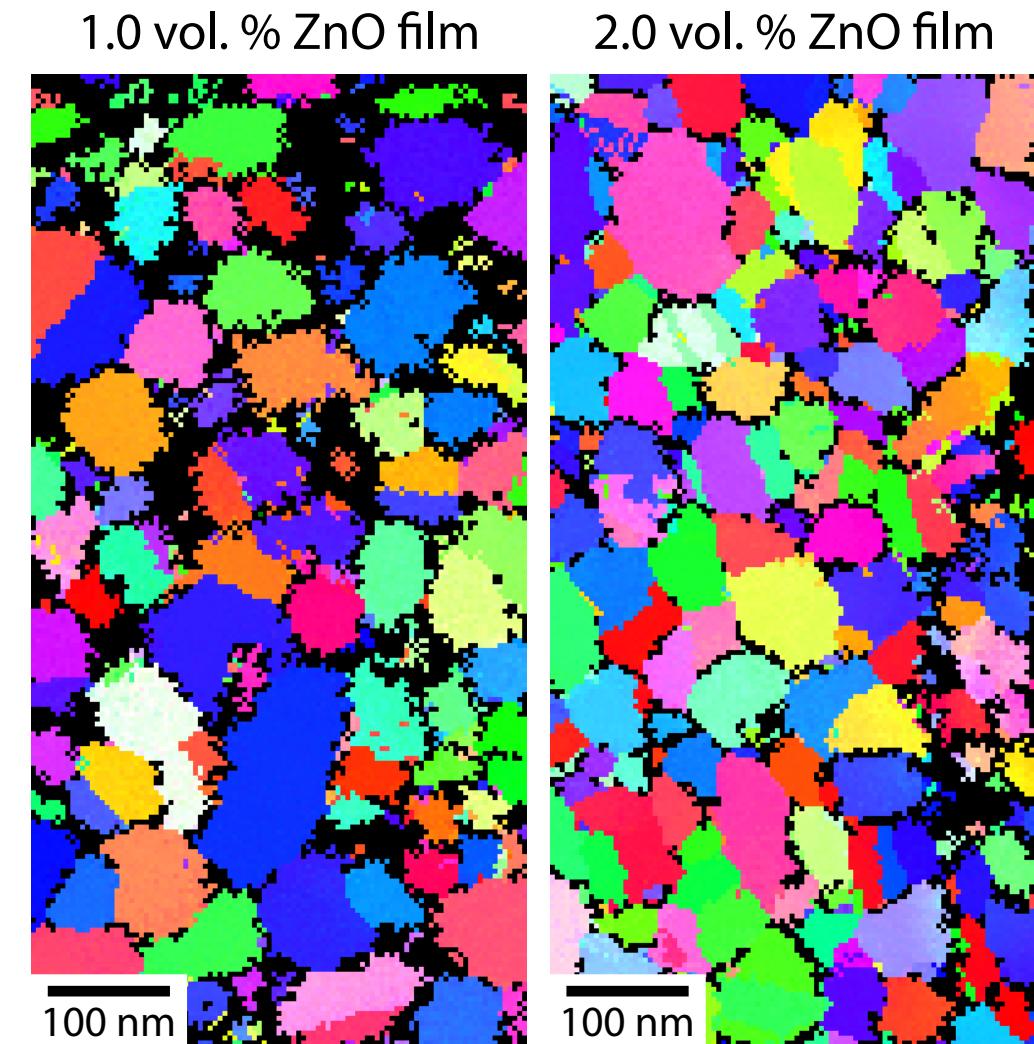
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Determination of grain size with varying composition via microscopy

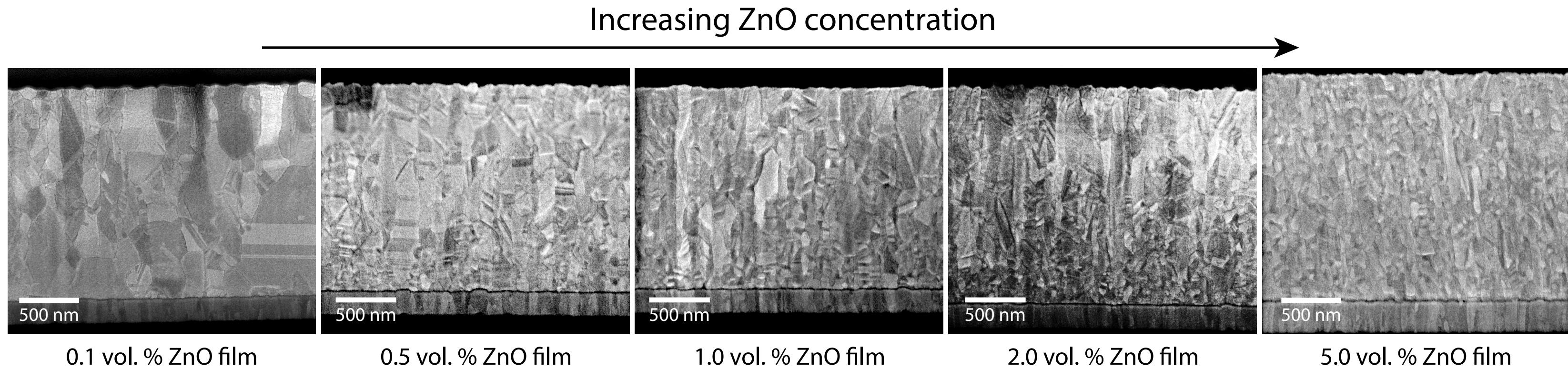
Film surface-normal EBSD mapping:



***Transmission* Kikuchi diffraction:**



SEM of FIB milled and etched cross-sectional views:



(XRD was inconclusive)

High throughput indirect method -- correlation b/w electrical resistivity/grain size

Mayadas-Shatzkes model (electron scattering at GBs):

$$\frac{\rho}{\rho_o} = \left[1 - \frac{3}{2} \alpha + 3\alpha^2 - 3\alpha^3 \ln\left(1 + \frac{1}{\alpha}\right) \right]^{-1}$$

Scattering parameter:

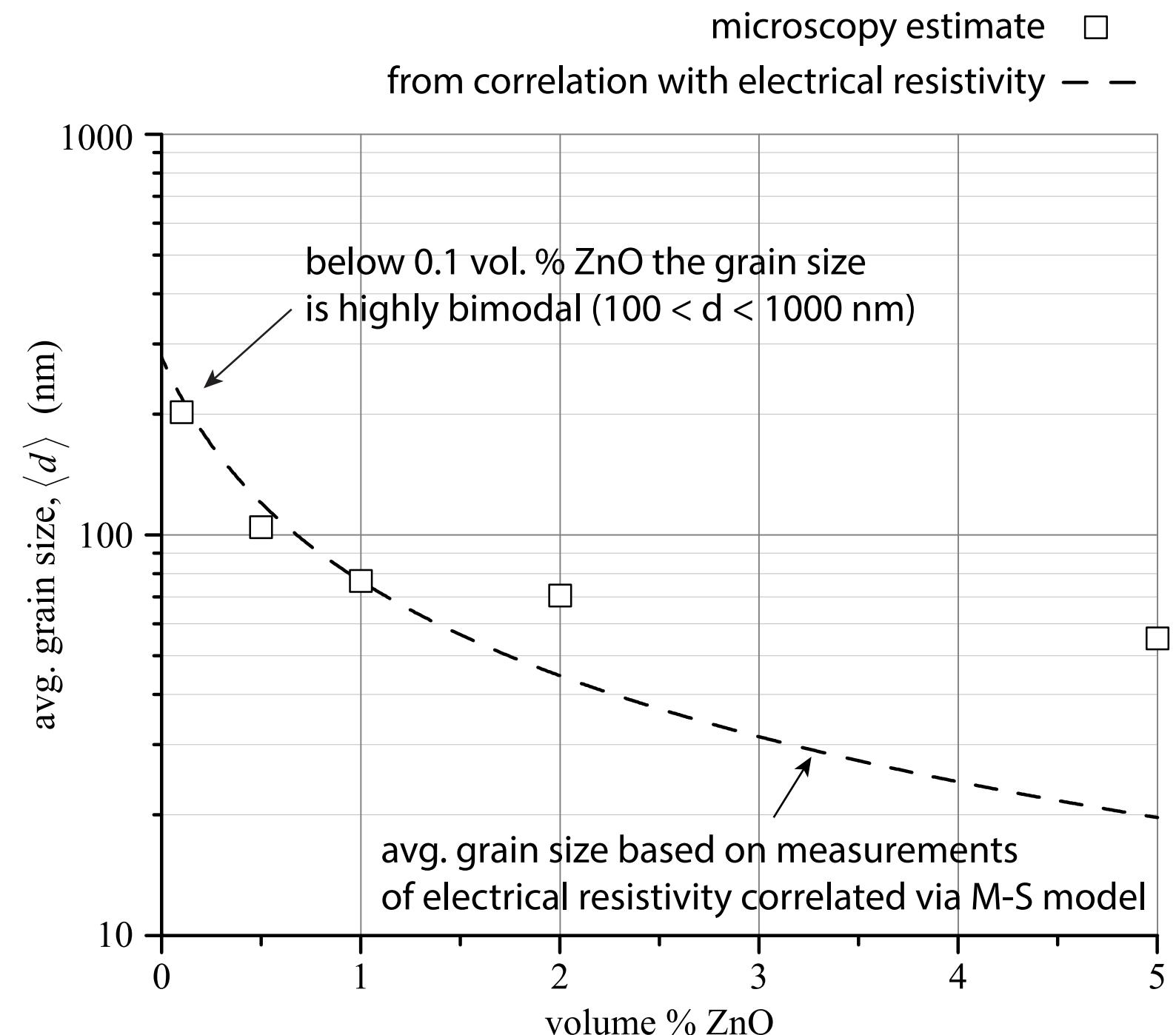
$$\alpha = \frac{\lambda}{d} \frac{R}{1-R}$$

Empirical relationship between scattering parameter and composition is linear:

$$\alpha = 43.19f + 0.165$$

Between 0 and 30 vol. % ZnO, M-S seems to fit well, corresponding to a range:

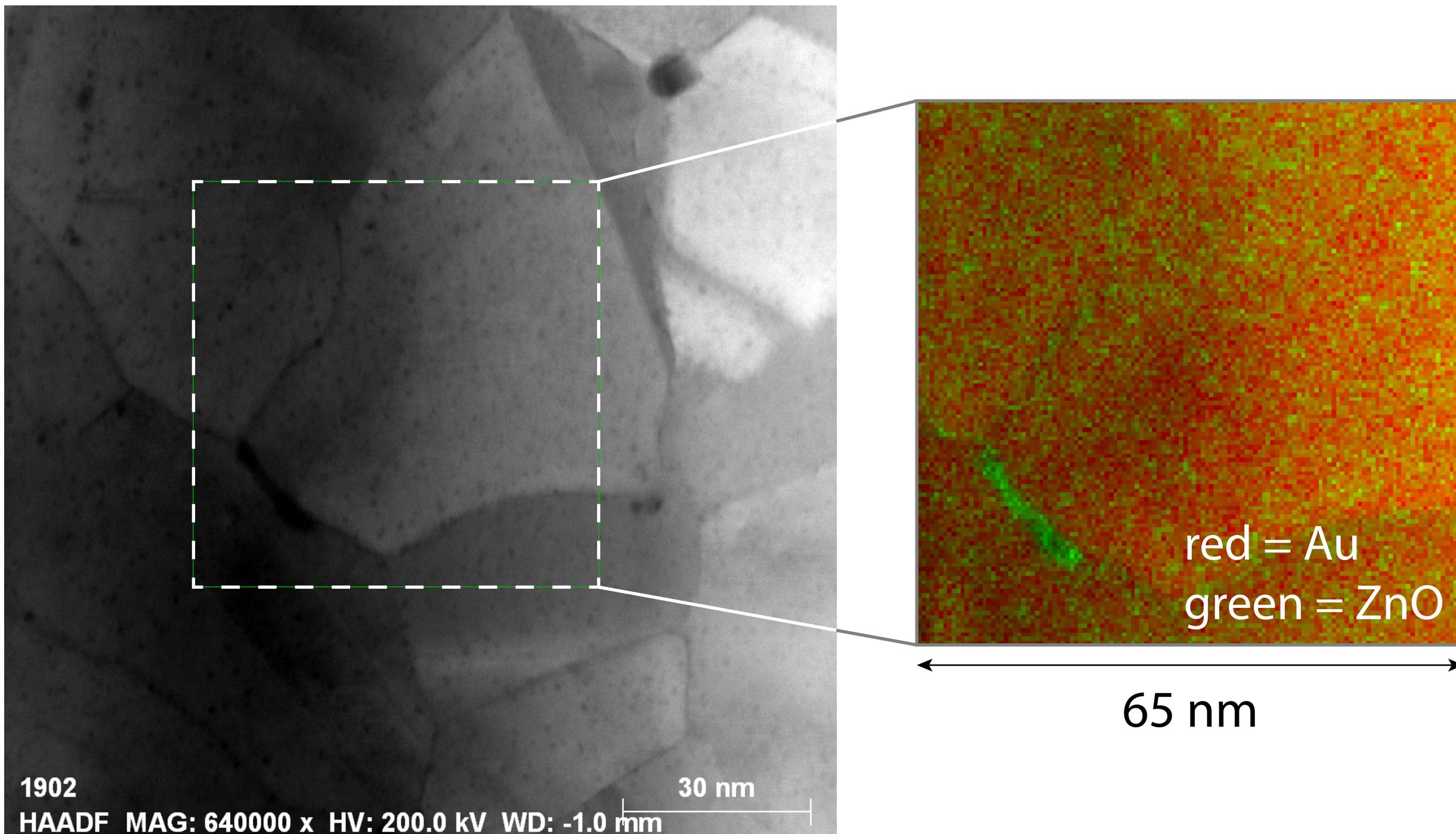
$$0.1 < \alpha < 10$$



Is it possible to confidently correlate grain size to resistivity via scattering parameter?

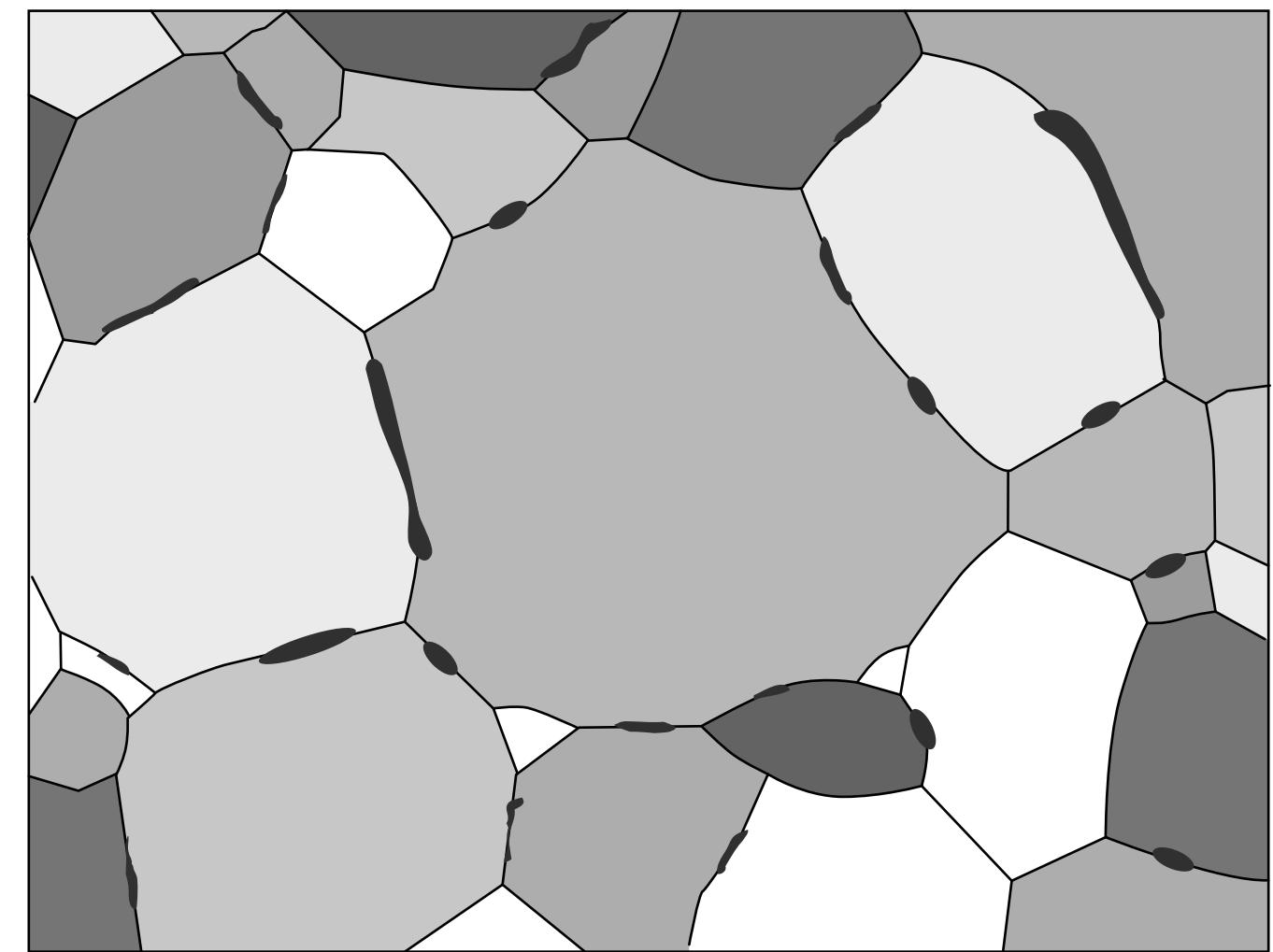
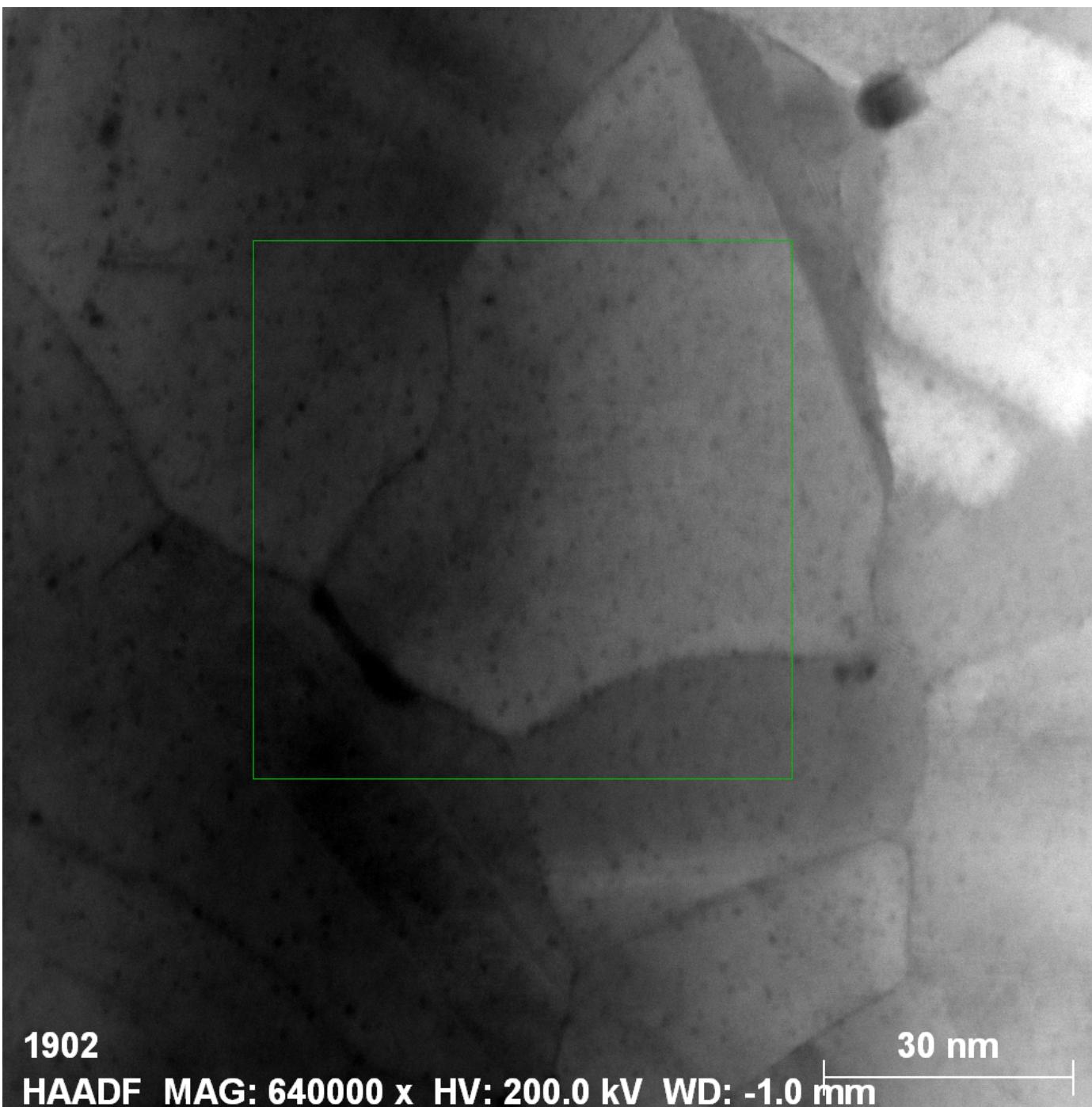
Film Surface-Planar STEM Composition Mapping -- Confirms GB Segregation

Cross-sectional composition map of a Au- 5 vol. % ZnO film showing grain boundary segregated ZnO in a Au matrix



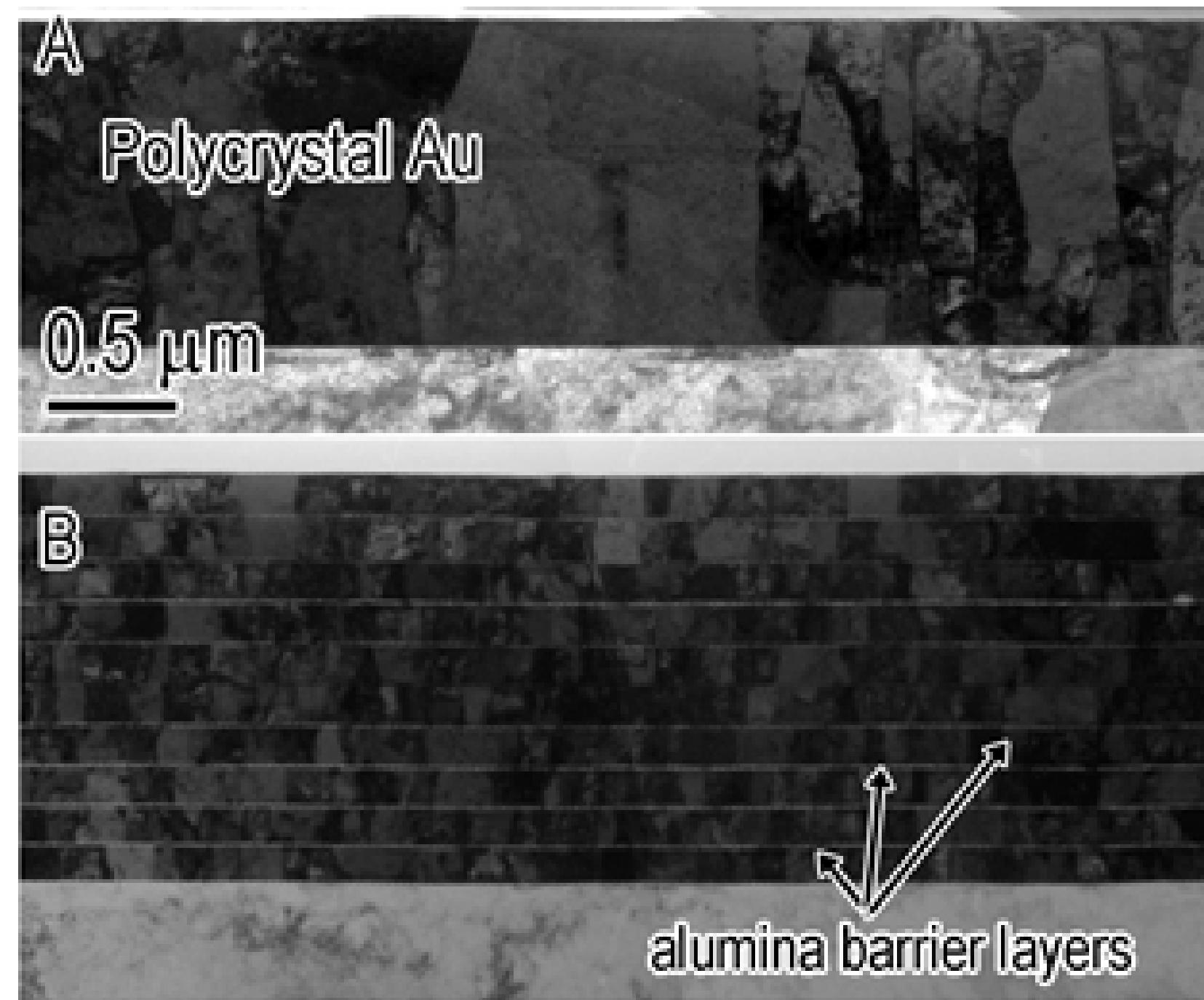
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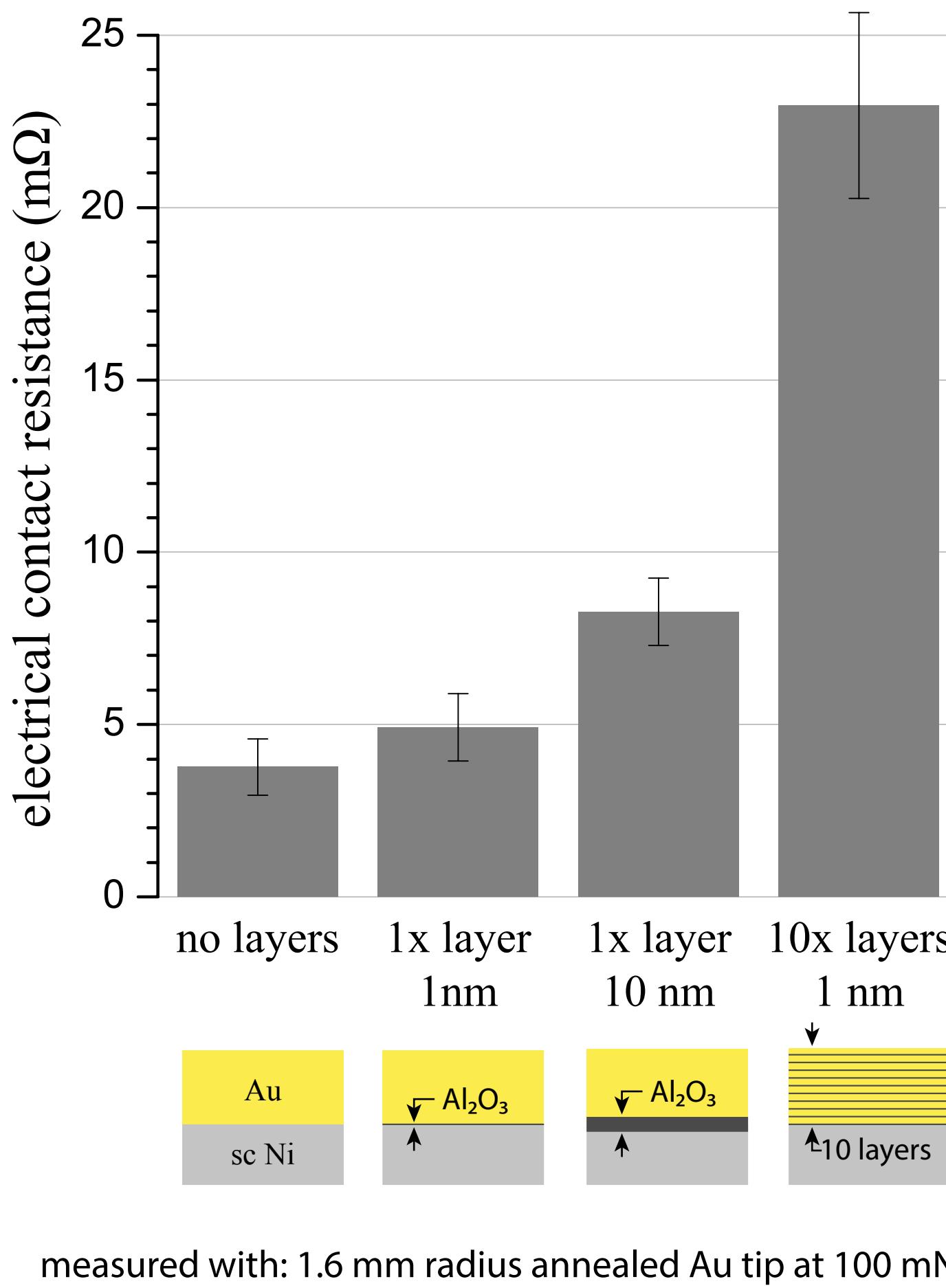
Investigation of ceramic diffusion barriers via pulsed laser deposition (PLD)

Au and Au/Al₂O₃ single and multi-layer films on PLD deposited onto single crystal nickel substrate

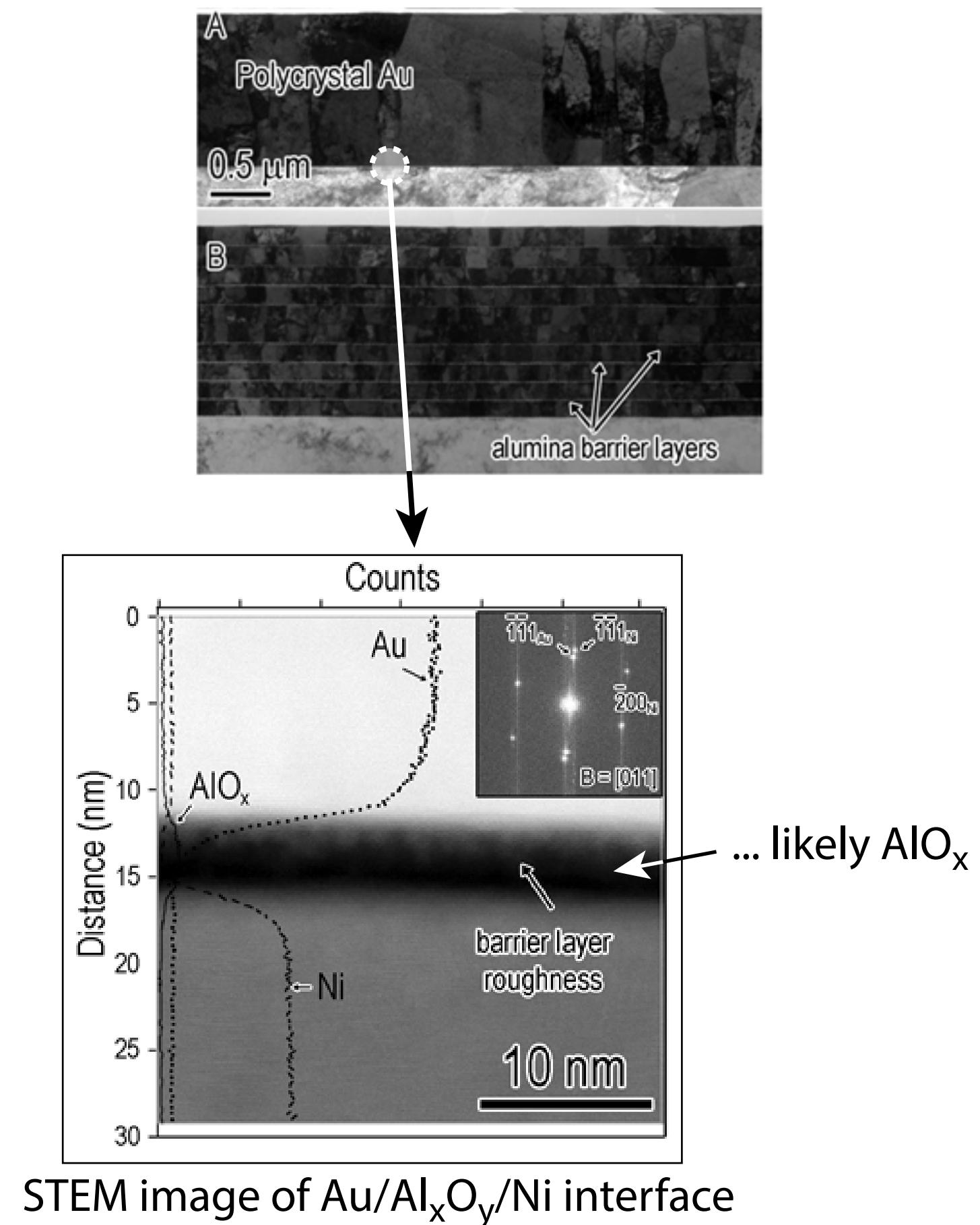


The ECR increase with oxide barrier (Al_2O_3) film was low

experimental data: contact resistance



Au and Au/ Al_2O_3 single and multi-layer films on PLD deposited onto single crystal nickel substrate



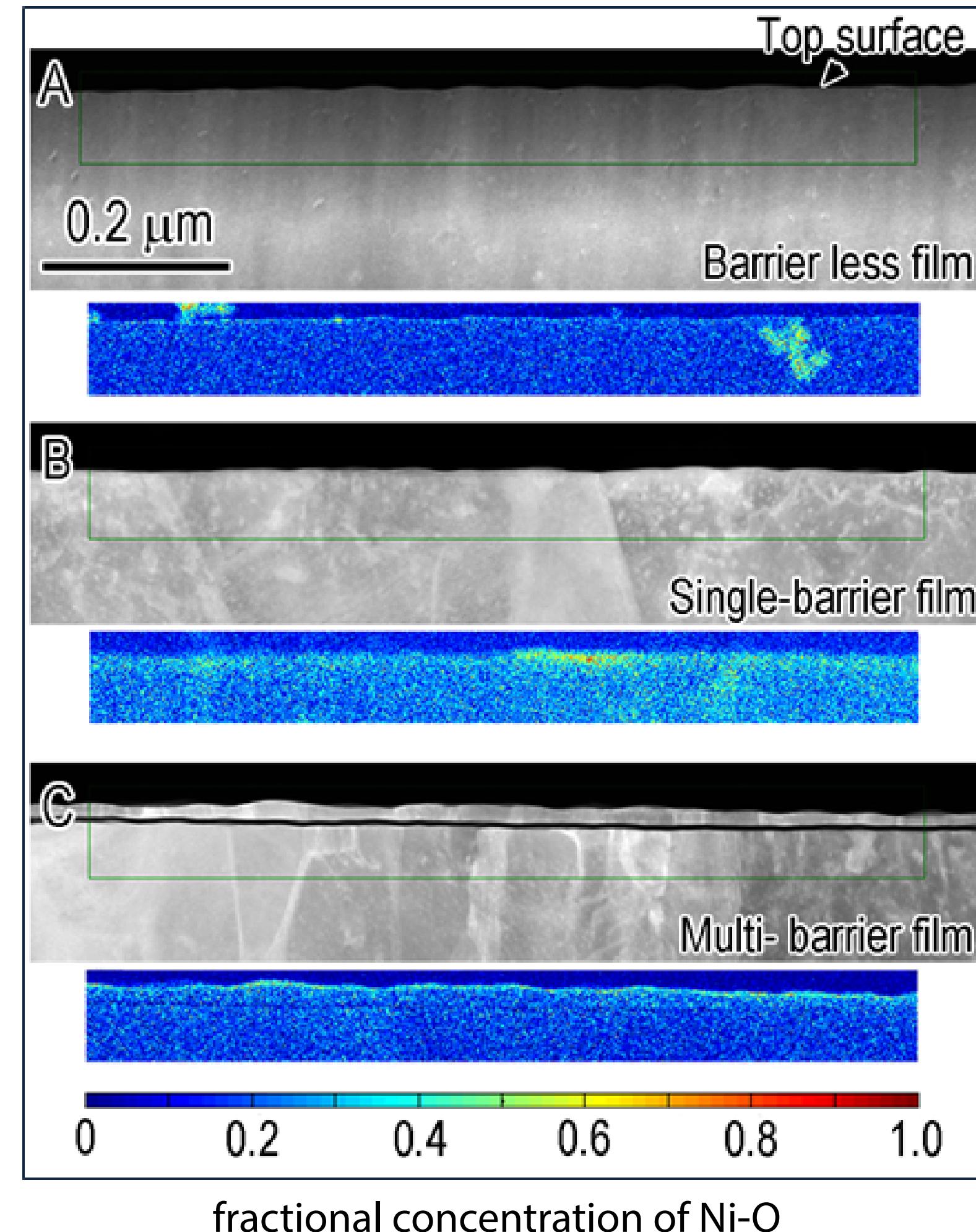
Surface accumulation of Ni reduced with alumina diffusion barrier layers

cross-section TEM of films after 5 day anneal at 250°C:

no barrier layer film,
but single crystal gold
(templated) top layer
on single crystal nickel
substrate

1 nm thick AlOx barrier
layer, polycrystal Au
top layer

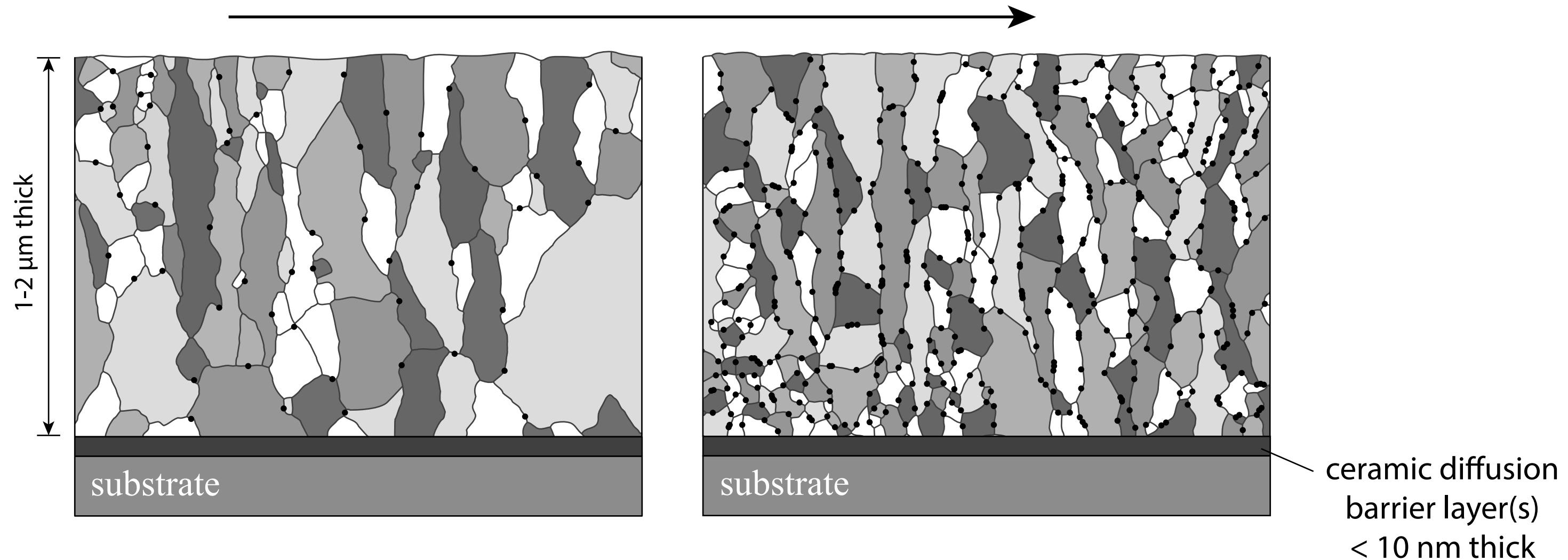
ten 1 nm thick AlOx
barrier layers,
polycrystal Au
top layer



Summary: E-beam codeposited Au-ceramic films and graded/layered structures

Nanocrystalline noble metal tribofilms strengthened via GB segregated codeposited ceramic phase(s)

reduced grain size (strengthening) with increasing ceramic phase concentration



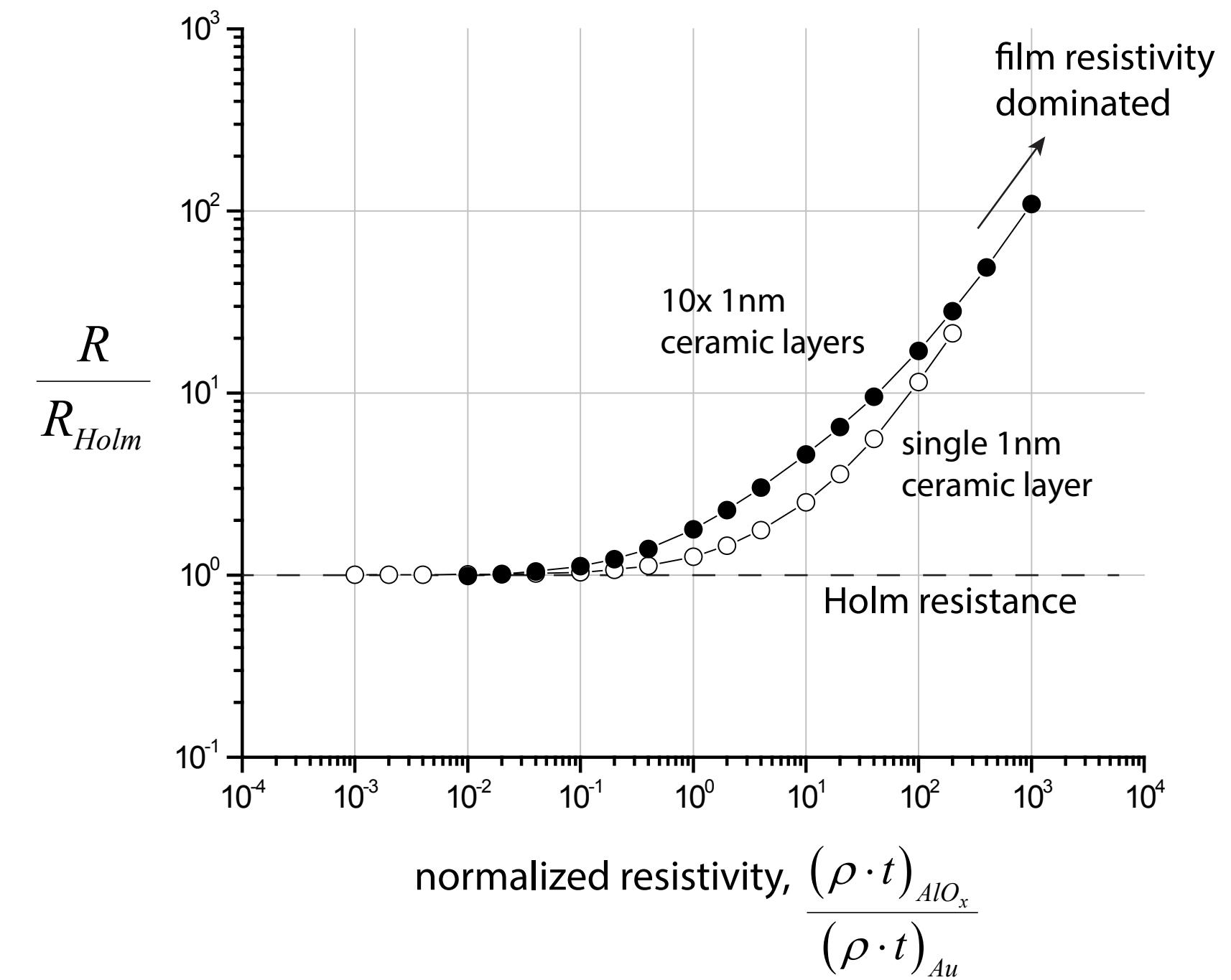
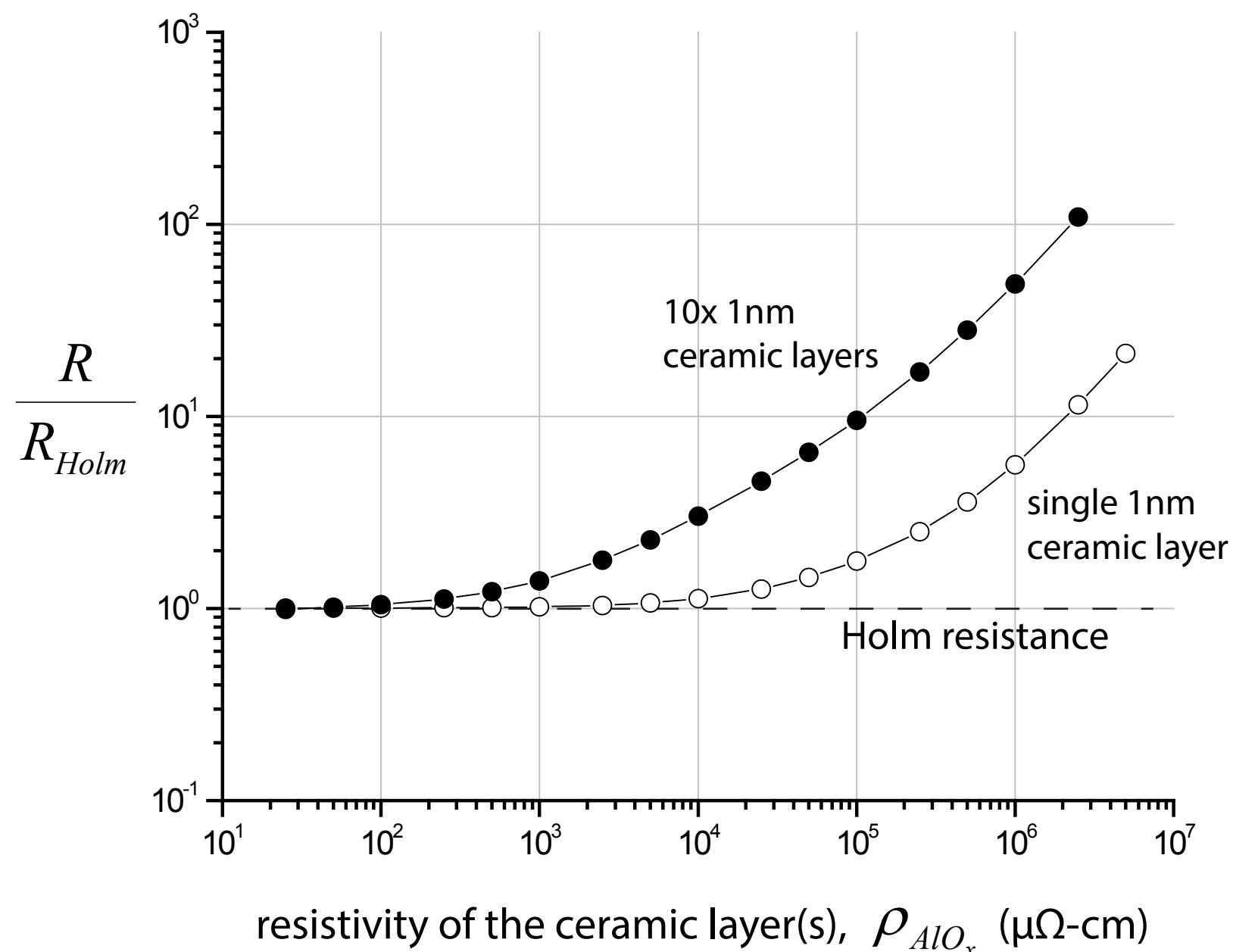
Acknowledgments

Rand Garfield for tribological test specimen preparation

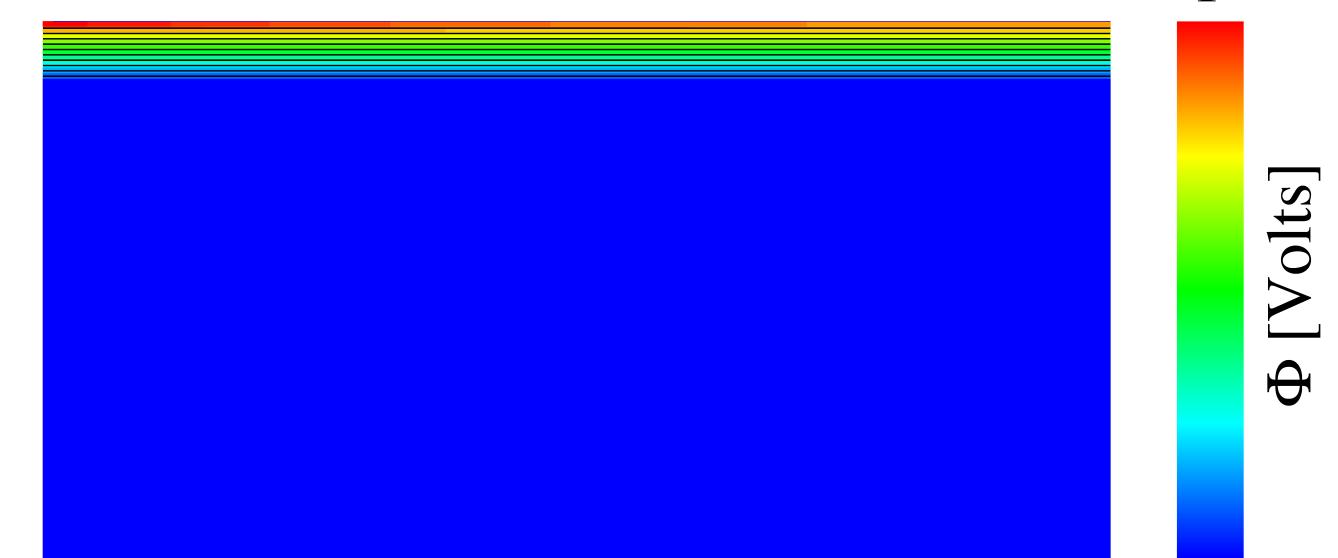
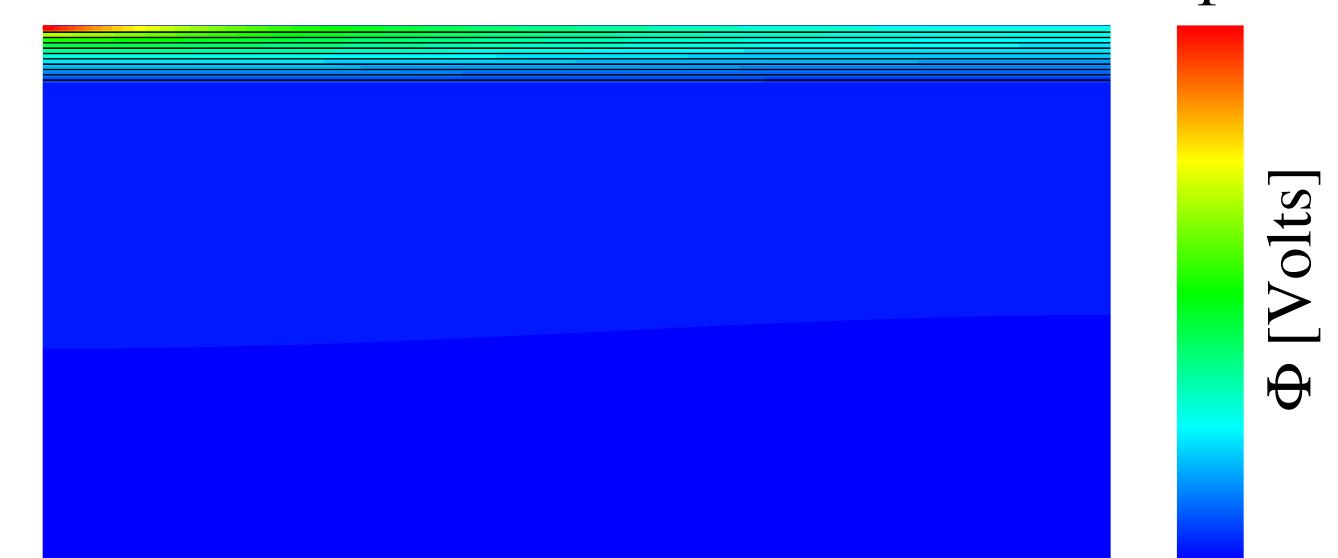
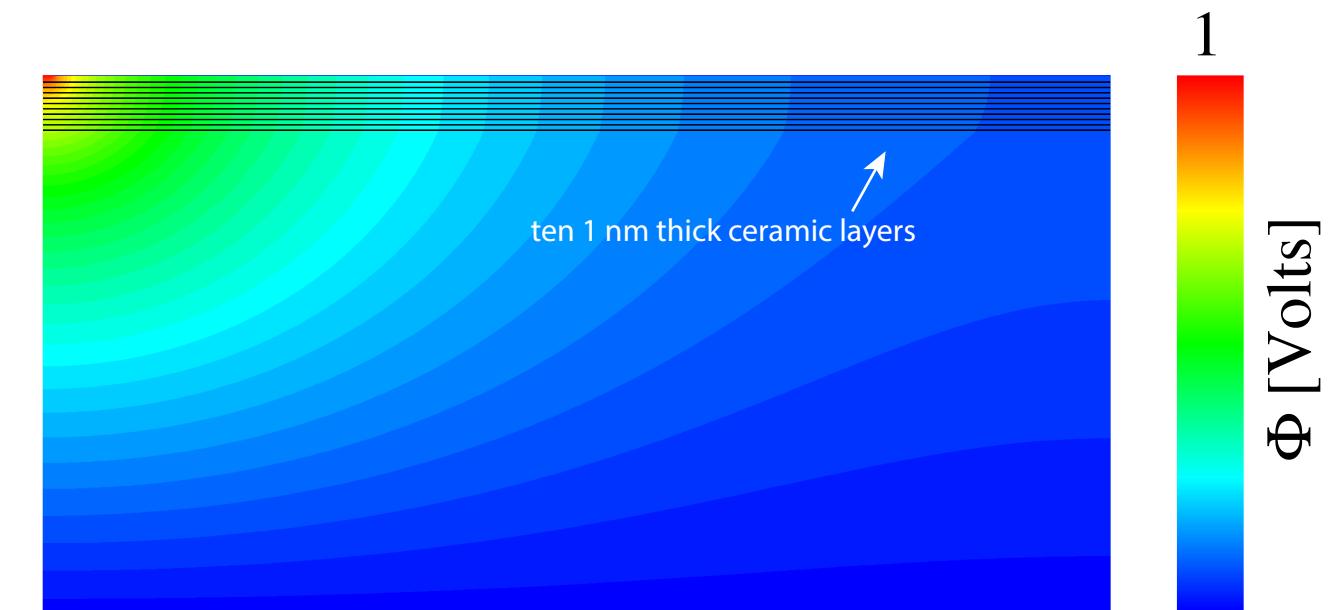
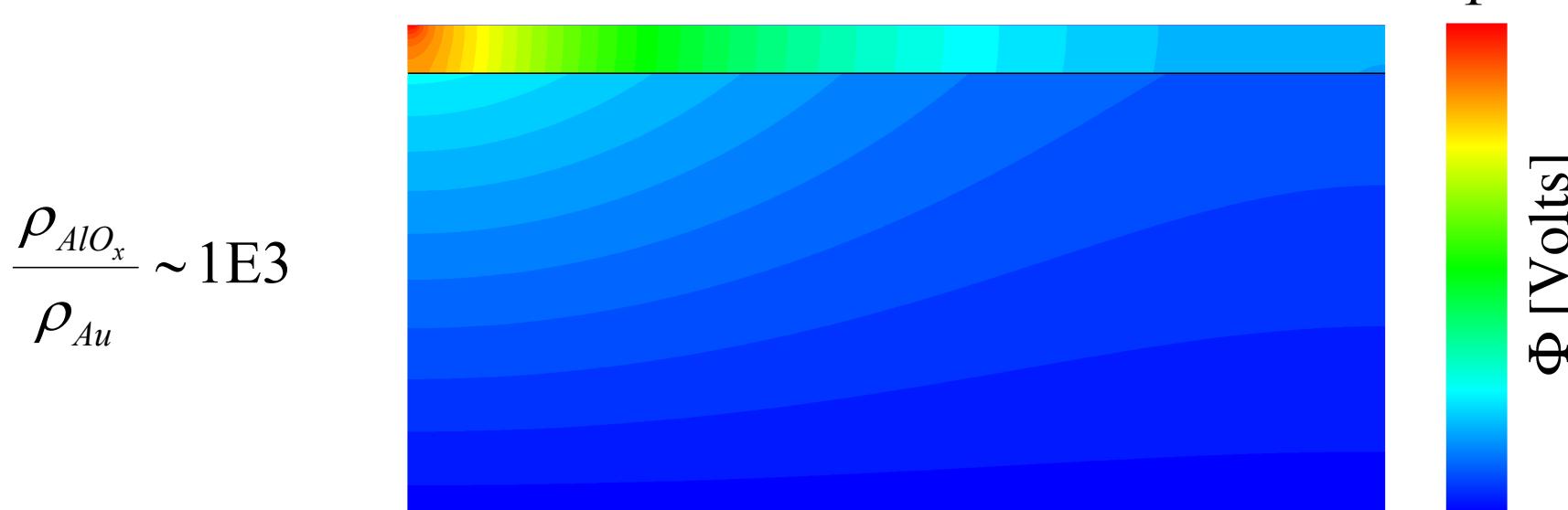
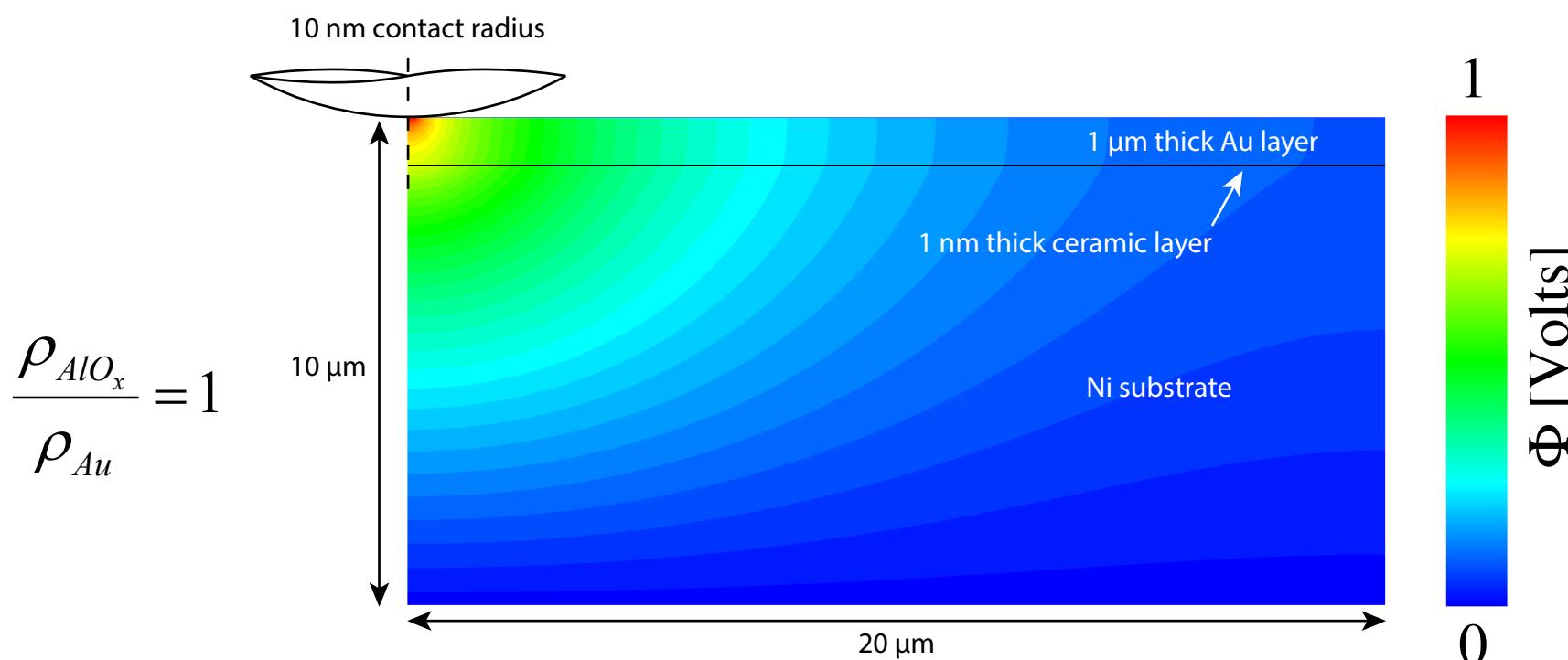
Bonnie McKenzie for SEM-EDS imaging

Michael Rye for diffraction composition mapping

Finite element modeling prediction of resistivity

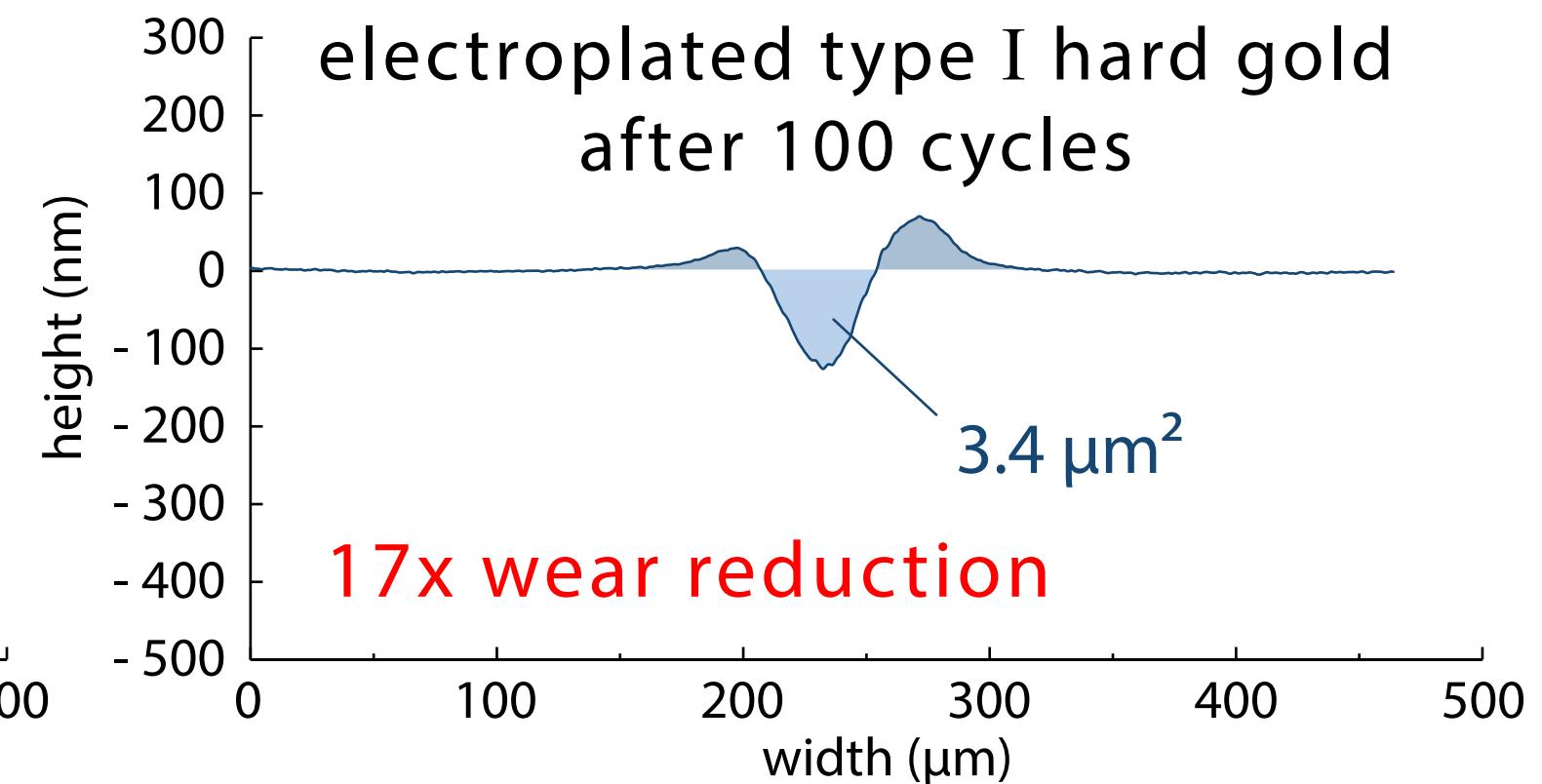
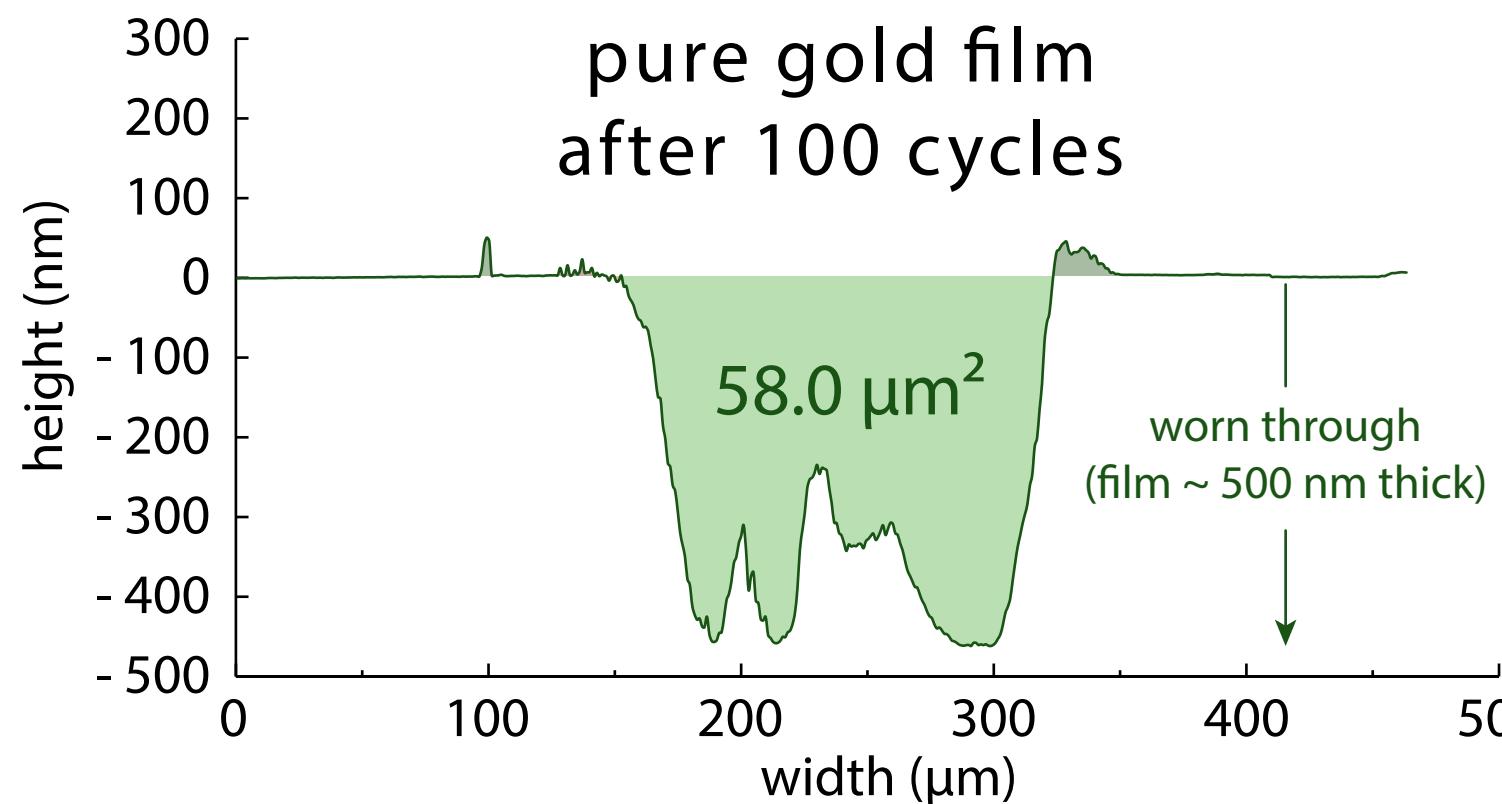


FEM isopotential maps

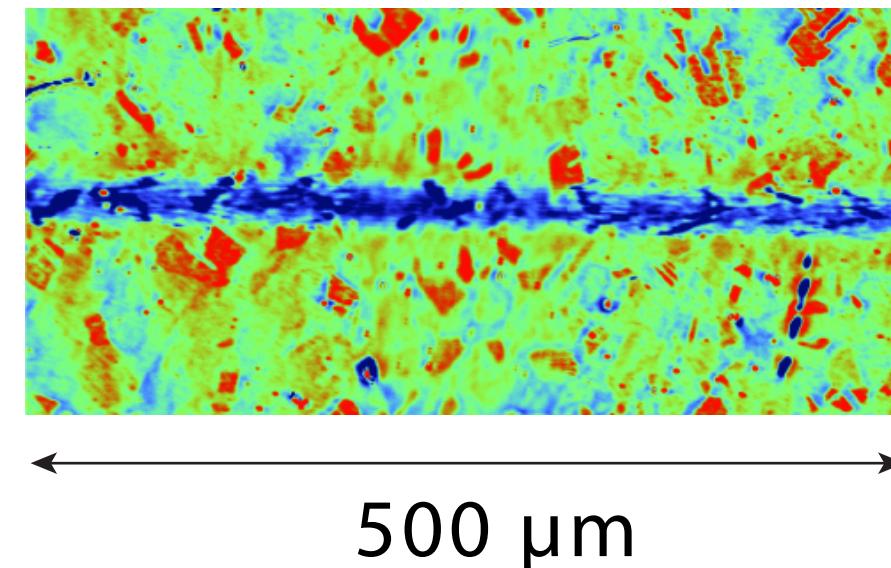


Hard gold is also highly wear resistant

average wear track cross-section in same sliding conditions against Neyoro G rider:

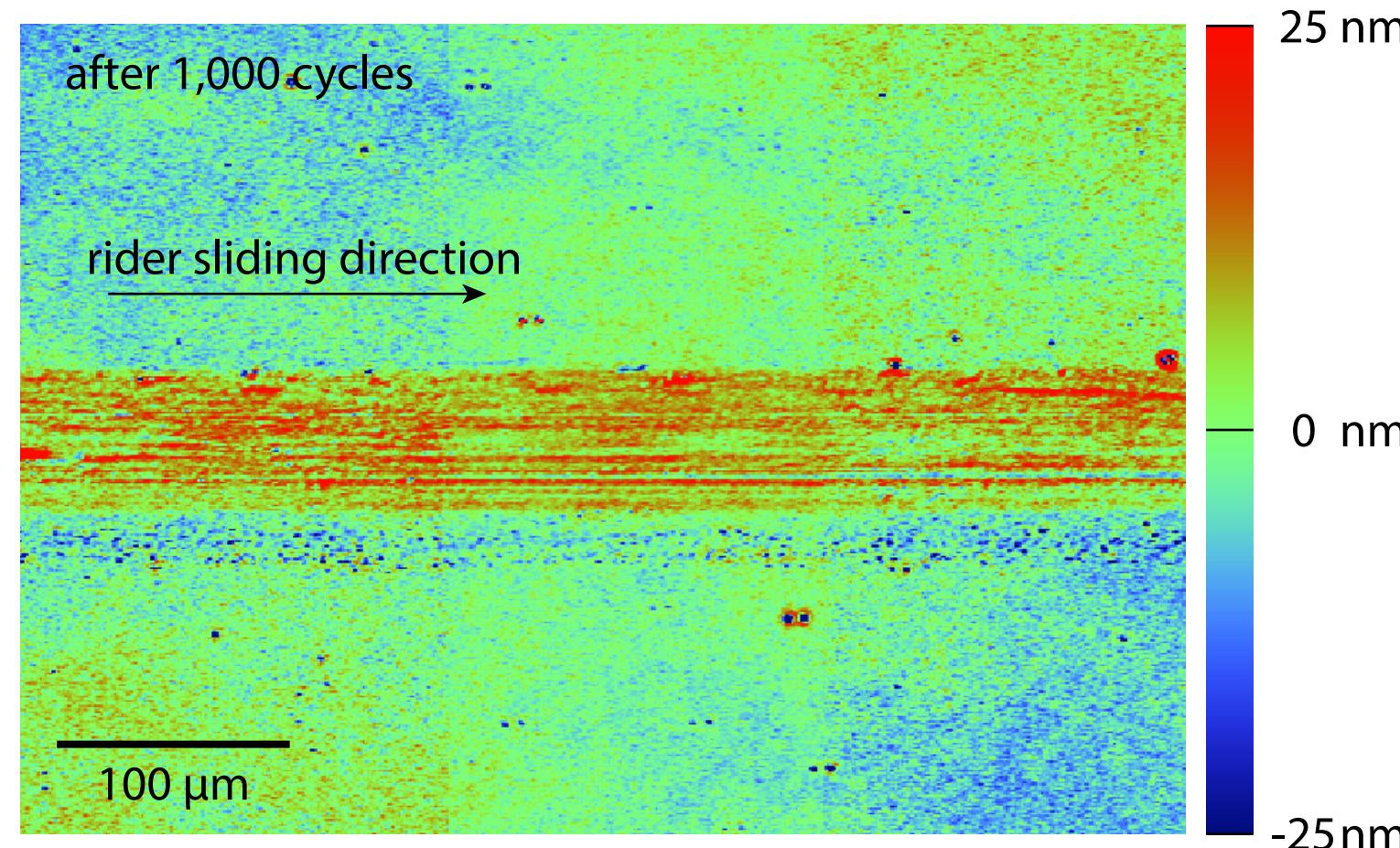
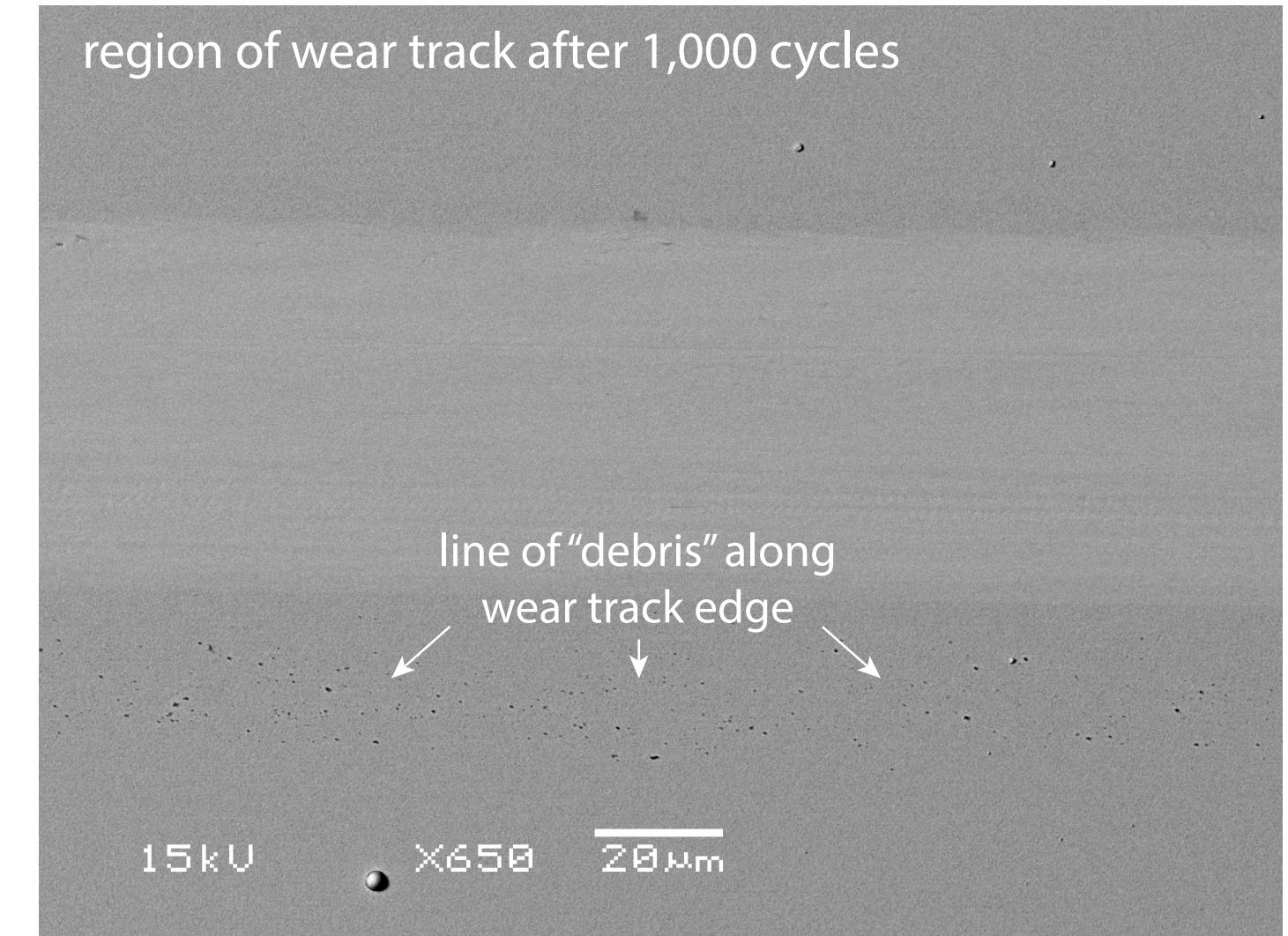
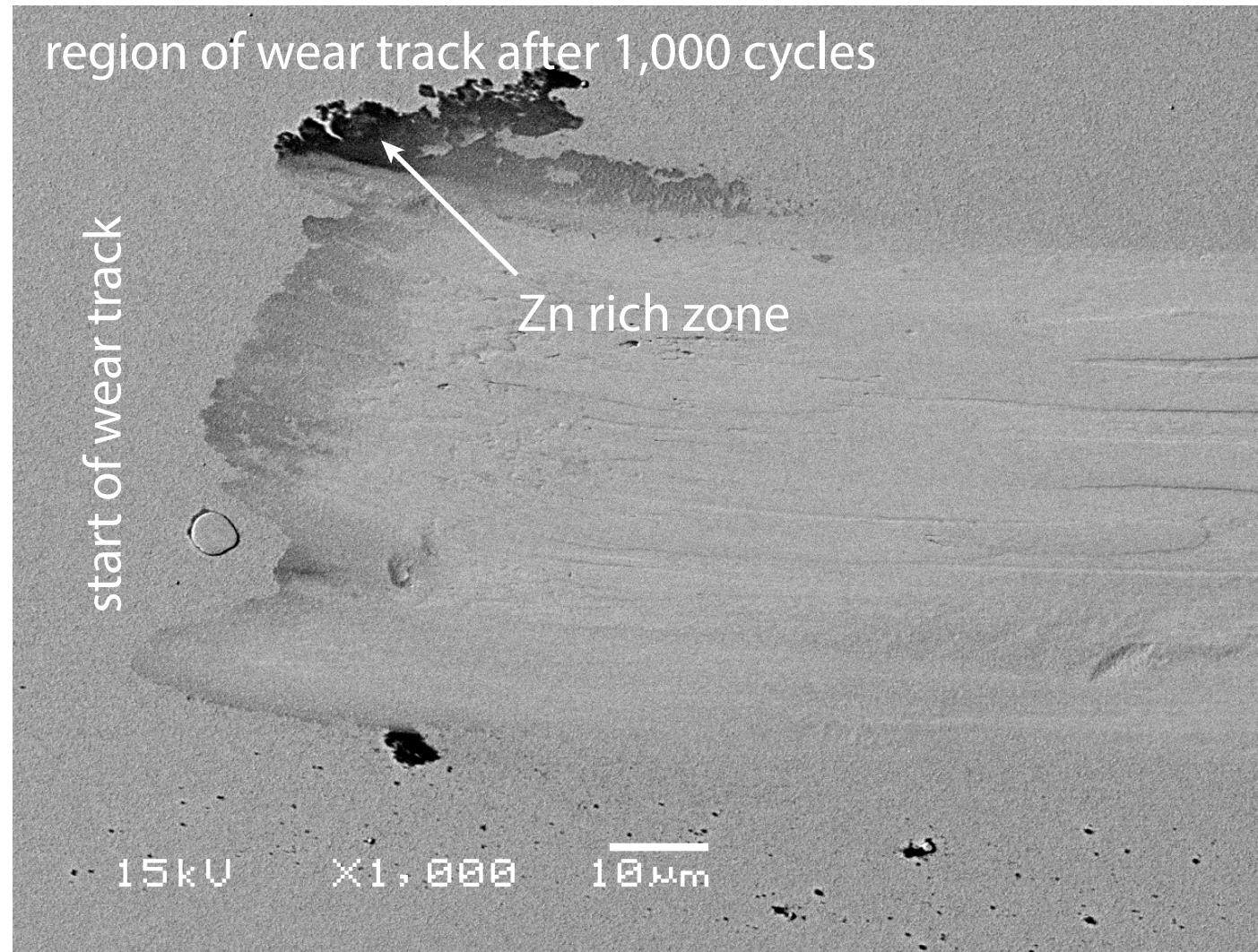


(example of topographical map)

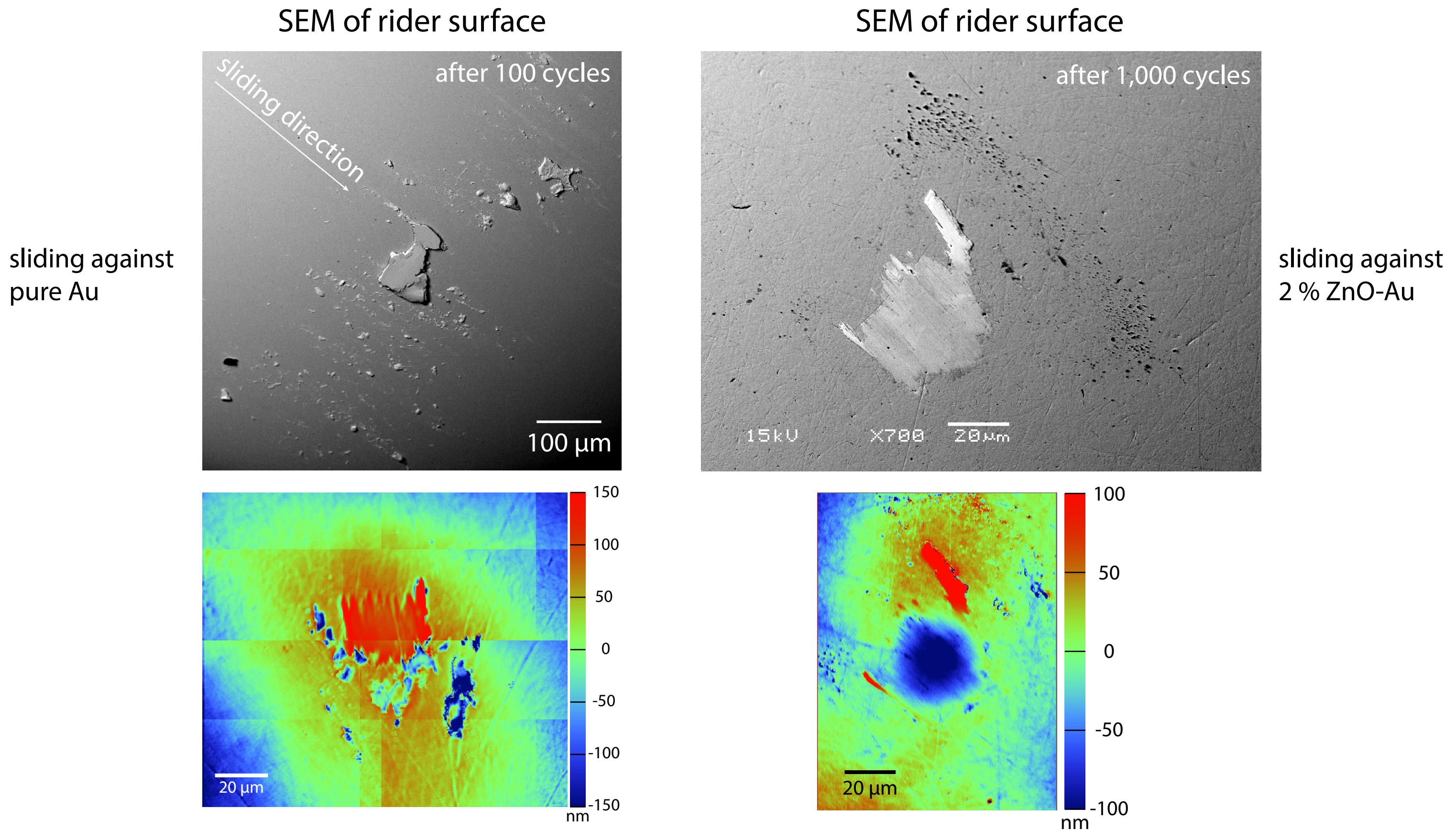


average linescans over
50% of wear track length

Effectively zero wear of the 2% ZnO gold nanocomposite



The 2% ZnO gold film wore the (hard!) Neyoro G pin



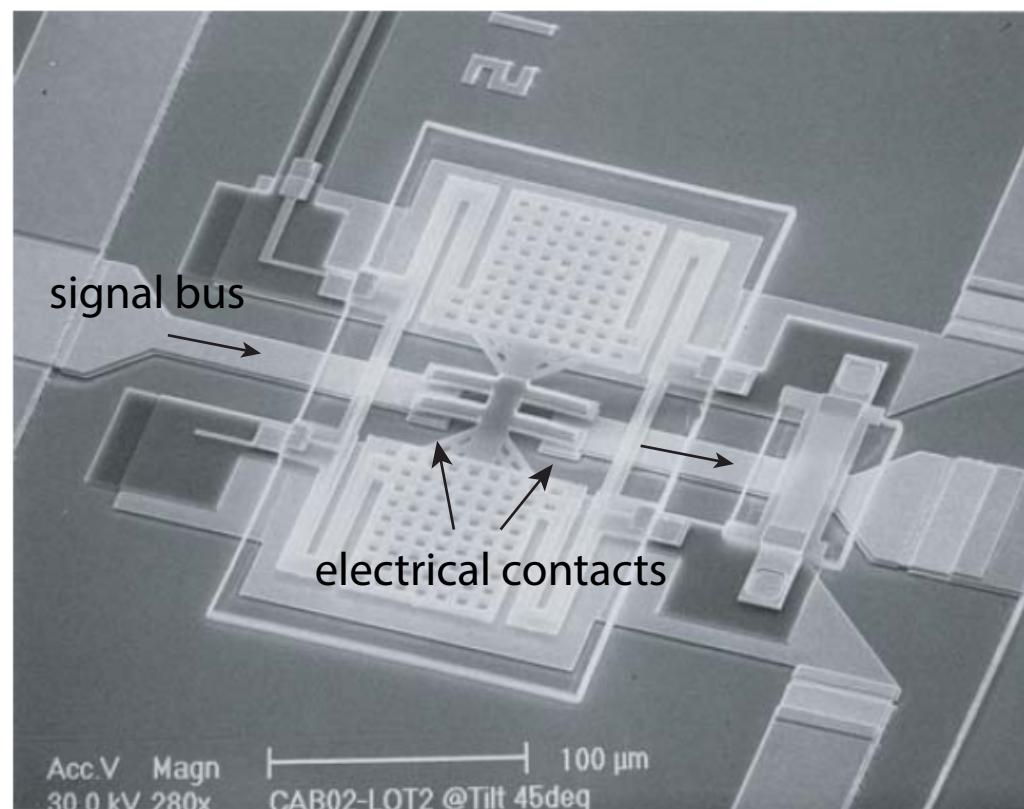
Neyoro G rider is **HARD** (~ 250 Knoop, or ~ 2.5 GPa)

reference: the hardest “hard gold” is in the 2.0 to 2.5 GPa range

preliminary result via nanoindentation, 0.1% strain : 1% ZnO-Au hardness ~ 2.6 GPa

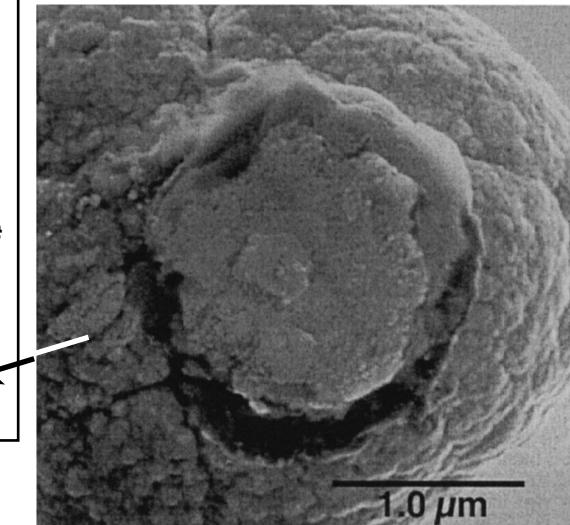
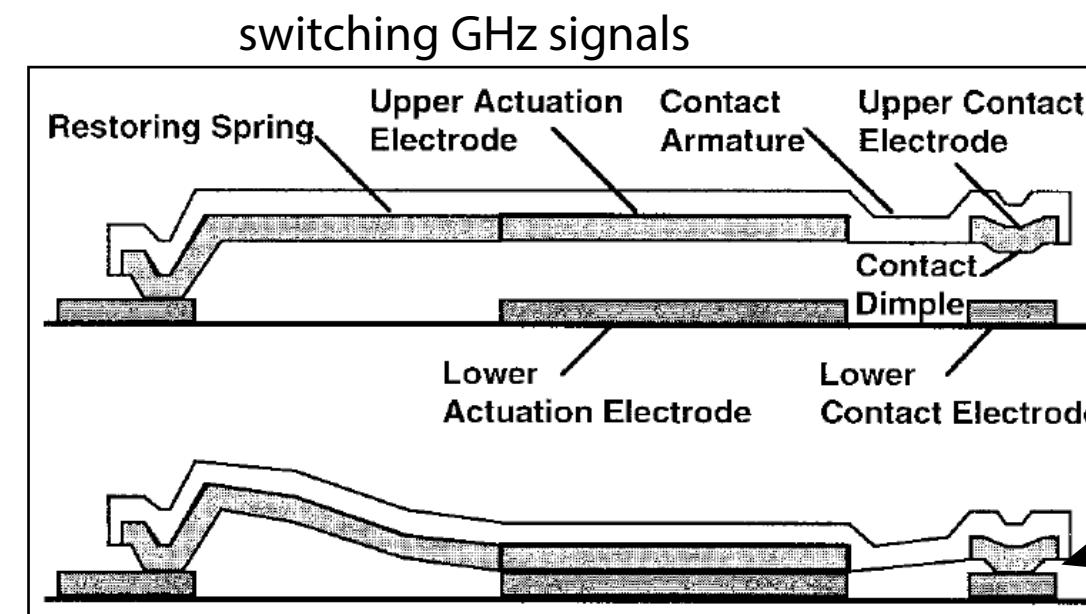
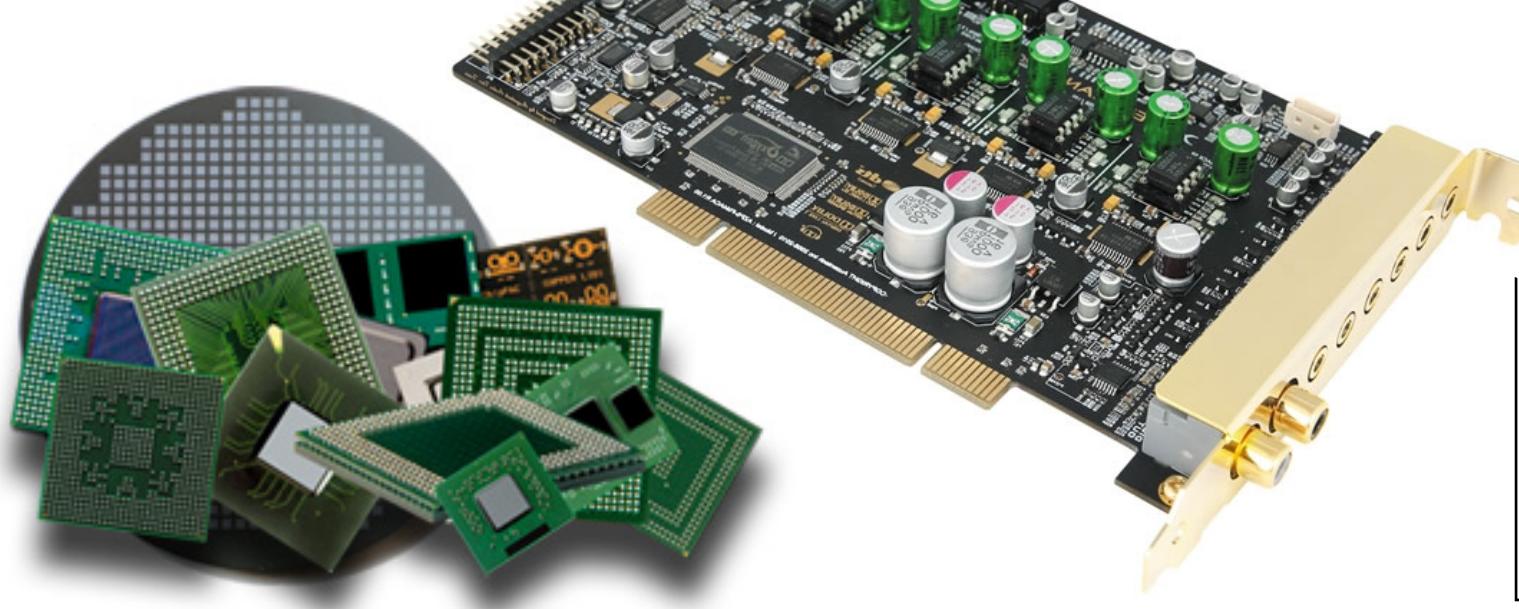
What are some examples of mechanical-electrical contacts?

MEMS

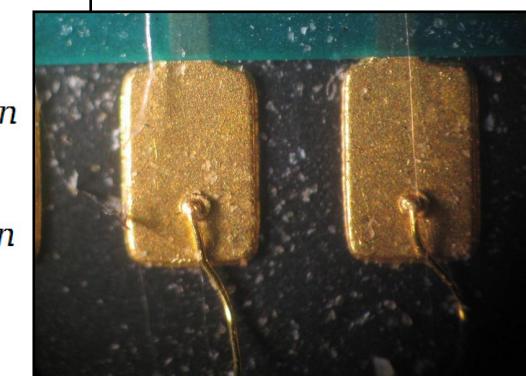
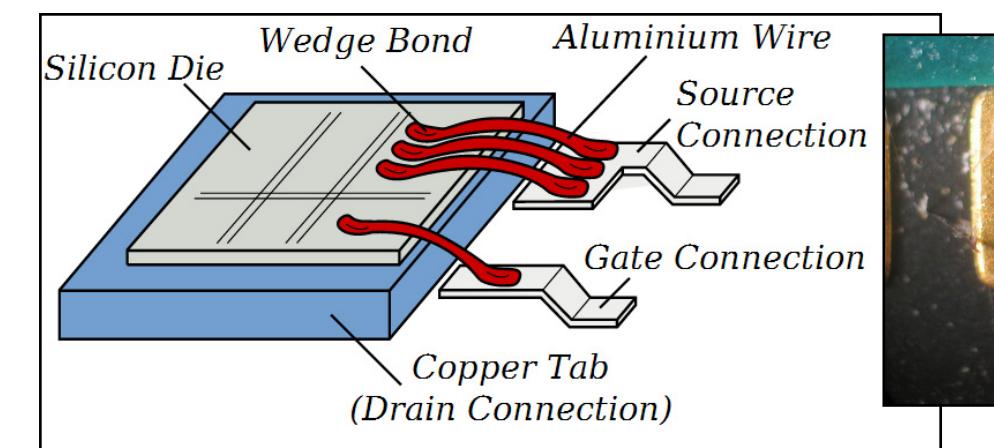


Rockwell Scientific metal-metal switch

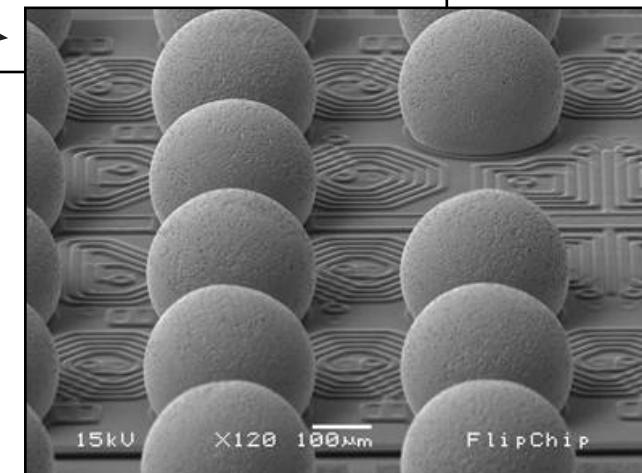
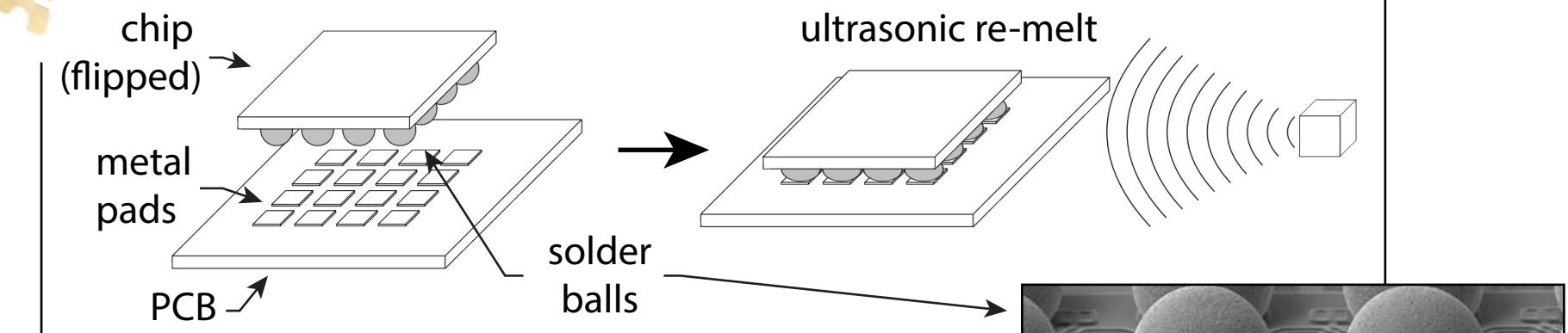
soldered connections for ICs and PCBs



wire bonding of ICs



flip chip (solder balls b/w pads, no wires)



**When electricity is required to pass through a contact,
the surfaces are metallic (conductivity!)**